

TPS65810 TPS65811

SLVS658B-MARCH 2006-REVISED FEBRUARY 2007

SINGLE-CELL LI-ION BATTERY- AND POWER-MANAGEMENT IC

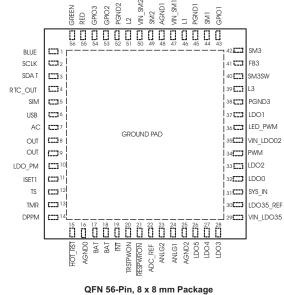
FEATURES

- BATTERY CHARGER
 - Complete charge management solution for single Li-Ion/Li-Pol cell with thermal foldback, dynamic power management and pack temperature sensing, supporting up to 1.5-A max charge current
 - Programmable charge parameters for AC adapter and USB port operation
- INTEGRATED POWER SUPPLIES
 - A total of 9 LDOs are integrated:
 - Six adjustable output LDOs (1.25-V to 3.3-V)
 - Two fixed-voltage LDOs (3.3-V)
 - One RTC backup supply with low leakage (1.5-V)
 - Two 0.6-V to 3.4-V programmable dc/dc buck converters (600-mA for TPS65810, 750-mA for TPS65811) with enable, standby-mode operation, and automatic low-power mode setting
- DISPLAY FUNCTIONS
 - Two open-drain PWM outputs with programmable frequency and duty cycle.
 Can be used to control keyboard backlight, vibrator, or other external peripheral functions
 - RGB LED driver with programmable flashing period and individual R/G/B brightness control
 - Constant-current white LED driver, with programmable current level, brightness control, and overvoltage protection can drive up to 6 LEDs in series configuration
- SYSTEM MANAGEMENT
 - Dual input power path function with input current limiting and OVP protection
 - POR function with programmable masking monitors all integrated supplies outputs

- Software and hardware reset functions
- 8-channel integrated A/D samples system parameters with single conversion, peak detection, or averaging operating modes
- HOST INTERFACE
 - Host can set system parameters and access system status using I²C interface
 - Interrupt function with programmable masking signals system status modification to host
 - 3 GPIO ports, programmable as drivers, integrated A/D trigger or buck converters standby mode control

APPLICATIONS

- PDAs
- Smart Phones
- MP3s
- Internet Appliances
- Handheld Devices



(Top View - Not To Scale)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





Res 1

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DESCRIPTION

The TPS65810 provides an easy to use, fully integrated solution for handheld devices, integrating charge management, multiple regulated power supplies, system management and display functions, in a small thermally-enhanced 8x8 package. The high level of integration enables typical board area space savings of 70% when compared to equivalent discrete solutions, while implementing a high-performance and flexible solution, portable across multiple platforms. If required, an external host may control the TPS65810 via I²C interface, with access to all integrated systems. The I²C enables setting output voltages, current thresholds, and operation modes. Internal registers have a complete set of status information, enabling easy diagnostics, and host-controlled handling of fault conditions. The TPS65810 can operate in stand-alone mode, with no external host control, if the internal power-up defaults are compatible with the system requirements

AVAILABLE OPTIONS⁽¹⁾

TJ	DEVICES ⁽²⁾ (3) (4)	MARKING
–40°C to 125°C	TPS65810RTQ	TPS65810
–40°C to 125°C	TPS65811RTQ	TPS65811

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

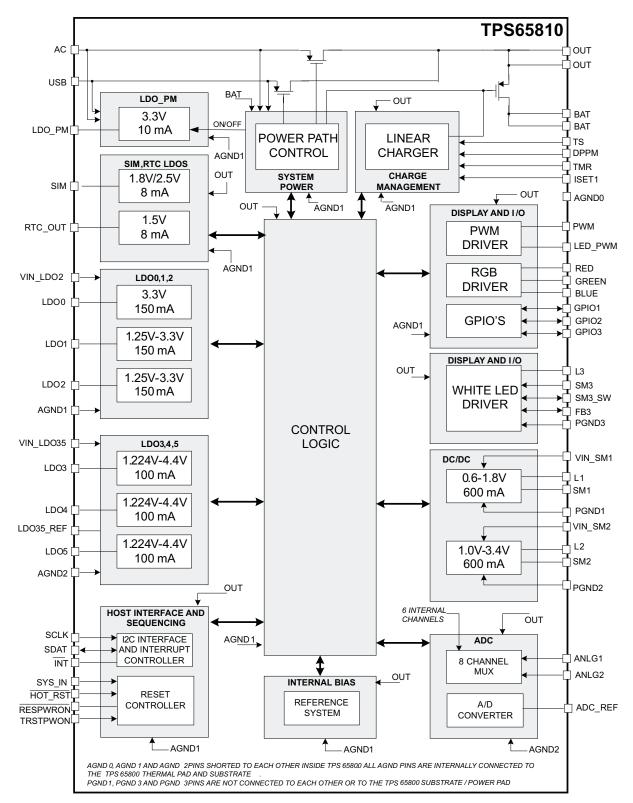
(2) The RTQ package is available in tape and reel. Add R suffix (TPS65810RTQR) to order quantities of 2000 parts per reel. Add T suffix (TPS65810RTQT) to order quantities of 250 parts per reel.

(3) This product is RoHS compatible, including a lead concentration that does not exceed 0.1% of total product weight, and is suitable for use in specified lead-free soldering processes. In addition, this product uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(4) Other power-up sequences and default power-up states for the supplies can be implemented upon request. Consult factory for available options

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾.

		VALUE	UNIT
	AC and USB with respect to AGND1	-0.3 to 18	
	ANLG1, ANLG2 with respect to AGND2	-0.3 to V(OUT)	
	V(OUT) with respect to AGND1	5	
	VIN_LDO12, VIN_LDO35, LDO3, LDO4, LDO5 with respect to AGND2	-0.3 to V(OUT)	
	LDO35_REF, ADC_REF with respect to AGND2	-0.3 to smaller of: 3.6 or V(OUT)	
	SIM, RTC_OUT with respect to AGND1	-0.3 to smaller of: 3.6 or V(OUT)	
	SM1, L1, VIN_SM1 with respect to PGND1	-0.3 to V(OUT)	V
	SM2, L2, VIN_SM2 with respect to PGND2	-0.3 to V(OUT)	
	SM3, L3 with respect to PGND3	-0.3 to 29	
	SM3SW with respect to PGND3	-0.3 to V(OUT)	
	ANLG1, ANLG2 with respect to AGND2-0.3 to V(OUT)V(OUT) with respect to AGND15VIN_LDO12, VIN_LDO35, LDO3, LDO4, LDO5 with respect to AGND2-0.3 to V(OUT)LDO35_REF, ADC_REF with respect to AGND1-0.3 to smaller of: 3.6SIM, RTC_OUT with respect to AGND1-0.3 to smaller of: 3.6SM1, L1, VIN_SM1 with respect to PGND1-0.3 to V(OUT)SM2, L2, VIN_SM2 with respect to PGND2-0.3 to V(OUT)SM3, L3 with respect to PGND3-0.3 to V(OUT)FB3 with respect to PGND3-0.3 to V(OUT)FB3 with respect to PGND1-0.3 to V(OUT)All other pins (except AGND and PGND), with respect to AGND1-0.3 to V(OUT)AGND2, AGND0, PGND1, PGND2, PGND3 with respect to AGND1-0.3 to V(OUT)AGND2, AGND0, PGND1, PGND2, PGND3 with respect to AGND1-0.3 to V(OUT)AGND2, Current, USB pin600Output continuous current, OUT pin3000Output continuous current, BAT pin-3000Continuous Current at L1, PGND1, L2, PGND21800Operating free-air temperature-40 to 85Maximum junction temperature125	-0.3 to 0.5	
	All other pins (except AGND and PGND), with respect to AGND1	-0.3 to V(OUT)	
	AGND2, AGND0, PGND1, PGND2, PGND3 with respect to AGND1	-0.3 to +0.3	
	Input Current, AC pin	2750	
	Input Current, USB pin	600	
	Output continuous current, OUT pin	3000	mA
	Output continuous current, BAT pin	-3000	
	Continuous Current at L1, PGND1, L2, PGND2	1800	
T _A	Operating free-air temperature	-40 to 85	
TJ	Maximum junction temperature	125	
T _{STG}	Storage temperature	-65 to 150	- °C
	Lead temperature 1,6 mm (1/16-inch) from case for 10 seconds	260	1
	ESD rating, all pins	1.5	kV

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE	θ_{JA}	T _A ≤ 55°C POWER RATING	DERATING FACTOR ABOVE T _A = 55°C
RTQ ⁽¹⁾ ⁽²⁾	21.7°C/W	3.22 W	0.046 W/°C

(1) This data is based on using the JEDEC High-K board and the exposed die pad is connected to a Cu pad on the board. This is connected to the ground plane by a via matrix.

(2) The RTQ package MSL level: HIR3 at 260°C

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RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
	AC and USB with respect to AGND1	4.35	16.5 ⁽¹⁾	V
	ANLG1,ANLG2 with respect to AGND2	0	2.6	V
	VIN_LDO35 with respect to AGND2	Greater of: 3.6 V OR minimum input	4.7	
	VIN_LDO12 with respect to AGND1	voltage required for LDO/converter operation outside dropout region	4.7	V
	VIN_SM1 with respect to PGND1		4.7	v
	VIN_SM2 with respect to PGND2		4.7	
	SM3 with respect to PGND3		28	V
T _A	Operating free-air temperature	-40	85	С
T _{J(op)}	Junction temperature, functional operation assured	-40	125	С
TJ	Junction temperature, electrical characteristics assured	0	125	С

(1) Thermal operating restrictions are reduced or avoided if input voltage does not exceed 5 V.

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ELECTRICAL CHARACTERISTICS – I²C INTERFACE

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
I ² C TIMING CH	ARACTERISTICS	I			
t _R	SCLK/SDATA rise time			300	
t _F	SCLK/SDATA fall time			300	ns
t _{W(H)}	SCLK pulse width high	600			
t _{W(L)}	SCLK Pulse Width Low	1.3			μs
t _{SU(STA)}	Setup time for START condition	600			
t _{H(STA)}	START condition hold time after which first clock pulse is generated	600			
t _{SU(DAT)}	Data setup time	100			ns
t _{H(DAT)}	Data hold time	0			
t _{SU(STOP)}	Setup time for STOP condition	600			
t _(BUF)	Bus free time between START and STOP condition	1.3			μs
FSCL	Clock Frequency			400	kHz
I ² C INTERFAC	E LOGIC LEVELS				
V _{IH}	High level input voltage	1.3		6	N
V _{IL}	Low level input voltage	0		0.6	V
I _H	Input bias current		0.01		μA

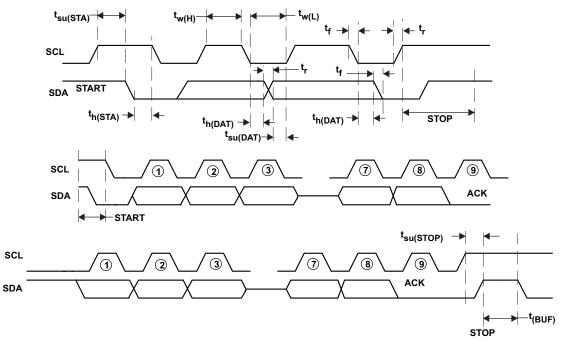


Figure 2. I²C Timing

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ELECTRICAL CHARACTERISTICS – SYSTEM SEQUENCING AND OPERATING MODES

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

F	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
QUIESCENT	CURRENT					
IBAT(SLEEP)	BAT pin current, sleep mode set	Input power not detected, V(BAT) = 4.2 V, Sleep mode set		400		μA
I _{BAT(DONE)}	BAT pin current, charge terminated	Charger function enabled by I ² C, termination detected, input power detected and selected		3		μA
IBAT(CHGOFF)	BAT pin current, charge function OFF	Charger function disabled by I ² C, termination not detected, input power detected and selected		3		μA
I _{INP(CHGOFF)}	AC or USB pin current, charge function OFF	Charger function disabled by I ² C, termination not detected, input power detected and selected. All integrated supplies and drivers OFF, no load at OUT pin.			200	μΑ
UNDERVOLT	AGE LOCKOUT					
V _{UVLO}	Internal UVLO detection threshold	NO POWER mode set at V(OUT) < V _{UVLO} , V(OUT) decreasing	-3%	2.5	3%	V
V _{UVLO_HYS}	UVLO detection hysteresis	V(OUT) increasing		120		mV
t _{DGL(UVLO)}	UVLO detection deglitch time	Falling voltage only		5		ms
SYSTEM LOV	V VOLTAGE THRESHOLD	· · · · · · · · · · · · · · · · · · ·			Ļ	
V _{LOW_SYS}	Minimum system voltage detection threshold	System voltage V(SYS_IN) decreasing, SLEEP mode set if V(SYS_IN) < V _{LOW_SYS}	0.97	1	1.03	V
V _{HYS(LOWSYS)}	Minimum system voltage detection hysteresis	V(SYS_IN) increasing		50		mV
t _{DGL(LOWSYS)}	Minimum system voltage detection deglitch time	V(SYS_IN) decreasing		5		ms
THERMAL FA	ULT	· · · · ·				
T _{SHUT}	Thermal shutdown	Increasing junction temperature		165		°C
T _{HYS(SHUT)}	Thermal shutdown hysteresis	Decreasing junction temperature		30		°C
INTEGRATED	SUPPLY POWER FAULT	DETECTION			Ļ	
V _{PGOOD}	Power good fault detection threshold	Falling output voltage, applies to all integrated supply outputs. Referenced to the programmed output voltage value	84%	90%	96%	
V _{HYS(PGOOD)}	Power good fault detection hysteresis	Rising output voltage, applies to all integrated supply outputs. Referenced to V_{PGOOD} threshold	3%	5%	7%	
HOT RESET I	FUNCTION					
V _{HRSTON}	Low level input voltage	RESET mode set at V(HOT_RESET) < V _{HRSTON}			0.4	V
V _{HRSTOFF}	High level input voltage	HOT reset not active at V(HOT_RESET) > V _{HRSTOFF}	1.3			V
t _{DGL(HOTRST)}	Hot reset input deglitch			5		ms
SYSTEM RES	ET – OPEN DRAIN OUTP	UT RESPWRON				
V _{RSTLO}	Low level output voltage	I _{IL} = 10 mA, V(RESPWRON) < V _{RSTLO}	0		0.3	V
ITRSTPWON	Pull-up current source	Internally connected to TRSTPWRON pin	0.9	1.0	1.2	μΑ
K _{RESET}	Reset timer constant	T _{RESET} = K _{RESET} × C _{TRSTPWON}		1		ms/nF

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ELECTRICAL CHARACTERISTICS – POWER PATH AND CHARGE MANAGEMENT

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIO	NS	MIN	TYP	MAX	UNIT
	DETECTION THRESHOLDS					шлл	
V _{IN(DT)}	Input Voltage detection threshold	AC detected at V(AC)– V(BAT) > $V_{IN(DT)}$; USB detected at V(USB)– V(BAT) > $V_{IN(DT)}$		190			mV
V _{IN(NDT)}	Input Voltage removal threshold	AC not detected at V(AC)– V(BAT) < V _{IN(NDT)} ; USB not detected at V(USB)– V(BAT) < V _{IN(NDT)}	T)			125	mV
t _{DGL(NDT)}	Power not detected deglitch		.,		22.5		ms
V _{SUP(DT)}	Supplement detection threshold	Battery switch ON at V(BAT) – V(OUT) > V _{SUP}	(DT)		60		mV
V _{SUP(NDT)}	Supplement not detected threshold	Battery switch OFF at V(BAT)- V(OUT) < V _{SUP(NDT)}			20		mV
POWER PA	TH INTEGRATED MOSFETs CH	HARACTERISTICS					
V _{ACDO}	AC switch dropout voltage	$V_{ACDO} = V(AC) - V(OUT); V(AC) = 4.75 V AC ii (typ), I_{O(OUT)} = 1.0 A$	nput current limit set to 2.75 A		350	375	mV
N/	LISP awitch dropout voltage	$V_{USBDO} = V(USB) - V(OUT); V(USB) = 4.6 V$	$_{BDO} = V(USB) - V(OUT); V(USB) = 4.6 V$ a input current limit set to 2.75 A (two)		175	190	mV
V _{USBDO}	USB switch dropout voltage	USB input current limit set to 2.75 A (typ)	I(OUT)+ I(BAT)= 0.1 A		35	45	mV
V _{BATDODCH}	Battery switch dropout voltage, discharge	V(BAT): 3 V \rightarrow V _{CH(REG)} , I(BAT) = -1 A			60	100	mV
V _{BATDOCH}	Battery switch dropout voltage, charge	Charger on, V(BAT): 3 V \rightarrow 4.2 V, I(BAT) = 1 μ	A		60	100	mV
POWER PA	TH INPUT CURRENT LIMIT	·					
INP(LIM1)	Selected input current limit, applies to USB input only	Selected input switch not in dropout, I ² C settin	gs: ISET2 = LO, PSEL = LO	80		100	mA
INP(LIM2)	Selected Input current limit, applies to USB input only	Selected input switch not in dropout, I ² C settin	gs: ISET2 = HI, PSEL = LO	400		500	mA
I _{INP(LIM3)}	Selected Input current limit, applies to either AC or USB input	Selected input switch not in dropout, I ² C settin = HI	gs: ISET2 = HI OR LO, PSEL			2.75	A
SYSTEM RE	GULATION VOLTAGE						
V _{SYS(REG)}	Output regulation voltage	V _{SYS(REG)} = V(OUT), DPPM loop not active, se reached. Selected input voltage (AC or USB) >	lected input current limit not > 5.1 V		4.6	4.7	V
POWER PA	TH PROTECTION AND RECOV	ERY FUNCTIONS					
V _{INOUTSH}	Input-to-output short-circuit detection threshold	AC and USB switches set to OFF if V(OUT) <	V _{INOUTSH}		0.6		V
R _{SH(USBSH)}	OUT short circuit recovery pullup resistor	V(OUT) < 1 V, internal resistor connected from	USB to OUT		500		Ω
R _{SH(ACSH)}	OUT short circuit recovery pullup resistor	V(OUT) < 1 V, internal resistor connected from	AC to OUT		500		Ω
N/	Overvoltage detection threshold	Rising voltage, overvoltage detected when V(A V(USB) > V_{OVP}	AC) > V _{OVP} or	6	6.5	6.8	V
V _{OVP}	Overvoltage detection hysteresis	Falling voltage, relative to detection threshold			0.1		v
V _{BATOUTSH}	Battery-to-output short-circuit detection threshold	BAT switch set to OFF if V(BAT) – V(OUT) > V _{BATOUTSH}			200		mV
K _{BLK(SHBAT)}	Battery-to-ouput short-circuit blanking time constant	V(DPPM) < 1v, t _{BLK(SHBAT)} = K _{BLK(SHBAT)} X C _{DPPM} , C _{DPPM} capacitor is connected from DPPM pin to AGND1			1		mS/n
I _{SH(BAT)}	OUT short circuit recovery pullup current source	$V_{(BAT)} - V_{(OUT)} > V_{BATOUTSH}$, Internal current source connected between OL	JT and BAT		10		mA
R _{SH(BAT)}	BAT short circuit recovery resistor	V _(BAT) < 1V, Internal resistor connected from OUT to BAT			1		kΩ
R _{DCH(BAT)}	BAT pulldown resistor	Internal resistor connected from BAT to AGND by ANLG1	1 when battery is not detected		500		Ω

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ELECTRICAL CHARACTERISTICS – POWER PATH AND CHARGE MANAGEMENT (Continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT
POWER PA	TH TIMING CHARACTERISTICS, DPP	AND THERMAL LOOPS NOT	Γ ACTIVE, R_{TMR} = 50 kΩ	-1			
t _{воот}	Boot-up time	Measured from input power	detection	120	200	300	ms
t _{SW(ACBAT)}	Switching from AC to BAT		No USB: measured from V(AC)– V(BAT) < V _{IN(NDT)} , USB detected:CE=LO (after CE hold-off time)			50	μs
t _{SW(USBBAT)}	Switching from USB to BAT	No AC: measured from V(US detected:CE=LO (after CE h				50	μs
t _{SW(PSEL)}	Switching from USB to AC	Toggling I ² C PSEL bit				50	μs
t _{SW(ACUSB)}	Switching from AC to USB or USB to AC	AC power removed or USB p	power removed			100	μs
BATTERY R	EMOVAL DETECTION						-
V _{NOBATID}	Battery ID resistor detection	ID resistor not detected at V	OUT)– V(ANLG1) < V _{NOBATID}		0.5		V
t _{DGL(NOBAT)}	Deglitch time for battery removal detection			0.6		1.2	ms
		Set via I ² C bits	00, $V_{(OUT)}\!\!:$ 2.5 V to 4.4 V	<u> </u>	UT) – 1.: 500 kΩ	2	
la un c ::	ANLG1 pullup current	(BATID1,BATID2)	01		10		μA
O(ANLG1)		ADC_WAIT register	10		50		
			11		60		
		Total accuracy		25%		25%	
FAST CHAR	RGE CURRENT, V(OUT) > V(BAT) + 0.1	V, V(BAT) > V _{LOWV}				,	
I _{O(BAT)}	Charge current range	$I_{O(BAT)} = \frac{K_{(SET)} \times V_{(SET)}}{R_{SET}}$		100		1500	mA
			11, 100% scaling	2.475	2.500	2.525	
		V _{SET} = V(ISET1),	10, 75% scaling	1.875	1.900	1.925	
V _{SET}	Battery charge current set voltage	(ISET1_1, ISET1_0) =	01, 50% scaling	1.225	1.250	1.275	V
		00, 25% scaling		0.575	0.600	0.625	
	5	100 mA < I _{O(BAT)} ≤ 1 A		350	400	450	-
K _{SET}	Battery charge current set factor	1 mA < I _{O(BAT)} ≤ 100 mA		100	400	1000	
PRE-CHAR	GE CURRENT, V(OUT) > V(BAT) + 0.1	V, V _{BATSH} < V(BAT) < V _{LOWV} , t	< t _(PRECHG)				
I _{O(PRECHG)}	Precharge current range	$I_{O(PRECHG)} = \frac{V_{(PRECHG)}}{R_{SE}}$	< К _(SET) г	10		150	mA
V _{PRECHG}	Precharge set voltage	$V_{PRECHG} = V(ISET1)$		220	250	270	mV
V _{LOWV}	Precharge to fast-charge transition	Fast charge at V(BAT) > V _{LC}	WV	2.8	3	3.2	V
t _{DGL(PRE)}	Deglitch time for fast charge to precharge transition	Decreasing battery voltage, I	$R_{\rm TMR} = 50 \ \rm k\Omega$		22.5		ms
CHARGE RI	EGULATION VOLTAGE, $V(OUT) > V_{O(E)}$	ATREG) + 0.1V					
		Voltage options, selection via	a 1 ² C		4.2		V
V _{O(BATREG)}	Battery charge voltage	voltage options, selection via			4.356		V
• U(BATREG)		Accuracy, $T_A = 25^{\circ}C$		-0.5%		0.5%	
		Total accuracy		-1%		1%	
CHARGE TE	ERMINATION, V(BAT) > V _{RCH} , VOLTAG						
I _{TERM}	Charge termination current range	$I_{(TERM)} = \frac{V_{(TERM)} \times K_{(SET)}}{R_{SET}}$		10		150	mA
			11, 100% scaling	240	260	280	
	Battery termination detection set	V _{TERM} = V(ISET1),	10, 75% scaling	145	160	175	
V _{TERM}	voltage	$(ISET1_1, SET1_0) =$	01, 50% scaling	90	110	130	mV
			00, 25% scaling	40	60	75	
t _{DGL(TERM)}	Deglitch time for termination detection	V(ISET1) < V _{TERM} , R _{TMR} = 50			22.5		ms

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ELECTRICAL CHARACTERISTICS – POWER PATH AND CHARGE MANAGEMENT (Continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BATTERY	RECHARGE DETECTION					
V _{RCH}	Recharge threshold voltage	New charge cycle starts if V(BAT) < V _{O(BATREG)} – V _{RCH} , after termination was detected	80	100	130	mV
t _{DGL(RCH)}	Deglitch time for recharge detection	$R_{TMR} = 50 \ k\Omega$		22.5		ms
DPPM FU	NCTION					
V _{DPPM}	DPPM regulation point range	$V_{(DPPM)} = R_{DPPM} \times K_{DPPMM} \times I_{O(DPPM)}$	2.6		4.4	V
I _{O(DPPM)}	DPPM pin current source	AC or USB Present	95	100	105	μΑ
K _{DPPM}	DPPM scaling factor		1.139	1.15	1.162	
t _{DGL(DPPM}	DPPM de-glitch time	Status bit set indicating DPPM loop active after deglitch time, R_{TMR} = 50 k Ω		500		μs
CHARGE	AND PRE-CHARGE SAFETY TIN	IER				
t _{CHG}	Charge safety timer programmed value	Safety timer range, thermal/DPPM loop not active, t_{CHG} = $R_{TMR} \times K_{TMR}$	3	5	10	h
K _{TMR}	Charge timer set factor		0.313	0.36	0.414	s/Ω
t _{CHGADD}	Total elapsed time when DPPM or thermal loop are active	Fast charge on, $t_{\mbox{CHGADD}}$ is the maximum add-on time added to $t_{\mbox{CHG}}$		$2 \times t_{\text{CHG}}$		h
t _{PRECHG}	Precharge safety timer programmed value	Pre charge safety timer range, thermal/DPPM loop not active, t_{PRECHG} = K_{\text{PRE}} \times R_{\text{TMR}} \times K_{\text{TMR}}	18	30	60	min
K _{PRE}	Pre-charge timer set factor		0.09	0.1	0.11	
t _{PCHGADD}	Total elapsed time when DPPM or thermal loop are active	Pre-charge on, t_{PCHGADD} is the maximum add-on time added to t_{PRECHG}		$2 imes t_{PRECHG}$		h
R _{TMR}	External timer resistor limits		30		100	kΩ
R _{TMR(FLT)}	Timer fault recovery pullup resistor	Internal resistor connected from OUT to BAT after safety timer timeout		1		kΩ
THERMAL	REGULATION LOOP	·				
T _{THREG}	Temperature regulation limit	Charge current decreased and timer extended when $T_{\rm J}$ > $T_{\rm THREG}$	115		135	°C
CHARGE	R THERMAL SHUTDOWN	·	-			
T _{THCHG}	Charger thermal shutdown	Charger turned off when T _J >T _{THCHG}		150		
T _{HCHGHYS}	Charger thermal shutdown hystersis			30		°C



ELECTRICAL CHARACTERISTICS – LINEAR REGULATORS

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN TYP MA	
SELECTABL	E OUTPUT VOLTAGE LDO'S: LDO1	LDO2		
I _{Q(LDO12)}	Quiescent current, either LDO1 or LDO2 enabled, LDO0 disabled	$I_{Q(LDO12)} = I(VIN_LDO02) \qquad \qquad I_{(LDO1,2)} = -1 \text{ mA}$	15	μA
	· · · · · · · · · · · · · · · · · · ·	$I_{(LDO1,2)} = -150 \text{ mA}$	160	
I _{O(LDO1,2)}	Output current range	Output Voltage, Selectable via I ² C.	15 Available output voltages: V _{O(LDO1,2)} TYP = 1.25, 1.5, 1.8 2.5, 2.85, 3, 3.2, 3.3	
		Dropout voltage, 150 mA load	30	0 mV
V _{O(LDO1,2)}	LDO1, LDO2 Output Voltage	Total accuracy, V(VIN_LDO02) = 3.65 V	-3% 3%	6
-()		Line Regulation, 100 mA load, V(VIN_LDO02): V _{(LDO1,2)TYP} + 0.5 V \rightarrow 4.7 V	-1% 19	6
		Load regulation, load: 10 mA \rightarrow 150 mA V(VIN_LDO02) > V _{O(LD01,2)} TYP + 0.5V	-1.5% 1.5%	6
P _{SR(LDO12)}	PSRR at 20 kHz	150mA load at output, V(VIN_LDO02) - V _{O(LDO1,2)} =1V	40	dB
I _{SC(LDO1,2)}	LDO1&2 short circuit current limit	Output grounded	300	mA
R _{DCH(LDO1,2)}	Discharge resistor	LDO disabled by I ² C command	300	Ω
I _{LKG(LDO1,2)}	Leakage current	LDO off	2	μΑ
SIM LINEAR	REGULATOR			
I _{Q(SIM)}	Quiescent current	Internally connected to OUT pin	20	μΑ
I _{O(SIM)}	Output current range			8 mA
		Output voltage, selectable via I ² C.	Available output voltages: V _{O(SIM)TYP} = 1.8 or 2.5	V
		Dropout voltage, 8 mA load	0.	2 V
V _{O(SIM)}	SIM LDO output voltage	Total accuracy, V(OUT): 3.2 V to 4.7 V, 8 mA	-5% 5%	6
O(OIM)		Load regulation, load: 1 mA \rightarrow 8 mA, V(OUT) > V_{O(SIM) TYP} + 0.5 V	-3% 39	6
		Line regulation, 5 mA load, V(OUT): $V_{O(SIM)\ TYP}$ + 0.5 V \rightarrow 4.7 V	-2% 2%	6
I _{SC(SIM)}	Short-circuit current limit	Output grounded	20	mA
I _{LKG(SIM)}	Leakage current	LDO off	1	μΑ
PROGRAM	IABLE OUTPUT VOLTAGE LDO'S: L	DO3, LDO4, LDO5		
I _{Q(LDO35)}	Quiescent current, only one of LDO3, LDO4, LDO5 is enabled	I _{Q(LDO35)} = I(VIN_LDO35)	70	μΑ
I _{O(LDO35)}	Output current range		10	0 mA
		Output voltage, selectable via I ² C	Available output voltages: V _{O(LDO35)TYP} = 1.224 V to 4.46 V, 25-mV steps	v
		Dropout voltage, 100-mA load	24	0 mV
V _{O(LDO35)}	LDO3, LDO4, LDO5 output voltage	Total accuracy, 100 mA load V _(VIN_LDO35) = 5 V	-3% 3%	6
		Load regulation, V(VIN_LDO35) > V _{O(LDO35)TYP} + 0.5 V, load: mA \rightarrow 50 mA	1 –1% 19	6
		Line regulation, 10-mA load, V(VIN_LDO35): V_{O(LDO35)TYP} + 0.5 V \rightarrow 4.7 V	-1% 19	6
I _{SC(LDO35)}	Short-circuit current limit	Output grounded	250	mA
PSR _(LDO35)	PSRR at 10 kHz	$V(VIN_LDO35) > V_{O(LDO3,5)} +1 V$, 50 mA load at output	40	dB
R _{DCH(LDO35)}	Discharge resistor	LDO is disabled by I ² C command	400	Ω
I _{LKG(LDO35)}	Leakage current	LDO off	1	μΑ

ELECTRICAL CHARACTERISTICS – LINEAR REGULATORS (continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
RTC_OUT LINEAR REGULATOR					



ELECTRICAL CHARACTERISTICS – LINEAR REGULATORS (continued) (continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

I _{Q(RTC_OUT)}	Quiescent current for RTC LDO	Internally connected to OUT pin			20		μA
I _{O(RTC_OUT)}	Output current range					8	mA
		Fixed output voltage value			1.5		V
		Dropout voltage, I(RTC_OUT) = -8 m	۱A			200	mV
V _{O(RTC_OUT)}	RTC OUT output voltage	Total accuracy, V(OUT): 2 V to 4.7 V sleep mode not set	, 8 mA load,	-5%		5%	
• O(RTC_OUT)		Load regulation, load: 1 mA \rightarrow 8 mA, 2 V < V(OUT) < 4.7 V		-3%		3%	
		Line regulation, 5-mA load V(OUT): 2 V \rightarrow 4.7 V		-2%		2%	
I _{SH(RTC_OUT)}	Short-circuit current limit	V(RTC_OUT) = 0 V			20		mA
		V(RTC_OUT) = 1.5 V,	$T_J = 85^{\circ}C$		880		
LKG(RTC_OUT)	Leakage current	V(OUT) = 0 V	$T_J = 25^{\circ}C$		250		nA
LDO0 LINEAR	REGULATOR		1				
I _{Q(LDO0)}	Quiescent current	Internally connected to VIN_LDO12	I(LDO0) = -1 mA		15		۵
		pin	I(LDO0) = -150 mA		160		μA
I _{O(LDO0)}	Output current range					150	mA
O(LDO0)		Fixed output voltage value			3.3		V
		Dropout voltage, I(LDO0) = -150 mA				300	mV
V _{O(LDO0)}	Output voltage	Total accuracy		-3%		3%	
VO(LDO0)	Output voltage	Line regulation, V(OUT): $V_{O(LDO0)} + 0$ I(LDO0) = -100 mA	.5 ightarrow 4.7 V,	-1%		1%	
		Load regulation, I(LDO0) = $-10 \text{ mA} \rightarrow -150 \text{ mA}$		-1.5%		1.5%	
PSR _(LDO0)	PSRR at 20 kHz	150 mA load at output, V(VIN_LDO12	2) – V _{O(LDO1,2)} = 1V		40		dB
I _{SC(LDO0)}	Short circuit current limit	V(LDO0) = 0 V			300		mA
I _{LKG(LDO0)}	Leakage current	LDO off			1		μΑ
LDO_PM LINE	AR REGULATOR						
I _{Q(LD0_PM)}	Output current range					20	mA
		Fixed output voltage value, V(OUT) >	• 4V		3.3		V
V _{O(LDO_PM)}	Output voltage	Dropout voltage, I(LDOPM) = -12 mA			0.5	0.7	V
		Total accuracy		-5%		5%	
ILKG(LDOPM)	Leakage current	LDO off			1		μA



ELECTRICAL CHARACTERISTICS – SWITCHED-MODE SM1 STEP-DOWN CONVERTER

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), $V_{O(SM1)} = 1.24$ V, application circuit Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
		I _{Q(SM1)} = I(VIN_ SM1), no output load	Not switching		10		
IQ(SM1)	Quiescent current for SM1	SM1 OFF, set via I ² C	1		0.1		μA
	Output aument reason	Vin = 4.2 v, Vout = 1.24 V (TPS65810)		600			(
I _{O(SM1)}	Output current range	Vin = 4.2 v, Vout = 1.24 V (TPS65811)		750			mA
		Output voltage, selectable via I ² C, Stand	lby OFF	Available output voltages: V _{O(SM1)TYP} = 0.6 V to 1.8 V, adjustable in 40-mV steps			V
V _{O(SM1)}	Output voltage, PWM mode	V _{O(SM1)} = V _{SBY(SM1)} , Output voltage rang	ge, Standby ON	Available output voltages: V _{SBY(SM1)} = 0.6 V to 1.8 V, adjustable in 40-mV steps			V
		Total accuracy, $V_{O(SM1)TYP} = V_{SBY(SM1)} = V(VIN_SM1) = 3.0 V to 4.7 V; 0 mA \le I_O$	-3%		3%		
		Line Regulation, V(VIN_SM1): 3.0 \rightarrow 4.7 $I_{O(SM1)}$ = 10 mA	0.027			%/V	
		Load Regulation, V(VIN_SM1) = 4.7 V, $I_{O(SM1)}$: 60 mA \rightarrow 540 mA			0.139		%/A
R _{DSON(PSM1)}	P-channel MOSFET on-resistance	V(VIN_SM1) = 3.6 V, 100% duty cycle s	et		310	500	mΩ
I _{LKG(PSM1)}	P-channel leakage current				0.1		μA
R _{DSON(NSM1)}	N-channel MOSFET on-resistance	V(VIN_SM1) = 3.6 V, 0% duty cycle set			220	330	mΩ
ILKG(PSM1)	N-channel leakage current				5		μΑ
1	P- and N-channel current limit	3 V < V(VIN_SM1) < 4.7 V (TPS65810)		900	1050	1200	mA
I _{LIM(SM1)}		3 V < V(VIN_SM1) < 4.7 V (TPS65811)		1000	1200	1400	ША
f _{S(SM1)}	Oscillator frequency	PWM mode set		1.3	1.5	1.7	MHz
EFF _(SM1)	Efficiency	V(VIN_SM1) = 4.2 V, PWM mode, I _{O(SM} V _{O(SM1)} = 3 V	₁₎ = 300 mA,		90%		
t _{SS(SM1)}	Soft start ramp time	Converter OFF \rightarrow ON, V _{O(SM1)} : 5% \rightarrow 95 value	% of target		750		μs
t _{DLY(SM1)}	Converter turn-on delay	GPIO1 pin programmed as SM1 convert control. Measured from V(GPIO1): LO –		170		μs	



ELECTRICAL CHARACTERISTICS – SWITCHED MODE SM2 STEP DOWN CONVERTER

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), $V_{O(SM1)} = 1.24$ V, application circuit Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
I _{Q(SM2)}	Quiescent current for SM2	I _{Q(SM2)} = I(VIN_ SM2), no output load, not switching		10		μA	
-(()		SM2 OFF, set via I ² C		•			
		Vin = 4.2 v, Vout = 1.24 V (TPS65810)	600				
O(SM2)	Output current range	Vin = 4.2 v, Vout = 1.24 V (TPS65811)	750			mA	
	Output voltage, selectable via I ² C, standby OFF		Available output voltages: V _{O(SM2)TYP} = 1 V to 3.4 V, adjustable in 80-mV steps			V	
		$V_{O(SM2)} = V_{SBY(SM2)}$, Output voltage range, Standby ON	Available out V _{SBY(SM2)} = adjustable in	ages: 4 V, steps	V		
V _{O(SM2)}	Output voltage	$ \begin{array}{l} \mbox{Total accuracy, $V_{O(SM2)TYP} = V_{SM2(SBY)} = 1.8$ V,} \\ V(VIN_SM2) = greater of [3.0$ V or ($V_{O(SM2)} + 0.3$ V)] \\ to 4.7$ V; 0$ mA \leq I_{O(SM2)} \leq 600$ mA \\ \end{array} $	-3%		3%		
		Line regulation, V(VIN_SM2) = greater of [3 V or (V _{O(SM2)} + 0.3 V)] to 4.7 V; 0 mA \leq I _{O(SM2)} \leq 600 mA	0.027			%/V	
		Load regulation, V(VIN_SM2) = 4.7 V, $I_{O(SM2)}$: 60 mA \rightarrow 540 mA		0.139		%/A	
R _{DSON(PSM2)}	P-channel MOSFET on-resistance	V(VIN_SM2) = 3.6 V, 100% duty cycle set		310	500	mΩ	
I _{LKG(PSM2)}	P-channel leakage current			0.1		μΑ	
R _{DSON(NSM2)}	N-channel MOSFET on-resistance	V(VIN_SM2) = 3.6 V, 0% duty cycle set		220	330	mΩ	
I _{LKG(PSM2)}	N-channel leakage current			5		μA	
		3 V < V(VIN_SM2) < 4.7 V (TPS65810)	900	1050	1200		
LIM(SM2)	P- and N-channel current limit	3 V < V(VIN_SM2) < 4.7 V (TPS65811)	1000	1200	1400	mA	
f _{S(SM2)}	Oscillator frequency	PWM mode set	1.3	1.5	1.7	MHz	
EFF _(SM2)	Efficiency	V(VIN_SM2) = 4.2 V, $I_{O(SM2)}$ = 300 mA, $V_{O(SM2)}$ = 3 V		90%			
t _{SS(SM2)}	Soft start ramp time	Converter OFF \rightarrow ON, V _{O(SM2)} : 5% \rightarrow 95% of target value		750		μs	
t _{DLY(SM2)}	Converter turn-on delay	GPIO2 pin programmed as SM2 converter enable control. Measured from V(GPIO2): LO \rightarrow HI		170		μs	

ELECTRICAL CHARACTERISTICS – GPIOs

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
GPIO1-3						
V _{OL}	Low level output voltage GPIO0	I _{OL} = 20 mA			0.5	V
I _{OGPIO}	Low level sink current into GPIO1,2,3	V(GPIOn) = V(OUT)	20			mA
V _{IL}	Low level input voltage				0.4	V
I _{LKG(GPIO)}	Input leakage current	V(GPIOn) = V(OUT)		1		μA

ELECTRICAL CHARACTERISTICS – ADC

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), V(ADC_REF) =2.535v if external reference voltage is used, application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
ANALOG INPU	ITS	I					I	
V _{RNG(CH1_5)}	Full scale input range Ch1 to Ch5	Positive inputs (active clamp) Full scale ~ 2.535 V		0		V(ADC_ REF)	V	
V _{RNG(CH6_8)}	Full scale input range Ch6 to Ch8	Positive inputs (active clamp), full scal	e ~4.7 V	0		V _{INTREF} ×1.854	V	
C _{IN(ADC)}	Input capacitance (all channels)			15		pF		
RINADC(CH1_5)	Input resistance	(Ch1 to Ch5)		1			MΩ	
ILKGADC(CH1_5)	Leakage current	(Ch1 to Ch5)				100	nA	
RINADC(CH6_8)	Input resistance	(Ch6 to Ch8)		430	540		kΩ	
ILKGADC(CH6_8)	Leakage current	(Ch6 to Ch8)				10	μΑ	
V _{CH5(ADC)}	Internal voltage proportional to junction temperature	$T_J = 25^{\circ}C$, ADC channel 5 input voltag		1.895 6.5		V mV/ °C		
DC ACCURAC	Y				0.0		, c	
RES _(ADC)	Resolution	SAR ADC			10		Bits	
MCD _(ADC)	No missing codes			SE	PECIFIED)	Dito	
INL _(ADC)	Integral linearity error			0.	±3	·	LSB	
DNL _(ADC)	Differential non-linearity error				±1		LSB	
OFF _{ZERO(ADC)}	Offset error	Difference between the first code trans (0000 to 0001) and the ideal AGN				5	LSB	
OFF _{CH(ADC)}	Offset error match between channels				5	LSB		
GAIN _{ADC}	Gain error	Deviation in code from the ideal full so (11111) for the full scale voltage		±8		LSB		
GAIN _{CH(ADC)}	Gain error match	Any two channels			2		LSB	
THROUGHPUT	SPEED							
ADC _{CLK}	Sampling clock			600	750	900	kHz	
ADC _{TCONV}	Conversion time	Sampling, conversion and setting Rs \leq CH1,CH2,CH3; Rs \leq 500 Ω for CH6, C		44	59	68	μs	
REFERENCE V	OLTAGES							
VINTREF	Internal ADC reference voltage	$T_A = 25^{\circ}C$, V(ADC_REF)=V _{INTREF} whe ADC reference is selected	en internal	2.53	2.535	2.54	V	
I _{SHRT(INTREF)}	Internal reference short circuit limit	V(ADC_REF)= AGND1, internal refere enabled via I ² C	ence		6		mA	
V _{REF(DRIFT)}	ADC internal reference temperature drift				50	100	ppm/°C	
I _{Q(ADC)}	ADC Internal reference quiescent current	Measured at OUT pin (internal referen ADC_REF pin (external reference)	ce) or		40		μA	
			00		0			
		ADC channel 2 bias current, set via I ² C register ADC_WAIT bits	01		10		μA	
I _(ANLG2)	ANLG2 pin internal pullup current source	(ADC_CH2I_D1_1, ADC_CH2I_D2)	10		50		μΛ	
			11		60			
		Total accuracy, relative to selected va	lue	-25%		25%		
		ADC channel 1 bias current, set via	00		0UT) — 1. 500 kΩ	2	μA	
1	ANLG1 pin internal pullup	I ² C register ADC_WAIT bits	01		10			
(ANLG1)	current source	(BATIDI_D1, BATIDI _D2)	10		50			
			11		60			
		Total accuracy		10%		10%		

ELECTRICAL CHARACTERISTICS – ADC (continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}$ C), V(ADC_REF) =2.535v if external reference voltage is used, application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INTERNAL R	EFERENCE POWER CONSUMP	TION				
PD _{ACTIVE}	Power dissipation	Conversion active		2.3		mW
PD _{ARMED}	Power dissipation	Not converting		0.43		mW
TRIGGER TIM	MING CHARACTERISTICS					
t _{DELAY(TRG)}	Trigger delay time accuracy	Time range, set via I ² C register ADC_DELAY	0		750	uS
		Relative to typical value set via I ² C	-20%		+20%	
t _{WAIT(TRG)}	Trigger wait time accuracy	Time range, set via I ² C register ADC_WAIT	0		20.48	mS
· · · ·		Relative to typical value set via I ² C	-20%		+20%	

ELECTRICAL CHARACTERISTICS – LED AND PWM DRIVERS

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	UNIT
SM3 BOOST	CONVERTER, WHITE LED CON	ISTANT CURRENT DRIVER					
V _{VIN(SM3)}	Input Voltage range	V(OUT) = 3.3 V		3		4.7	V
V _{OVP3}	Output overvoltage trip	OVP detected at V(SM3) > \	/ _{OVP3}	26.5	29	30	V
V _{HYS(OVP3)}	Output overvoltage hysteresis	OVP not detected at V(SM3)		1.8		V	
V _{SM3REF}	LED current sense threshold	LED current below regulation V(FB3) < V _{SM3REF}	n point at	244	252	260	mV
I _{O(SM3)}	LED current	Current range, Vin = 3.3 V,	$_{O(SM3)} = \frac{V(SM3REF)}{R_{FB3}}$	0		25	mA
		Total accuracy, $I_{O(SM3)} = 10r$	mA	-10%		10%	
D _{SM3SW}	LED switch duty cycle	Duty cycle range		D _{SM3SW} = 0% to 99.6%, set via I ² C, 256 steps, 0.4% minimum step			_
F	LED switch duty cycle pattern	256 pulses within repetition	SM3_LF_OSC = 0	122			
F _{REP_SM3}	repetition rate	rate time	SM3_LF_OSC = 1		183		Hz
R _{DSON(SM3SW)}	LED switch MOSFET on-resistance	V(OUT)=3.6 V; I(SM3SW)=2	20 mA		1	2	Ω
I _{LKG(SM3SW)}	LED switch MOSFET leakage				1		μΑ
R _{DSON(L3)}	Power stage MOSFET on-resistance	V(OUT) = 3.6 V; I(L3) = 200	mA		300	600	mΩ
I _{LKG(L3)}	Power stage MOSFET leakage				1		μA
I _{MAX(L3)}	Power stage MOSFET current limit	3 V < V(OUT) < 4.7 V		400	500	600	mA
PWM DRIVER	, PWM OPEN DRAIN OUTPUT						
V _{OL(PWM)}	Low level output voltage	I(PWM)= 150 mA				0.5	V
F _{PWM}	PWM driver frequency	Frequency range	Set via I ² C, F _{PWM} = 0.5/1/1.5/2/3/4.5/7.8/15.6			Hz	
		Total accuracy, relative to se	elected value	-20%		+20%	
D _{PWM}	PWM driver duty cycle	Duty cycle range	D _{PWM} = 6.2	5% to 10 % minim	via I ² C,	_	

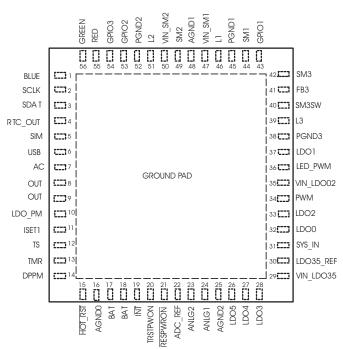
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ELECTRICAL CHARACTERISTICS – LED AND PWM DRIVERS (continued)

Over recommended operating conditions (typical values at $T_J = 25^{\circ}C$), application circuit as in Figure 3 (unless otherwise noted).

	PARAMETER	TEST COND	TEST CONDITIONS			MAX	UNIT
LED_PWM D	RIVER, LED_PWM OPEN DRAI	N OUTPUT					
D _{LEDPWM}	LED_PWM driver duty cycle	Duty cycle range		D _{LEDPWM} = 0% to 99.6%, set via I ² C, 256 steps 0.4% minimum step			
F	LED_PWM driver duty cycle	_PWM driver duty cycle 256 pulses within repetition SM3_LF_OSC = 0				Hz	
F _{REP(LEDPWM)}	pattern repetition rate						ΠZ
V _{OL(LEDPWM)}	Low level output voltage	I(LED_PWM) = 150 mA	I			0.5	V
V _{OH(LEDPWM)}	High level output voltage					6	V
	, RED/GREEN/BLUE OPEN DR						
t _{FLASH(RGB)}	Flashing period	Flashing period range	t _{FLASH(RGB)} = 1 to 8 sec, set via I ² C, 0.5 sec minimum step, 8 steps			sec	
	Total accuracy			-20%		+20%	
t _{FLASH(ON)}	Flash on time	Flash on time range, value s	Flash on time range, value selectable by I^2C		Set via I ² C, t _{FLASH(ON)} = 0.1/0.15/0.2/0.25/0.3/0.4/ 0.5/0.6 Sec		
		Total accuracy relative to set	lected value	-20%		+20%	-
D _{RGB}	Duty cycle	Duty cycle range, value sele	ctable via I ² C	D _{RGB} = 0% via I ² C, 3	6 to 99.9 3.23% m	8%, set ninimum step	
		V(RED) = V(GREEN) =	00 = (Driver set to OFF)				
I _{SINK(RGB)}	RGB output sink current	V(RED) = V(GREEN) = V(BLUE) = 2 V, set via I ² C	01	2.4	4	5.6	mA
Cirti(ICOD)	·	RGB_ISET1,0	10	4.8	8	11.2	
			11	7	12	16.6	
V _{OL(RGB)}	Low-level output voltage	Output low voltage, 8-mA loa PINS	Dutput low voltage, 8-mA load, RED/GREEN/BLUE 0.3				V
I _{LKG(RGB)}	Output off leakage current	V(RED)=V(GREEN)=V(BLUE) = 4.7 V, all drivers disabled				μΑ	



PIN ASSIGNMENT

PIN DESCRIPTION, REQUIRED EXTERNAL COMPONENTS

NAME	PIN	I/O	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (SEE APPLICATION DIAGRAM)
AC	7	I	Adapter charge input voltage, connect to AC_DC adapter positive output terminal (dc voltage)	1-μF (minimum) capacitor to AGND1 pin to minimize overvoltage transients during AC power hot-plug events.
ADC_REF	22	I/O	ADC internal reference filter or ADC external reference input	4.7 μF (minimum) to 10 μF (maximum) capacitor connected to AGND2 pin
AGND0	16	-	Analog ground connection	Connect to analog ground plane
AGND1	48	-	Analog ground pin	Connect to analog ground plane
AGND2	25	-	Analog ground pin	Connect to analog ground plane
ANLG1	24	I	Analog input to ADC, programmable current source output	Can be used to monitor additional system or pack parameters
ANLG2	23	I	Analog input to ADC, programmable current source output	Can be used to monitor additional system or pack parameters
BAT	17, 18	I/O	Battery power	Connect to battery positive terminal. Connect $10-\mu F$ capacitor (minimum) from BAT pin to AGND1 pin.
BLUE	1	0	Programmable blue driver, open drain output, current sink output when active.	Connect to BLUE input of RGB LED
DPPM	14	I	Dynamic power path management set-point	External resistor from DPPM pin to AGND1 pin sets the DPPM regulation threshold. 1-nF (minimum) capacitor to from DPPM to AGND1 sets BAT to OUT short circuit blanking delay when battery is hot-plugged into system
FB3	41	I/O	White LED duty cycle switch output, LED current setting	External resistor from FB3 pin to PGND3 pin sets LED peak current. Connect 100 pF (minimum) filter capacitor to PGND3 pin.
GPIO1	43	I/O	General purpose programmable I/O	Power-up default: SM1 enable control, SM1 ON @ GPIO1=HI.
GPIO2	53	I/O	General purpose programmable I/O	Power-up default: SM2 enable control, SM2 ON at GPIO2 = HI.
GPIO3	54	I/O	General purpose programmable I/O.	Example: ADC conversion start trigger.
GREEN	56	0	Programmable LED driver, open drain output, current sink output when active.	Connect to GREEN input of RGB LED



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TPS65810

NAME	PIN	I/O	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (SEE APPLICATION DIAGRAM)
HOT_RST	15	I/O	Hardware reset input, reset generated when connected to ground	Connect to an external push-button switch. Connect to external pullup resistor.
INT	19	0	Interruption pin, open-drain output	Connect 100-k Ω external pullup resistor between $\overline{\text{INT}}$ and OUT $\overline{\text{INT}}$ pin is LO when interrupt is requested by TPS65810.
ISET1	11	I	Current set point when charging in auto mode with AC selected. Pre-charge and charge termination set point for all charge modes	External resistor from ISET1 pin to AGND1 pin sets charge current value
L1	46	0	SM1 synchronous buck converter power-stage output	3.3-µH inductor to SM1 pin
L2	51	0	SM2 synchronous buck converter power-stage output	3.3-µH inductor to SM2 pin
L3	39	0	Drain of the integrated boost power-stage switch	4.7- μ H inductor to OUT pin, external Schottky diode to SM3 pin
LDO0	32	0	LDO0 output, fixed voltage	1-μF (minimum) capacitor to AGND1
LDO1	37	0	LDO1 output	1-μF (minimum) capacitor to AGND1
LDO2	33	0	LDO2 output	1-μF (minimum) capacitor to AGND1
LDO3	28	0	LDO3 output	2.2-µF (minimum) capacitor to AGND2
LDO35 REF	30	I	Linear regulators LDO3-5 reference filter	100-nF capacitor to AGND2
LDO4	27	0	LDO4 output	2.2-μF (minimum) capacitor to AGND2
LDO5	26	0	LDO5 output	2.2-μF (minimum) capacitor to AGND2
LDO_PM	10	0	General purpose LDO output	1-μF (minimum) capacitor to AGND1 pin
LED_PWM	36	0	PWM driver output, open drain.	Can be used to drive a keyboard backlight LED
OUT	8, 9	0	Power-path output. Connect to system main power rail (system power bus)	10-μF capacitor to AGND1 pin
PGND1	45	-	SM1 synchronous buck converter power ground	Connect to Power ground plane
PGND2	52	-	SM1 synchronous buck converter power ground	Connect to power ground plane
PGND3	38	_	White LED driver power ground input.	Connect to a power ground plane
PWM	34	0	PWM driver output, open drain.	Can be used to drive a vibrator or other external functions
RED	55	0	Programmable LED driver, open drain output, current sink output when active.	Connect to RED input of RGB LED
RESPWRON	21	0	System reset, open-drain output	100-k Ω external pullup resistor to OUT. RESPWRON pin is LO when TPS65810 is resetting the system.
RTC_OUT	4	0	Low leakage LDO output. Can be connected to a super-capacitor or secondary cell, if used as a RTC backup output.	1-μF (minimum) capacitor to AGND1 pin or supercapacitor
SCLK	2	Ι	I ² C interface clock line	$2 \cdot k\Omega$ pullup resistor to OUT pin
SDAT	3	I/O	I ² C interface data line	2-k Ω pullup resistor to OUT pin
SIM	5	0	General purpose LDO output	1-µF (minimum) capacitor to AGND1 pin
SM1	44	I	SM1 synchronous buck converter output voltage sense	LC filter: 10-µF capacitor to PGND1 pin
SM2	49	I	SM2 synchronous buck converter output voltage sense	LC filter: 10-µF capacitor to PGND2 pin
SM3	42	I	White LED driver output overvoltage detection	Connect 1- μ F capacitor to PGND3 pin. Connect SM3 pin to the positive side of white LED ladder.
SM3SW	40	I	Integrated white LED duty cycle switch input	Connect to negative side of external LED ladder
SYS_IN	31	I	System power bus low-voltage detection	External resistive divider sets minimum system operational voltage. TPS65810 enters sleep mode when voltage below minimum system voltage threshold is detected. 1-nF filter capacitor to AGND1 recommended.

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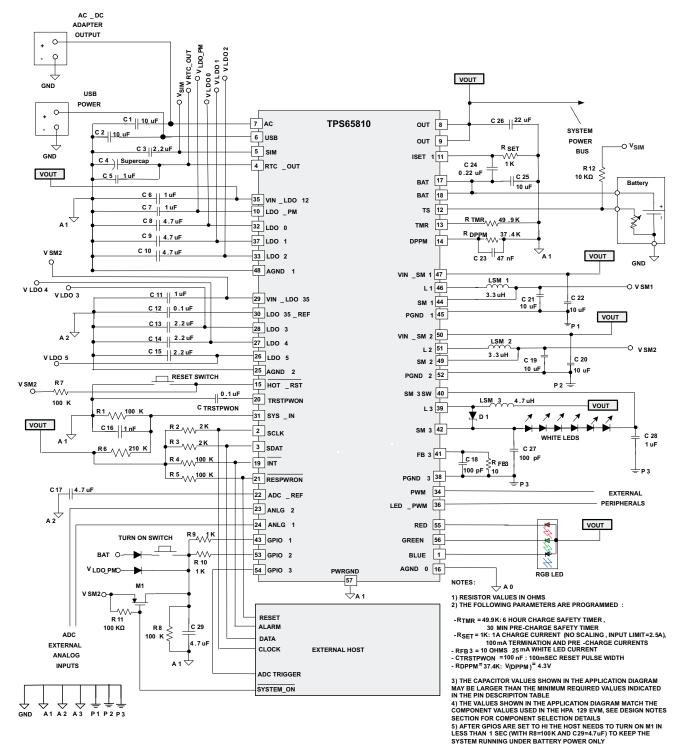


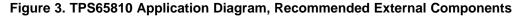
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NAME	PIN	I/O	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (SEE APPLICATION DIAGRAM)
TMR	13	I	Charge safety timer program input	External resistor from TMR pin to AGND1 pin sets the charge safety timer time-out value
TRSTPWON	20	I	System reset pulse-duration setting	100-nF (minimum) capacitor to AGND. External capacitor from TRSTPWON pin to AGND1 pin sets RESPWRON pulse duration.
TS	12	I/O	Temperature sense input, current source output	Connect to battery pack thermistor to sense battery pack temperature. Connect to external pullup resistor.
USB	6	I	USB charge input voltage, connect to USB port positive power output	1-μF (minimum) capacitor to AGND1 pin, to minimize overvoltage transients during USB power hot-plug events.
VIN_LDO35	29	-	Input to LDOs 3 to 5	1-µF (minimum) decoupling capacitor to AGND2
VIN_LDO02	35	-	Positive supply input for LDO0, LDO1, LDO2	$1{\mbox{-}}\mu F$ (minimum) decoupling capacitor to AGND1
VIN_SM1	47	_	SM1 synchronous buck converter positive supply input	10-μF capacitor to PGND1 pin
VIN_SM2	50	_	SM2 synchronous buck converter positive supply input	10-μF capacitor to PGND2 pin
Exposed thermal pad	57	_	exposed thermal pad must be connected to	etween the exposed thermal pad and AGNDn pins of the IC. The to the same potential as the AGND1 pin on the printed circuit primary ground input for the IC. AGNDn pins must be connected



APPLICATION DIAGRAM

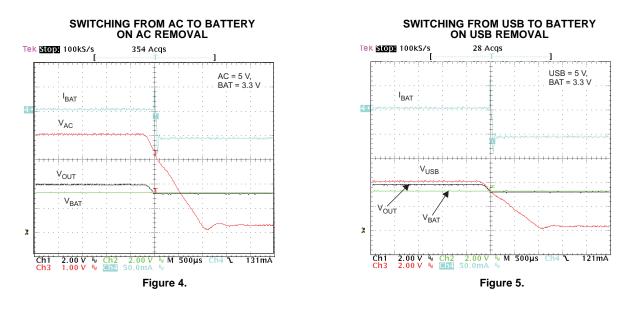






TYPICAL CHARACTERISTICS – POWER PATH MANAGEMENT

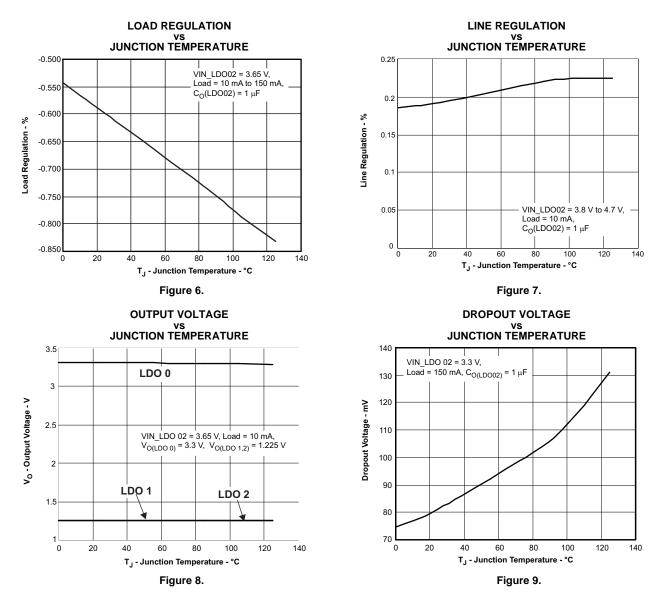
Measured with Application Circuit shown in Figure 3 (unless otherwise noted).





TYPICAL CHARACTERISTICS – LINEAR REGULATORS 0, 1, 2

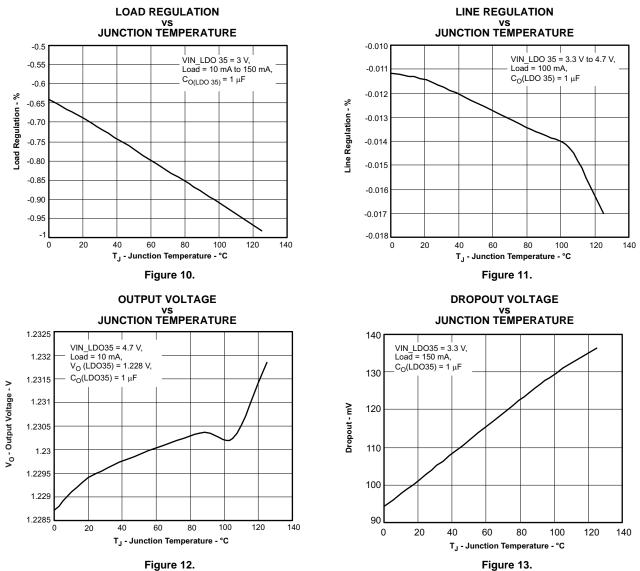
Measured with application circuit shown in Figure 3 (unless otherwise noted).





TYPICAL CHARACTERISTICS – LINEAR REGULATORS 3, 4, 5

Measured with application circuit shown in Figure 3 (unless otherwise noted).

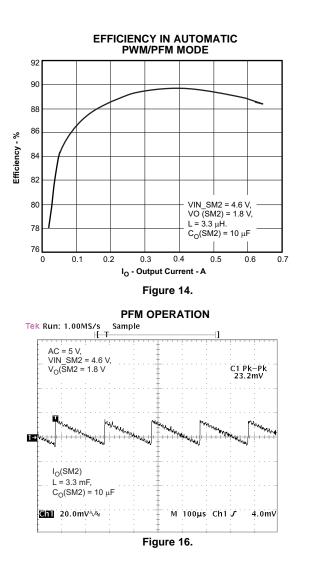


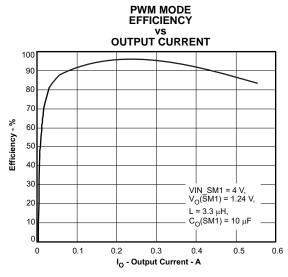
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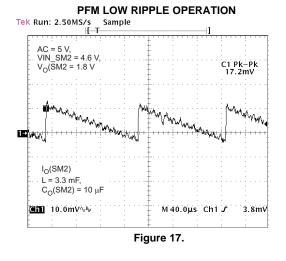
TYPICAL CHARACTERISTICS – SM1 AND SM2 BUCK CONVERTERS

Measured with application circuit shown in Figure 3 (unless otherwise noted).





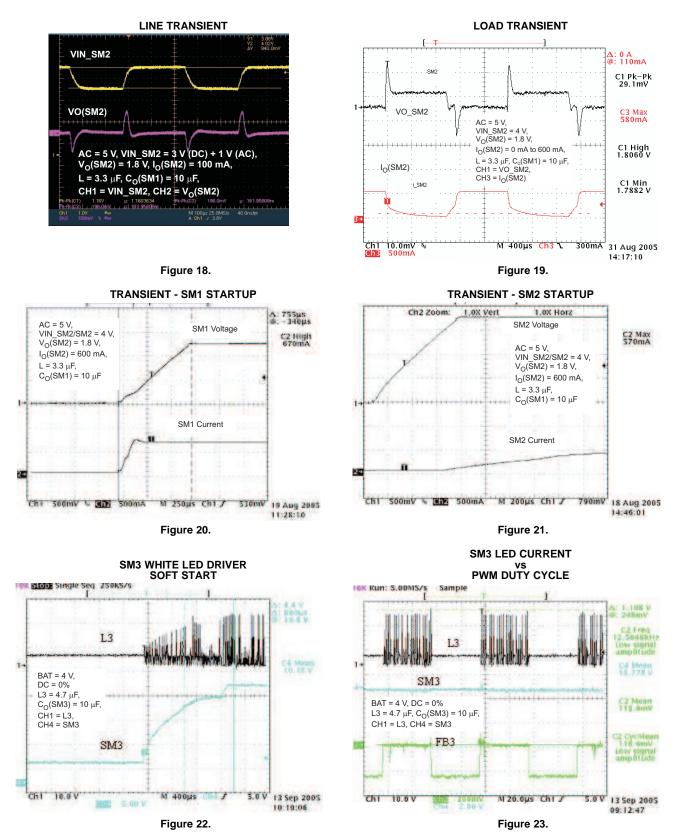






TYPICAL CHARACTERISTICS – DRIVERS

Measured with application circuit shown in Figure 3 (unless otherwise noted)





SERIAL INTERFACE

Overview

The TPS65810 is compatible with a host-controlled environment, with internal parameters and status information accessible via an I²C interface. An I²C communication port provides a simple way for an I²C compatible host to access system status information and reset fault modes, functioning as a SLAVE port enabling I²C compatible hosts to WRITE to or to READ from internal registers. The TPS65810 I²C port is a 2-wire bidirectional interface using SCL (clock) and SDA (data) pins; the SDA pin is open drain and requires an external pullup. The I²C is designed to operate at SCL frequencies up to 400 kHz. The standard 8 bit command is supported, the CMD part of the sequence is the 8 bit register address to READ from or to WRITE to.

Register Default Values

The internal TPS65810 registers are loaded during the initial power-up from an internal, non-volatile memory bank. The power-up default values are described in the sections detailing the registers functionality.

The register contents remain intact as long as OUT pin voltage remains above the internal UVLO threshold, V_{UVLO} . All register bits are reset to the internal power up default when the OUT pin voltage falls below the V_{UVLO} threshold or if the HOT_RESET pin is set to LO.

I²C Address

The I²C specification contains several global addresses, which the slaves on the bus are required to respond to. The TPS65810 only responds (ACK) to addresses: 0x90 and 0x91 and does not respond (NACK) to any other address.

BYTE				В	IT			
	MSB	6	5	4	3	2	1	LSB
TPS65810 I ² C WRITE ADDRESS	1	0	0	1	0	0	0	0
TPS65810 I ² C READ ADDRESS	1	0	0	1	0	0	0	1
I/O DATA BUS	B7	B6	B5	B4	B3	B2	B1	B0

Table 1. TPS65810 I²C Read/Write Address

Incremental Read

The TPS65810 does not support incremental read operations. Each register must be accessed in a single read operation.

I²C Bus Release

The TPS65810 I²C engine does not create START or STOP states on the I²C bus during normal operation.

Sleep Mode Operation

When the sleep mode is set SDAT is held LO by the TPS65810. The overall system operation is not affected, as in sleep mode all TPS65810 integrated supplies are disabled and no power is available for any external devices connected to the TPS65810 SDAT pin. When sleep mode ends the SDAT pin is released before the TPS65810 integrated regulated supplies are enabled. See section on *System Sequencing and TPS65810 Operating Modes* for additional details on sleep mode operation.

I²C Communication Protocol

The following conventions are used when describing the communication protocol:

Table 2. I²C Naming Conventions Used

CONDITION	CODE
START sent from host	S
STOP sent from host	Р
TPS65810 I ² C slave address sent from host, bus direction set from host to TPS65810 (WRITE)	hA0

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CONDITION	CODE
TPS65810 register address sent from TPS65810, bus direction is from TPS65810 to host (READ)	hA1
Non-valid I ² C slave address sent from host	hA_N
Valid TPS65810 register address sent from host	HCMD
Non-valid TPS65810 register address sent from host	HCMD_N
I/O data byte (8 bits) sent from host to TPS65810	hDATA
I/O data byte (8 bits) sent from TPS65810 to host	bqDATA
Acknowledge (ACK) from host	hA
Not acknowledge (NACK) from host	hN
Acknowledge (ACK) from TPS65810	bqA
Not acknowledge (NACK) from TPS65810	bgN

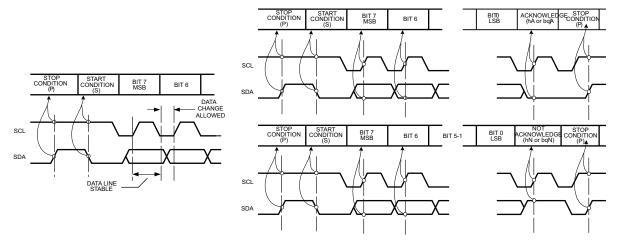


Figure 24. I²C operation waveforms

For normal data transfers, SDA is allowed to change only when SCL is low, and one clock pulse is used per bit of data. The SDA line must remain stable whenever the SCL line is high, as SDA changes when SCL is high are reserved for indicating the start and stop conditions. Each data transfer is initiated with a start condition and terminated with a stop condition.

When addressed, the TPS65810 device generates an acknowledge bit after the reception of each byte by pulling the SDA line Low. The master device (microprocessor) must generate an extra clock pulse that is associated with the acknowledge bit. After the acknowledge/not acknowledge bit the TPS65810 leaves the data line high, enabling a STOP condition generation.

I²C Read and Write Operations

The TPS65810 supports the standard I²C one byte Write. The basic I²C read protocol has the following steps:

- Host sends a start and sets TPS65810 I²C slave address in write mode
- TPS65810 ACK's that this is a valid I²C address and that the bus is configured for write
- Host sends TPS65810 register address
- TPS65810 ACK's that this is a valid register and stores the register address to be read
- Host sends a repeated start and TPS65810 I²C slave address, reconfiguring the bus for read
- TPS65810 ACK's that this is a valid address and that bus is reconfigured
- Bus is in read mode, TPS65810 starts sending data from selected register

The I²C write protocol is similar to the read, without the need for a repeated start and bus being set in write mode. In a WRITE, it is not necessary to end each 1-byte WRITE command with a STOP; a START has the same effect (repeated start).



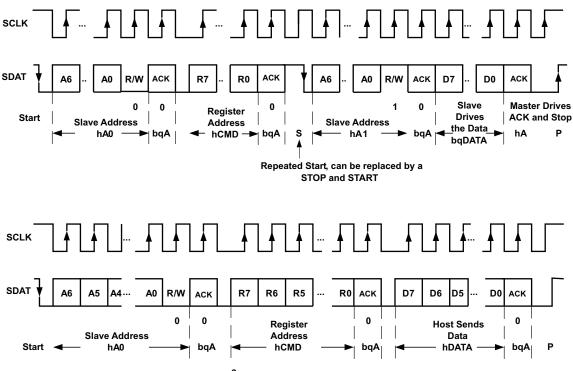


Figure 25. I²C read and write operations

The host can complete a READ or a WRITE sequence with either a STOP or a START.

Valid Write Sequences

The TPS65810 always ACKs its own address. If the CMD points to an allowable READ or WRITE address, bq writes the address into its RAM address register and sends an ACK. If the CMD points to a non-allowed address, bq does NOT write the address into its RAM address register and sends a NACK.

1	S	hA0	bqA		
	S	hA0	bqA	hCMD	bqA
	S	hA0	bqA	hCMD_N	bqN

One-Byte Write

The data is written to the addressed register when the bq ACK ending the one byte write sequence is received. The host can cancel a WRITE by sending a STOP or START before the trailing edge of the bq ACK clock pulse.

S NAU DQA NCMID DQA NDATA DQA	S	hA0	bqA	hCMD	bqA	hDATA	bqA
-------------------------------	---	-----	-----	------	-----	-------	-----

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Valid Read Sequences

The TPS65810 always ACKs its own address.

S	hA1	bqA
-		

Upon receiving hA1, TPS65810 starts at wherever the RAM address register is pointing. The START and the STOP both act as priority interrupts. If the host has been interrupted and is not sure where it left off it can send a STOP and reset the TPS65810 state machine to the WAIT state; once in WAIT state, the TPS65810 ignores all activity on the SCL and SDA lines until it receives a START. A repeated START and START in the I²C specification are both treated as a START.

S	hA0	bqA	hCMD	bqA	Р					
S	hA0	bqA	hCMD	bqA	S	hA1	bqA	bqDATA	hN	Р
S	hA1	bqA	bqDATA	hN	Р					

Non-Valid Sequences

Incremental read sequences

S hA1 bqA bqDATA hA bqDATA hA bqDA	ATA hA bqDATA hA bqDATA hA P
------------------------------------	------------------------------

START and non-hA0 or non-hA1 Address

A START followed by an address which is not bqA0 or bqA1 is NACKED.

S hA_N bqN	
------------	--

Attempt to Specify Non-Allowed READ Address

If the CMD points to a non-allowed READ address (reserved registers), bq sends a NACK back to the host, and it does not load the address in the RAM address register. Note that TPS65810 NACKS whether a stop is sent or not.

S	hA0	bqA	hCMD_N	bqN	Р
S	hA0	bqA	hCMD_N	bqN	

Attempt to Specify Non-Allowed WRITE Address

If the host attempts to WRITE to a READ-ONLY or non-accessible address TPS65810 ACKS the CMD containing the allowed READ address, loads the address into the address register and NACKS after the host sends the next data byte. After issuing the NACK TPS65810 returns to WAIT state. A subsequent hA1 READ could read this address.

S	hA0	bqA	hCMD	bqA	hDATA	bN

TPS65810 INTERNAL REGISTER MAP

hex	NAME	DESCRIPTION	ADDITIONAL DETAILS
0	RESERVED_01	RESERVED	FACTORY ONLY
1	RESERVED_02	RESERVED	FACTORY ONLY
2	PGOOD	Output voltage status for linear regulators and dc/dc buck converters	
3	INTMASK1	Interrupt request masking settings	
4	INTMASK2	Interrupt request masking settings	
5	INT_ACK1	Masked interrupt request register, latched	
6	INT_ACK2	Masked interrupt request register, latched	
7	PGOODFAULT_MASK	System Reset masking settings	
8	SOFT_RESET		
9	CHG_CONFIG	Battery charger configuration	
А	CHG_STAT	Battery charger status	
В	EN_LDO	Linear regulator ON/OFF control	
С	LDO12	LDO1 and LDO2 output voltage setting	
D	LDO3	LDO3 output voltage settings	
Е	LDO4	LDO4 output voltage settings	
F	LDO5	LDO5 output voltage settings	
10	SM1_SET1	SM1 Buck converter ON/OFF control and output voltage setting, normal mode	
11	SM1_SET2	SM1 Buck converter configuration	
12	SM1_STANDBY	SM1 Buck converter standby mode ON/OFF and standby output voltage setting	
13	SM2_SET1	SM2 Buck converter ON/OFF control and output voltage setting, normal mode	
14	SM2_SET2	SM2 Buck converter configuration	
15	SM2_STANDBY	SM2 Buck converter standby mode ON/OFF and standby output voltage setting	
16	SM3_SET	SM3 White LED driver ON/OFF control and settings	
17	RGB_FLASH	Overall RGB driver timing settings	
18	RGB_RED	RGB driver: RED duty cycle and output current setting	
19	RGB_GREEN	RGB driver: GREEN duty cycle and output current setting	
1A	RGB_BLUE	RGB driver: BLUE duty cycle and output current setting	
1B	GPIO12	GPIO1 and GPIO2 configuration	
1C	GPIO3	GPIO2 and GPIO3 configuration, battery charge voltage selection	
1D	PWM	PWM output configuration	
1E	ADC_SET	ADC On/OFF control, ADC configuration	
1F	ADC reading_hi	ADC data output	
20	ADC reading_lo	ADC data output	
21	DHILIM1	ADC Maximum threshold setting	
22	DHILIM2	ADC Maximum threshold setting	
23	DLOLIM1	ADC Minimum threshold setting	
24	DLOLIM2	ADC Minimum threshold setting	
25	ADC_DELAY	ADC configuration: conversion delay	
26	ADC_WAIT	ADC configuration: wait and repeat operation	
27	LED_PWM	LED_PWM configuration	
2E	RESERVED_03	RESERVED	FACTORY ONLY



FUNCTIONALITY REFERENCE GUIDE – HOST INTERFACE AND SYSTEM SEQUENCING

INTERRUPT CONTROLLER, OPEN-DRAIN OUTPUT (INT) System Parameters Monitored by Interrupt Controller						
SM1, SM2, SM3, LDO1, LDO2, LDO3, LDO4, LDO5	Thermal Fault or GPIO 1,2 configured as external interrupt request	ADC conversion end ADC Input out of range External resistive load connected to ANLG1	Charge: Pre↔ Fast ↔Done DPPM:on ↔ off Charge Suspend: on ↔ off Thermal Foldback: on ↔ off	AC detected: yes ↔ no USB detected: yes ↔ no Input OVP: yes ↔ no System Power: AC ↔ USB	All interrupt controller inputs set to non-masked	
Can be masked Individually via I ² C. Blanked during initial power up		Individually via I ² C		oup via a single I ² C mask ster bit		

(1) For all supplies (except) for SM3 an output fault is detected if the output voltage is below 90% of the programmed regulation voltage. In the SM3 converter an output fault indicates that the output OVP threshold was reached.

EVENTS TRIGGERING TPS65810 OPERATING MODE CHANGES					
EVENT	POWER GOOD FAULT DETECTION ⁽¹⁾	THERMAL FAULT	HARDWARE RESET	SOFTWARE RESET	
How transition is triggered	Integrated regulator output voltage below target value: SM1, SM2, SM3, LDO1, LDO2,LDO3, LDO4, LDO5	Internal IC junction temperature	Using HOT_RST control pin	I ² C register control bit	
Operating mode change	Sets Sleep mode or starts a new power-up cycle when power good fault is detected (see state machine diagram).	Sets Sleep mode when thermal fault is detected	Generates external host reset pulse at pin RESPWON when HOT_RST=LO.	Generates external host reset pulse at pin RESPWON when I ² C control bit is set.	
	Power good fault detection comparators are blanked during initial power-up.	Input and Battery power cycling required to exit sleep	Pulse duration set by external capacitor.	Pulse duration set by external capacitor.	
Controls	Can be masked Individually via I ² C.	Fixed Internal Threshold	External Input	Set via I ² C	

(1) For all supplies (except) for SM3 an output fault is detected if the output voltage is below 90% of the programmed regulation voltage. In the SM3 converter an output fault indicates that the output OVP threshold was reached.

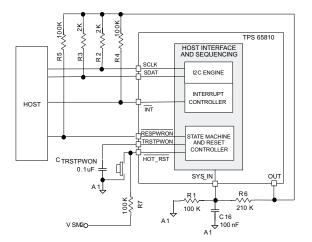


Figure 26. Required External Components, Recommended Values, External Connections



INTERRUPT CONTROLLER AND SYSTEM SEQUENCING

Overview

The TPS65810 has two dedicated internal controllers that execute the host interface and system sequencing tasks: a sequencing controller and an interrupt controller.

The sequencing controller monitors internal and system parameters and defines the sequencing of the internal power supplies during power up and power down / power fault events, and executes specific internal power supply reset operations under external hardware control or host software commands.

The following parameters are monitored by the sequencing controller:

- System power bus voltage (at SYS_IN pin), input supply voltage, battery pack voltage
- TPS65810 thermal fault status
- Integrated supply status

The interrupt controller monitors multiple system status parameters and signals to the host when one of the monitored parameters toggled, as a result of a system status change. The interrupt controller inputs include all the parameters monitored by the sequencing controller plus:

- Charger status
- Battery pack status
- ADC status

Internal I²C registers enable masking of all the monitored parameters. Using those registers, the host can select which parameters trigger an interrupt or a power-good fault. Power-good faults trigger a change in the TPS65810 operating mode, as detailed in the next sections.

A simplified block diagram for the TPS65810 sections that interface to the external host is shown in Figure 27.

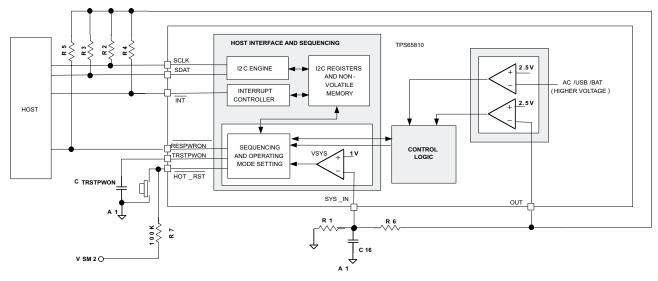
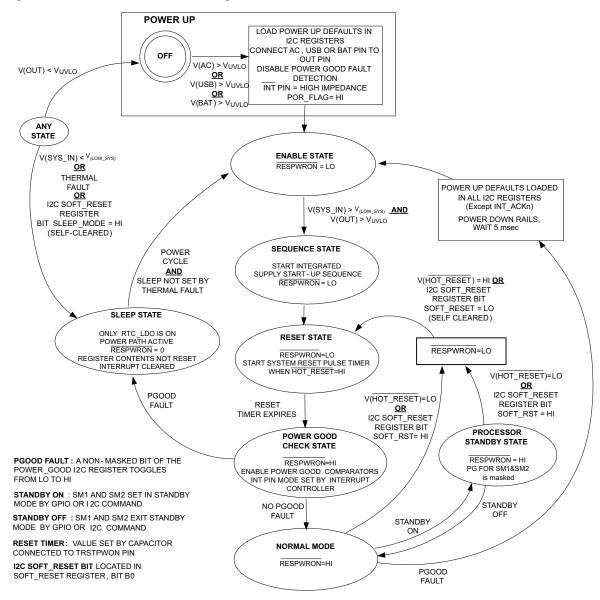


Figure 27. Simplified Block Diagram



SYSTEM SEQUENCING AND TPS65810 OPERATING MODES

The TPS65810 has a state machine that controls the device power up and power down sequencing. The main operating modes are shown in the state diagram below:





POWER UP – If the AC, USB and BAT pin voltages are below the internal UVLO threshold V_{UVLO} (2.5 V typ) all IC blocks are disabled and the TPS65810 is not operational, with all functions OFF. When an external power source or battery with voltage greater than the V_{UVLO} voltage threshold is applied to AC/USB or BAT pins the internal TPS65810 references are powered up, biasing internal circuits. When all the main internal supply rails are active the TPS65810 I²C registers are set to the power-up default values, shown below:

	0 11 9	•	•
SUPPLY	POWER-UP DEFAULT	OTHER BLOCKS	POWER-UP DEFAULT
LDO0	OFF, 3.3 V	POWER PATH	INPUT TO SYSTEM
LDO1	1.25V, OFF	PWM	OFF
LDO2	3.3 V, OFF	PWM_LED	OFF
LDO3	1.505 V, OFF	GPIO1	INPUT, SM1 ON/OFF CONTROL
LDO4	1.811 V, OFF	GPIO2	INPUT, SM2 ON/OFF CONTROL
LD05	3.111 V, ON	GPIO3	INPUT
SIM	2.5 V, ON	ADC	OFF
RTC_OUT	ON, 1.5 V	SM3 (WHITE LED)	OFF
LDO_PM	3.3 V, ON @ OUT POWERED	RGB DRIVER	OFF
SM1	OFF, 1.24 V	INTERRUPT MASK	NONE MASKED
SM2	OFF, 3.32 V	POWER GOOD MASK	ALL MASKED
CHARGER	OFF		

 Table 3. Integrated Supply and Drivers I²C Registers Power-Up Defaults

After the internal I²C register power-up defaults are loaded the power path control logic is enabled, connecting the external power source to the OUT pin. A status flag (nRAMLOAD) is set to LO in the SOFT_RESET register, indicating that the I²C registers were loaded with the power-up defaults, and the TPS65810 enters the ENABLE state.

ENABLE: In the ENABLE mode the RESPWRON output is set to the LO level, the INT pin mode is set to high impedance and all the power good comparators that monitor the integrated supply outputs are disabled. The ENABLE mode is used by the TPS65810 to detect when the main system power rail (OUT pin) is powered and ready to be used on the internal supply power-up. The OUT pin voltage is sensed by an internal low-system-voltage comparator which holds the IC in the ENABLE mode until the system power-bus voltage (OUT pin) has reached a minimum operating voltage, defined by the user. The internal comparator senses the system voltage at pin SYS_IN, and the threshold for the minimum system operating voltage is calculated as follows:

$$V(OUT) = V_{(LOW_SYS)} \times \left(1 + \frac{R6}{R1}\right)$$
:

where R6 and R1 are external resistors, $V_{(LOW SYS)} = 1 V$ typical

(1)

The minimum system operating voltage should always be set above the internal UVLO threshold V_{UVLO} . In normal application conditions the minimum system operating voltage is usually set to a value that assures that the TPS65810 integrated regulators are not operating in the dropout region.

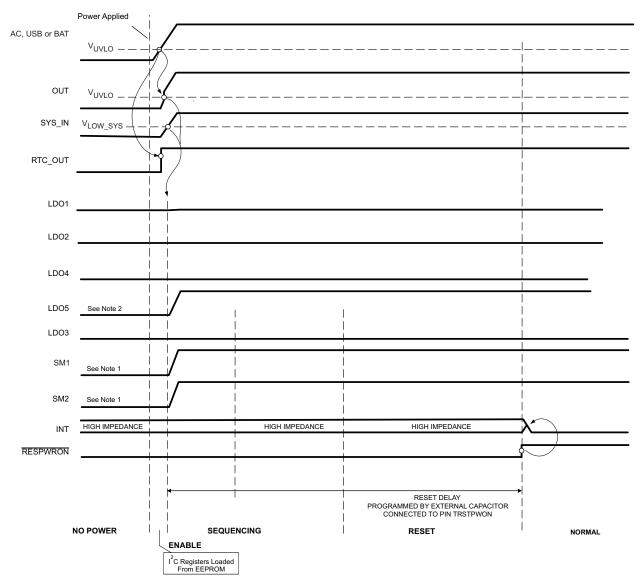
When the voltage at the SYS_IN pin exceeds the internal threshold $V_{(LOW_SYS)}$ the TPS65810 is ready to start the system power sequencing, and the SEQUENCING mode is entered.

SEQUENCING – The sequencing state starts immediately after the enable state. In this mode of operation the integrated supplies are turned ON. The TPS65810 sequencing timing diagram shown in figure details the internal timing delays and supply sequencing. At the end of the sequencing state the user-programmable reset timer is started, and the TPS65810 enters the reset state.

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- (1) SM1 and SM2 are externally enabled by GPIO1 and GPIO2. This waveform represents the earliest time that SM1 and SM2 are enabled if GPIO1 and GPIO2 are tied high.
- (2) LDO5, SM1, and SM2 are all enabled at the same time. This waveform represents the earliest time that LDO5 is enabled if VIN_LDO35 is connected to OUT. LDO5 power up can be synchronized to SM1 or SM2 by connecting VIN_LDO35 to the SM1 or SM2 output, respectively.

Figure 29. TPS65810 Supply Sequencing Timing

RESET – When the reset state starts the **RESPWRON** output is LO. The user can program the reset timer value selecting the value of the external capacitor connected to pin TRSTPWON, as shown below:

 $T_{(RESET)} = K_{RESET} \circ C_{TRSTPWON}$; where K_{RESET} is the reset timer constant (1 ms/nF typ)

The TPS65810 RESPWRON pin should be used to reset the external host. During the external host reset (RESPWRON = LO) the I²C SDA and SCL pins are not used to access TPS65810 internal registers. If a non-standard configuration is used to reset the system the SDA and SCL lines should not be used to communicate with the TPS65810 until RESPWRON = HI, in order to avoid overwriting the integrated power supply internal power-up settings during the sequencing mode.

The power good comparators are masked during the reset mode. The reset mode ends when the reset timer expires, and the TPS65810 goes into the power good check mode.

The RESPWRON signal set to a high level is the proper signal to use as an indicator that the device has transitioned out of the reset state. During the power-up sequence the RESPWRON pin is asserted LOW until the RESET TIMER expires. The RESET TIME ($t_{reset} = 1$ ms/nF × CTRSTPWON) can be programmed via a capacitor between the TRSTPWON pin and ground.

When the RESPWRON signal is LO, all internal and external interrupts are ignored. As a result, the open-drain output that asserts the INT pin LO during a NORMAL MODE interrupt request is disabled. The INT pin is then asserted HI via a pullup resistor that is typically connected to VOUT. After the RESPWRON signal goes HI, the interrupt controller is given control of the INT pin. Finally, the rising edge of the RESPWRON pin should be used to indicate the PMIC has transitioned from the RESET STATE to the POWER GOOD CHECK STATE. At that point, the interrupt controller asserts an interrupt if necessary.

POWER GOOD CHECK – In the power good check mode the power good comparators are enabled, providing status on the integrated supplies output voltages. An output voltage is considered as out of regulation and generates a fault condition if the output voltage is below 90% of the target output voltage regulation value. If a power good fault is detected the SLEEP mode is set, if a power good fault is not detected the NORMAL mode is set.

The individual supply power good status can be masked via an I²C register PGOODFAULT_MASK. Supplies that have their power-good fault status masked do not generate a power-good fault. However, the status bit for the supply indicates that the output voltage is out of regulation.

The power good mask register bits default to masked upon power up.

NORMAL MODE – If a power good fault is not present at the end of the power good check mode the NORMAL mode starts. In this mode of operation the I²C registers define the TPS65810 operation, and the host has full control on operation modes, parameter settings, etc. The normal state operation ends if a thermal fault, system low voltage fault ($V(SYS_IN) < V_{LOW_SYS}$) or power good fault is detected. A thermal fault or system low voltage fault sets the SLEEP mode operation, a power good fault sets the NO POWER operation mode. From the normal mode the converters SM1 and SM2 can be set in the STANDBY mode, with reduced output voltages. In NORMAL mode either an I²C register bit (SOFT_RESET register bit SOFT_RST) or a hardware input (HOT_RESET pin set to LO) can trigger a transition to the RESET state, enabling implementation of a host reset function. In NORMAL mode an I²C register bit (SOFT_RESET register bit SLEEP_MODE) can trigger a transition to SLEEP mode.

SLEEP MODE – The SLEEP mode is set when a thermal fault or system low voltage fault is detected, under NORMAL operation mode set. This operation mode is also set when a power good fault is detected during the power good check state or via the I²C bit SLEEP_MODE. In the SLEEP mode the RESPWRON output is set to LO, and the I²C registers keep the same contents as in the state preceding SLEEP mode, with the exception of the following control bits, which are reset to the default power-up values:

- 1. LDO1,2,3,4,5 and RTC_OUT are enabled, SIM LDO is disabled: EN_LDO register set to default values
- 2. LDO0 disabled, all GPIO's with no control function assigned: GPIO12, GPIO3 registers set to default values
- 3. White LED driver is set to OFF: SM3_SET register has all bits set to LO
- 4. RGB drivers are set to OFF: RGB_FLASH, RGB_RED, RGB_GREEN, RGB_BLUE registers are set to default values
- 5. PWM, PWM_LED drivers OFF: PWM, LED_PWM registers are set to default values
- 6. ADC engine reset to power up default: ADC_SET, ADC_DELAY, ADC_WAIT registers are set to default values

In SLEEP mode the power path and main internal blocks are still active, but the internal integrated supply sequencing is disabled. As a result of that, during SLEEP mode ALL integrated supplies (ALL LDO's, ALL buck Converters) are disabled.

At the end of the SLEEP mode, the sequencer block uses the I²C control register values (which were reset to the default power-up values) to sequence the integrated power supplies. The SLEEP mode ends when one of the three following events happens:

- 1. *If SLEEP was set by thermal fault:* The SLEEP mode ends only when all external input supplies and battery pack are removed and a UVLO condition is detected by the TPS65810, setting the NO POWER mode.
- 2. If SLEEP was set by a system low voltage detection, or I²C bit SLEEP_MODE, only with battery present: Input power must be connected, setting the TPS65810 in the ENABLE mode. If no input power is inserted, the battery discharges until the TPS65810 detects a UVLO condition and enters the NO POWER mode.



3.) If sleep was set by a system low voltage detection, power good fault or SLEEP_MODE, with battery and input power present: all external input supplies connected to AC and USB pins must be removed, and then at least one of them reconnected to the system. The input power cycling triggers a transition from SLEEP mode to the ENABLE mode.

PROCESSOR STANDBY STATE – This state is set using an I²C register or a GPIO configured as SM1/SM2 standby control. In standby mode operation, the SM1 and SM2 voltages are set to value distinct than the normal mode output voltage, and SM1/SM2 are set to PFM mode. The standby output voltage is defined in I²C registers SM1_STANDBY and SM2_STANDBY.

TPS65810 OPERATING MODE CONTROLS

HARDWARE RESET: A dedicated control pin, $\overline{\text{HOT}_\text{RESET}}$, enables implementation of a hardware reset function. The system reset pin $\overline{\text{RESPWRON}}$ is set to LO when $\overline{\text{HOT}_\text{RESET}} = LO$ for a period longer than the internal deglitch (5mSec typ). The RESET mode is started when the $\overline{\text{HOT}_\text{RESET}}$ pin transitions from LO to HI, as shown in the state diagram. When $\overline{\text{HOT}_\text{RESET}} = LO$ all I²C registers are reset to the default power-up values.

SOFTWARE RESET: The external host can set the TPS65810 in RESET mode using the I²C register SOFT_RESET, bit B0 (SOFT_RST).

SOFTWARE SLEEP: The external host can set the TPS65810 in SLEEP mode using the I²C register SOFT_RESET, bit B6 (SLEEP_MODE).

A software reset does not affect the contents of the I²C registers.

SEQUENCING AND OPERATING MODES – I²C REGISTERS

The I²C registers that control sequencing-related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values.

SOFT_RESET,	ADDRESS=08, AL	L BITS R/W, BITS	6 B7/B6/B1/B0 A	PPLY TO SEQUE	NCING.			
	B7	B6	B5	B4	B3	B2	B1	B0
Bit name	STBY MODE	SLEEP MODE	NOT USED	NOT USED	SM3_LF_OSc	NOT USED	nRAMLOAD	SOFT RST
Function	SET SM1 AND SM2 IN STANDBY MODE	SET TPS65810 IN SLEEP MODE	NOT USED	NOT USED	NOT RELATED TO SEQUENCING SEE SM3	NOT USED	RAM RESET FLAG	SOFTWARE RESET CONTROL
When 0	NOT ACTIVE	NOT ACTIVE	NOT USED	NOT USED	SECTION	NOT USED	RAM DEFAULTS LOADED	NOT ACTIVE
When 1	When 1 SET SM1 AND SM2 IN STANDBY	SET SLEEP MODE (reset to LO internally)	NOT USED	NOT USED		NOT USED	RAM DEFAULTS NOT LOADED	SET RESET MODE (reset to LO internally)

Some host algorithms need to identify when the power-up defaults are loaded in the RAM, in order to start routines that initialize specific RAM registers. If that functionality is required the nRAMLOAD bit should be set to HI by the host when entering the NORMAL operation mode. The nRAMLOAD bit is reset to LO by the TPS65810 when the power-up defaults are loaded in the I²C registers (V(OUT) < V_{UVLO} OR V(HOT_RESET) = LO), enabling the host algorithm to detect that the RAM registers need to be initialized.

The integrated supplies status is available in a dedicated register, shown below. The host can select which integrated supply outputs trigger a power-good fault condition using the PGOODFAULT_MASK register. When a non-masked power-good status register bit toggles state, the sequence controller generates a transition in the TPS65810 state machine, indicated as a PGOOD FAULT in TPS65810 state diagram. The power-good status register are shown below:

SYSTEM STAT	SYSTEM STATUS MONITORED BY SEQUENCING CONTROLLER									
	B7	B6	B5	B4	B3	B2	B1	B0		
PGOOD, ADDF	RESS=02, ALL BITS	BITS READ ONLY - POWER UP DEFAULTS SHOW SYSTEM STATUS WHEN EXITING POWER DOWN								
Bit name	PGOOD SM1	PGOOD SM2	PGOOD SM3	PGOOD LDO1	PGOOD LDO2	PGOOD LDO3	PGOOD LDO4	PGOOD LDO5		
Function	SM1 OUTPUT STATUS	SM2 OUTPUT STATUS	SM3 OVP STATUS	LDO1 OUTPUT STATUS	LDO2 OUTPUT STATUS	LDO3 OUTPUT STATUS	LDO4 OUTPUT STATUS	LDO5 OUTPUT STATUS		

SYSTEM STATUS MONITORED BY SEQUENCING CONTROLLER R7 R6 **B**5 R4 **B**3 B2 **B1 B0** When 0 οк Оĸ ОK OK ΟK OK ОK ОK When 1 FAULT FAULT FAULT FAULT FAULT FAULT FAULT FAULT PGOODFAULT_MASK, ADDRESS=07, ALL BITS R/W Bit name MASK PSM1 MASK PSM2 MASK PSM3 MASK PLDO1 MASK PLDO2 MASK PLDO3 MASK PLDO4 MASK PLDO5 MASK PGOOD MASK PGOOD Function MASK PGOOD MASK MASK PGOOD MASK PGOOD MASK PGOOD MASK PGOOD FAULT BY SM1 PGOOD FAULT BY SM3 LDO1 LDO2 LDO3 LDO4 LDO5 SM2 When 0 UNMASKED UNMASKED UNMASKED UNMASKED UNMASKED UNMASKED UNMASKED UNMASKED MASKED MASKED MASKED MASKED MASKED MASKED MASKED MASKED When 1

INTERRUPT CONTROLLER

The TPS65810 has internal block and overall system status information stored in I²C status registers. The following subsystems and system parameters are monitored:

- External power supply status: AC or USB supply detected, AC or USB connected to system, AC/USB OVP
- Charger status: on/off/suspend, fast charge/pre-charge, termination detected, DPPM on, thermal loop ON
- Battery pack status: temperature, discharge on/off
- TPS65810 thermal shutdown
- ADC status: conversion status, input out of range, ANLG1 high impedance detection
- Integrated supplies status: output out of regulation (power good fault)

The GPIO1 and GPIO2 pins can be configured as inputs, generating an interrupt request to the host ($\overline{INT}:HI \rightarrow LO$) at the GPIO rising or falling edge. The host can use internal the INT_MASK I²C registers to define which of the monitored status variables triggers an interrupt. When a non-masked system status bit toggles state, the interrupt controller issues an interrupt, following the steps below:

- 1. system status bits that caused the interruption are set to HI in registers INT_ACK1 and INT_ACK2
- 2. An interrupt is sent to the host ($\overline{INT}:HI \rightarrow LO$)

Once an interrupt is sent to the host, \overline{INT} is kept in the LO state and the INT_ACK register contents are latched, holding the system status that generated the currently issued interrupt request. When an interrupt request is active ($\overline{INT} = LO$) additional changes in non-masked status registers and control signals are ignored, and the INT_ACK registers are not updated.

The host must write a 0 to the INT_ACK register bit that generated the interrupt in order to set \overline{INT} = HI and enable new updates to the INT_ACK registers. If the host stops in the middle of a WRITE or READ operation, the \overline{INT} pin stays at the LO level. The TPS65810 has no reset timeout; it is assumed that the host does not leave \overline{INT} = LO and the status registers unread for a long time.

The non-masked I²C register bits and internal control signals generate a new interrupt only after INT is set to HI. The non-masked power-good fault register bits generate a power-good fault when any of the non-masked bits detects that the monitored output voltage is out of regulation, independently of the INT pin level.

SYSTEM STATUS — I²C REGISTERS

The I²C registers that have system status data are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Those registers are valid, after an initial power up, when the TPS65810 enters the normal operation mode.

	B7	B6	B5	B4	B3	B2	B1	B0
PGOOD, ADDRESS=02, ALL BITS READ ONLY - POWER UP DEFAULTS SHOW SYSTEM STATUS WHEN EXITING POWER DOWN								
Bit name	PGOOD SM1	PGOOD SM2	PGOOD SM3	PGOOD LDO1	PGOOD LDO2	PGOOD LDO3	PGOOD LDO4	PGOOD LDO5
Function	SM1 OUTPUT STATUS	SM2 OUTPUT STATUS	SM3 OVP STATUS	LDO1 OUTPUT STATUS	LDO2 OUTPUT STATUS	LDO3 OUTPUT STATUS	LDO4 OUTPUT STATUS	LDO5 OUTPUT STATUS
When 0	OK	ОК	OK	ОК	ОК	OK	OK	ОК
When 1	FAULT	FAULT	FAULT	FAULT	FAULT	FAULT	FAULT	FAULT



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SYSTEM STATUS MONITORED BY INTERRUPT CONTROLLER									
	B7	B6	B5	B4	B3	B2	B1	B0	
REGISTER ADC_READING_HI, B7: CONVERSION COMPLETE; INTERNAL STATUS BITS (NO I ² C REGISTER BIT AVAILABLE: INPUT OUT OF RANGE (HI OR LO), ANLG1 PIN IMPEDANCE TO AGND2 EXCEEDS 1 mΩ. See additional details in the <i>Analog-to-Digital Converter</i> section.								EXCEEDS 1 mΩ.	
OTHER SYST	TEM STATUS: THER	MAL FAULT DET	ECTED						

INTERRUPT CONTROLLER – I²C REGISTERS

The I²C registers that control an interrupt generation (INT: HI \rightarrow LO) are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values.

INTERRUFTAN	ND POWER GOOL	FAULI MANAGI	EMENT REGISTE	RS				
	B7	B6	В5	B4	B3	B2	B1	B0
INTMASK1, AD	DRESS=03, ALL E	BITS R/W						
Bit name	MASK_ISM1	MASK_ISM2	MASK_ISM3	MASK_ILDO1	MASK_ILDO2	MASK_ILDO3	MASK_ILDO4	MASK_ILDO5
Function	MASK INT by SM1 PGOOD FAULT	MASK INT by SM2 PGOOD FAULT	MASK INT by SM3 PGOOD FAULT	MASK INT by LDO1 PGOOD FAULT	MASK INT by LDO2 PGOOD FAULT	Mask INT by LDO3 PGOOD FAULT	MASK INT by LDO4 PGOOD FAULT	MASK INT by LDO5 PGOOD FAULT
When 0	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED
When 1	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED
INTMASK2, AD	DRESS=04, ALL E	BITS R/W			L			
Bit name	MASK_IADC	MASK_IANLG1	MASK_IGPIO2	MASK_IGPIO1	MASK_ITHSHU T	MASK_ICHGS T	MASK_IADC_H	MASK_IADC_L O
Function	MASKS INT BY ADC END OF CONVERSION	MASKS INT BY ANLG1 HIGH IMPEDANCE	MASKS INT BY GPIO2 EDGE TRANSITION	MASKS INT BY GPIO1 EDGE TRANSITION	MASKS INT BY THERMAL FAULT	MASK INT BY CHG_STAT REGISTER BITS	MASK INT BY ADC INPUT ABOVE HI LIMIT	MASK INT BY ADC INPUT BELOW LO LIMIT
When 0	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED
When 1	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED
INT_ACK1, AD	DRESS=05, ALL B	BITS R/W			L			
Bit name	ACK_SM1	ACK_SM2	ACK_SM3	ACK_LDO1	ACK_LDO2	ACK_LDO3	ACK_LDO4	ACK_LDO5
Function	SM1 INT REQUEST	SM2 INT REQUEST	SM3 INT REQUEST	LDO1 INT REQUEST	LDO2 INT REQUEST	LDO3 INT REQUEST	LDO4 INT REQUEST	LDO5 INT REQUEST
When 0	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG
When 1	SM1 PGOOD FAULT GENERATED INT	SM2 PGOOD FAULT GENERATED INT	SM3 OVP FAULT GENERATED INT	LDO1 PGOOD FAULT GENERATED INT	LDO2 PGOOD FAULT GENERATED INT	LDO3 PGOOD FAULT GENERATED INT	LDO4 PGOOD FAULT GENERATED INT	LDO5 PGOOD FAULT GENERATED INT
INT_ACK2, ADI	DRESS=06, ALL B	SITS READ ONLY	r	r				r
Bit name	ACK_ADC	ACK_ANLG1	ACK_GPIO2	ACK_GPIO1	ACK_THSHUT	ACK_CHGSTA T	ACK_ADC_HI	ACK_ADC_LO
Function	ADC INT REQUEST 1	ANLG1 COMPARATO R INT REQUEST	GPIO2 INT REQUEST	GPIO1 INT REQUEST	THERMAL FAULT INT REQUEST	CHARGER INT REQUEST	ADC INT REQUEST 2	ADC INT REQUEST 3
When 0	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG	CLEAR FLAG
When 1	ADC DONE GENERATED INT REQUEST	ANLG1 HIGH IMPEDANCE DETECTION GENERATED INT REQUEST	GPIO2 EDGE GENERATED INT REQUEST	GPIO1 EDGE GENERATED INT REQUEST	THERMAL FAULT GENERATED INT REQUEST	CHARGER STATUS CHANGE GENERATED INT REQUEST	ADC INPUT ABOVE HI LIMIT GENERATED INT REQUEST	ADC INPUT BELOW LO LIMIT GENERATED INT REQUEST
PGOODFAULT	_MASK, ADDRES	S=07, ALL BITS F	R/W					
Bit name	PGOOD SM1	PGOOD SM2	PGOOD SM3	PGOOD LDO1	PGOOD LDO2	PGOOD LDO3	PGOOD LDO4	PGOOD LDO5
Function	MASK PGOOD FAULT BY SM1	MASK PGOOD FAULT BY SM2	MASK PGOOD FAULT BY SM3	MASK PGOOD FAULT BY LDO1	MASK PGOOD FAULT BY LDO2	MASK PGOOD FAULT BY LDO3	MASK PGOOD FAULT BY LDO4	MASK PGOOD FAULT BY LDO5
When 0	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED	UNMASKED
When 1	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED	MASKED

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FUNCTIONALITY GUIDE — SYSTEM POWER AND CHARGE MANAGEMENT

	CHARGE MANAGEMENT										
Fast (Charge ⁽¹⁾	Precharge	Termi	nation	Charge	Precharge	SafetyTimer	Power Up Default			
Charge Current Value	Charge Current Scaling	Current	Current	Current Scaling	Voltage	Voltage	Timeout				
I _{O(BAT)} , Programmable, 1.5A max	25%, 50%, 75%, 100% of I _{O(BAT)}	10% of I _{O(BAT)}	I(TERM), 10% of I _{O(BAT)}	25%, 50%, 75%, 100% of I _(TERM) value	4.2 V or 4.36 V	3.0 V	Programmable	Charger OFF			
Set via external resistor	Set via I ² C	Fixed ratio	Fixed ratio	Set via I ² C	Set via I ² C	Fixed	Set via external resistor				

(1) The input current limit (see system power management below) regulates the input current, effectively limiting the charge current if the input current limit is lower than the fast charge current value programmed.

	POWER PATH MANAGEMENT							
INPUT C	URRENT LIMIT	INPUT CONNECTED TO OUT P	POWER UP DEFAULT					
AC PIN	USB PIN	INPUT POWER TO SYSTEM	BATTERY TO SYSTEM					
2.5 A typ	100 mA max or 500 mA max or 2.5 A typ	 #1 – AC #2 – USB #3 – Battery (when AC pin power and USB pin power are not detected) 	Battery connected to system, independently of battery voltage	Input Power to System, USB mode selected, 100 mA max				
Internal fixed current limit	Set via I ² C	Automatic internal algorithm	Set via l ² C, overrides internal algorithm					

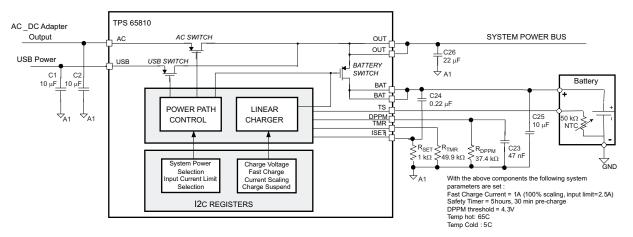


Figure 30. Required External Components, Recommended Values, External Connections

POWER PATH AND CHARGE MANAGEMENT

Overview

The TPS65810 has an integrated charger with power path integrated MOSFETs. This topology, shown in the simplified block diagram below, enables using an external input power to run the system and charge the battery simultaneously. The power path has dual inputs that can be used to select either an external AC_DC adapter (AC pin) or an USB port power (USB pin) to power the end equipment main power rail (OUT pin, also referred to as the system power bus) and charge the battery pack (connected to BAT pin).



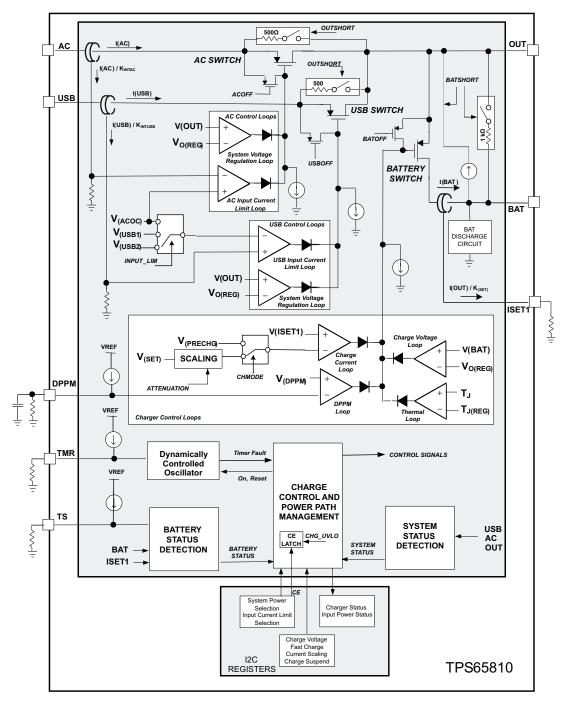


Figure 31. TPS65810 Charger and Power Path Section Simplified Block Diagram

The power path has three integrated power MOSFETs: the battery to system MOSFET (battery switch), the AC input to system MOSFET (AC switch) and the USB input to system MOSFET (USB switch). Each of those power MOSFETs can be operated either as an ON/OFF switch or as a linear pass element under distinct operating conditions, as defined by the control circuits that set the power MOSFET gate voltage.

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The TPS65810 regulates the voltage at the OUT pin to 4.6 V when one of the external supplies connected to pins AC or USB is powering the OUT pin. The selected input (AC or USB pin) current is limited to a value defined by I²C register settings. The input current limit function assures compatibility with USB standard requirements, and also implements a protection function by limiting the maximum current supplied by an external AC_DC adapter or USB port power terminal.

The AC power MOSFET and USB power MOSFET operating modes are set by integrated control loops. Each of the power MOSFETs is controlled by two loops: one system voltage regulation loop and one input current limiting loop. The integrated loops modulate the AC or USB power MOSFETs drain to source resistance to regulate either the OUT pin voltage or to limit the input current. If no input power is present (AC and USB input power not detected) the AC and USB power MOSFETs are turned OFF, and the battery MOSFET is turned ON, connecting the BAT pin to the OUT pin.

The battery switch is turned ON when the AC or USB input power is detected and the charger function is enabled, charging the battery pack. During charge the battery MOSFET switch operation mode is defined by the charger control loops. The battery MOSFET switch drain-to-source resistance is modulated by the charge current loop and charge voltage loop in order to implement the battery charging algorithm. In addition to that multiple safety functions are activated (thermal shutdown, safety timers, short circuit recovery), and additional functions (thermal loop and DPPM loop) optimize the charging process.

POWER PATH MANAGEMENT FUNCTION

Detecting the System Status

The power path and charge management block operate independently of the other TPS65810 circuits. Internal circuits check battery parameters (pack temperature, battery voltage, charge current) and system parameters (AC and USB voltage, battery voltage detection), setting the power path MOSFETs operating modes automatically. The TPS65810 has integrated comparators that monitor the battery voltage, AC pin voltage, USB pin voltage and the OUT pin voltage. The data generated by those comparators is used by the power path control logic to define which of the integrated power path switches are active. A simplified block diagram for the system status detection is shown below.

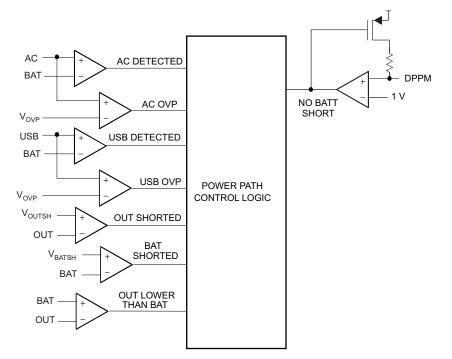


Figure 32. TPS65810 Systems Status Detection, Charger and Power Path Section

Table 4 lists the system power detection conditions. V_{IN(DT)}, V_{OUTSH}, V_{BATSH}, V_{OVP} are TPS65810 internal references, refer to the electrical characteristics for additional details.



AC input voltage detected	$V(AC) - V(BAT) > V_{IN(DT)}$
USB input voltage detected	$V(USB) - V(BAT) > V_{IN(DT)}$
AC overvoltage detected	V(AC) > V _{OVP}
USB overvoltage detected	V(USB) > V _{OVP}
AC PIN TO OUT pin OR USB TO OUT PIN short detected	V(OUT) < V _{INOUTSH}
BAT pin to OUT pin short detected	V(BAT) - V(OUT) > V _{BATOUTSH}
Battery supplement mode need detected	$V(BAT) - V(OUT) > V_{SUP}$
Blank BAT to OUT short circuit detection	V(DPPM) < 1V

Table 4. System Status Detection, Charger and Power Path Section

Power Path Logic: Priority Algorithm

The system power bus supply is automatically selected by the power path control logic, following an internal algorithm. The power path function detects an external input power connection when the input voltage exceeds the battery pack voltage. It also detects a supplement mode need (battery switch must be turned ON) when the system voltage (OUT pin) is below the battery voltage. A connected and non-selected external supply or the battery is automatically switched to the system bus, following the priority algorithm, when the external supply currently selected is disconnected from the system.

The input power priority is hard-wired internally, with the AC input having the higher priority, followed by the USB input (2nd) and the battery pack (3rd). Using the I²C CHG_CONFIG register control bit CE the user can override the power path algorithm, connecting the battery to the system power bus. Care must be taken when using the battery-to-system connection option, as the system power bus **is not** connected back to the AC or USB inputs (even if those are detected) when the battery is removed. Table 5 describes the priority algorithm.

CE BIT (I ² C CHG_CONFIG Register)	EXTERNAL DETE			SW	ITCH MODE	SYSTEM POWER SOURCE	
	AC	USB	AC	USB	Battery		
HI	YES	NO	ON	OFF	ON if Supplement mode is	AC	
	NO	YES	OFF	ON	required, OFF otherwise	USB	
	YES	YES	ON	OFF		AC	
	NO	NO	OFF	OFF	-	BATTERY	
LO	XX	XX	OFF	OFF	ON	BATTERY	

Table 5. Power Path Control Logic Priority Algorithm

The power path status is stored in register CHG_STAT.

Input Current Limit

The USB input current is limited to the maximum value programmed by the host, using the I²C interface. If the system current requirements exceed the input current limit, the output voltage collapses, the charge current is reduced, and finally, the supplement mode is set. The input current limit value is set with the I²C charge control register bits PSEL and ISET2, and it is applied to the USB input ONLY. The AC input current limit is fixed to the internal short circuit limit value.

	-	-	
PSEL (I ² C)	ISET2 (I ² C)	INPUT CURRENT LIMIT	
		USB	AC
LO	LO	100 mA	2.75 A
LO	HI	500 mA	2.75 A
Н	LO	2.75 A	2.75 A
HI	HI	2.75 A 2.75 A	

Table 6. Charge Current Scaling via I²C



System Voltage Regulation

The system voltage is regulated to a fixed voltage when one of the input power supplies is connected to the system. The system voltage regulation is implemented by a control loop that modulates the selected switch Rds(on).

The typical system regulation voltage is 4.6 V.

Input Overvoltage Detection

The AC and USB input voltages are monitored by voltage comparators that identify an overvoltage condition. If an overvoltage condition is detected a status register bit is set, indicating a potential fault condition.

When an overvoltage condition is detected, the AC or USB switches state is not modified. If any of those switches was ON, it is kept in the ON state. During overvoltage conditions, the system voltage is still regulated, and no major safety issues are observed when not modifying the input switch state.

If the input overvoltage condition results in excessive power dissipation, the thermal shutdown circuit is activated, the AC and USB switches are turned OFF, and the BAT switch is turned ON.

Output Short-Circuit Detection

If the OUT pin voltage falls below an internal threshold $V_{INOUTSH}$ the AC and USB switches are turned off and internal pullup resistors are connected from AC pin to OUT pin and USB pin to OUT pin. When the short circuit is removed those resistors enable the OUT pin voltage to rise above the $V_{INOUTSH}$ threshold, returning the system to normal operation.

Battery Short-Circuit Detection

If the OUT pin voltage falls below the BAT pin voltage by more than an internal threshold $V_{BATOUTSH}$ the battery switch is turned off and internal pullup resistor is connected between the OUT pin and the BAT pin. This resistor enables detection of the short removal, returning the system to normal operation.

Initial Power Path Operation

During the initial TPS65810 power-up the contents of the ISET2, CE and SUSPEND bits on the control register are immediately implemented. The charger is disabled (SUSPEND=LO) and the selected input current limit is set internally to 500 mA max.

No-Battery Detection Circuit

The ANLG1 pin may be used to detect the connection of an external resistor that is embedded in a battery pack and is used as a pack ID function. The ANLG1 pin has an internal current source connected between OUT and ANLG1, which is automatically enabled when the TPS65810 is not in SLEEP mode. The current levels for ANLG1 pin can be programmed via I²C register ADC_WAIT, bits BATID_n, as shown below:

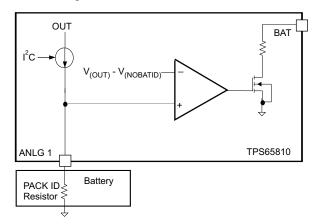


Figure 33. Battery Removal Detection, ANLG1 Pin



An internal comparator with a fixed deglitch time, t $_{DGL(NOBAT)}$ monitors the ANLG1 pin voltage, if V(ANLG1) > V(OUT) - V_{NOBATID} a battery removed condition is detected and an internal discharge switch is activated, connecting an internal resistor from BAT pin to AGND1. Note that ANLG1 can also be used as an analog input for the ADC converter, in this case the voltage at pin ANLG1 must never exceed the V(OUT) - V_{NOBATID} threshold to avoid undesired battery discharge.

Using the Input Power to Run the System and Charge the Battery Pack

The external supply connected to AC or USB pins must be capable of supplying the system power and the charger current. If the external supply power is not sufficient to run the system and charge the battery pack the TPS65810 executes a two-stage algorithm that prevents a low voltage condition at the system power bus:

- 1. The charge current is reduced, until the total (charger + system current) is at a level that can be supplied by the external input supply. This function is implemented by a dedicated charger control loop (see DPPM section in charger functional description for additional details).
- 2. The battery switch is turned ON if the charge current is reduced to zero and the input current is not enough to run the system. In this mode of operation both the battery and the external input power supply the system power (supplement operation mode).

The supplement operation mode is automatically set by the TPS65810 when the input power is switched to the OUT pin, and the OUT pin voltage falls below the battery voltage.

BATTERY CHARGE MANAGEMENT FUNCTION

Operating Modes

The TPS65810 supports charging of single-cell Li-Ion or Li-Pol battery packs. The charge process is executed in three phases: pre-charge (or pre-conditioning), constant current and constant voltage.

The charge parameters are selectable via I²C interface and using external components. The charge process starts when an external input power is connected to the system, the charger is enabled by the I²C register CHG_CONFIG bits CE=HI and CHGON=HI, and the battery voltage is below the recharge threshold, V(BAT) < $V_{(RCH)}$. When the charge cycle starts a safety timer is activated. The safety timer timeout value is set by an external resistor connected to the TMR pin.

When the charger is enabled two control loops modulate the battery switch drain to source impedance to limit the BAT pin current to the programmed charge current value (charge current loop) or to regulate the BAT pin voltage to the programmed charge voltage value (charge voltage loop). If V(BAT) < 3 V (typ) the BAT pin current is internally set to 10% of the programmed charge current value. A typical charge profile is shown below, for an operation condition that does not cause the IC junction temperature to exceed 125°C (typ).

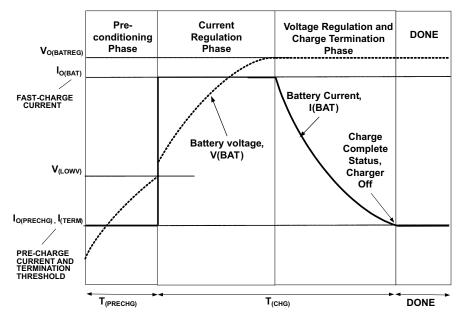
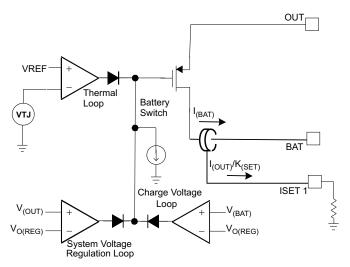


Figure 34. Typical Charge Cycle, Thermal Loop not Active

If the operating conditions cause the IC junction temperature to exceed 125°C the charge cycle is modified, with the activation of the integrated thermal control loop. The thermal control loop is activated when an internal voltage reference, which is inversely proportional to the IC junction temperature, is lower than a fixed, temperature stable internal voltage. The thermal loop overrides the other charger control loops and reduces the charge current until the IC junction temperature returns to 125°C, effectively regulating the IC junction temperature.



A modified charge cycle, with the thermal loop active, is shown here:

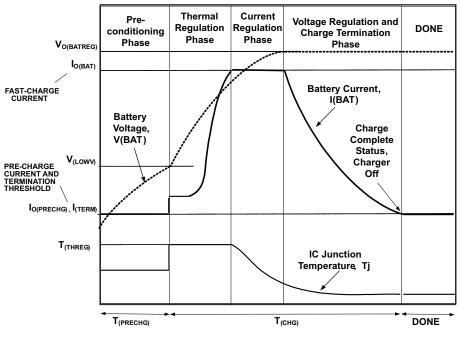


Figure 35. Typical Charge Cycle, Thermal Loop Active

Battery Preconditioning

The TPS65810 applies a pre-charge current $I_{o(PRECHG)}$ to the battery if the battery voltage is below the $V_{(LOWV)}$ threshold, pre-conditioning deeply discharged cells. The charge current loop regulates the ISET1 pin voltage to an internal reference value, V_{PRECHG} . The resistor connected between the ISET1 and AGND pins, R_{SET} , determines the precharge rate.

The pre-charge rate programmed by R_{SET} is always applied to a deeply discharged battery pack, independently of the input power selection (AC or USB). The pre-charge current can be calculated as follows:

$$V_{O(PRECHG)} = \frac{V_{PRECHG} \times K_{SET}}{R_{SET}}$$
(2)

where:

 K_{SET} is the charge current scaling factor and V_{PRECHG} is the pre-charge set voltage.

CONSTANT CURRENT CHARGING

The constant charge current mode (fast charge) is set when the battery voltage is higher than the pre-charge voltage threshold. The charge current loop regulates the ISET1 pin voltage to an internal reference value, V_{SET} . The fast charge current regulation point is defined by the external resistor connected to the ISET1 pin, R_{SET} , as shown in the following:

$$I_{O(BAT)} = \frac{V_{SET} \times K_{SET}}{R_{SET}}$$
(3)

where:

 V_{SET} (2.5 V typ) is the voltage at ISET1 pin during charge current regulation and K_{SET} = Charge Current Scaling Factor.

The reference voltage V_{SET} can be reduced via I²C register CHG_CONFIG bits ISET1_1 and ISET1_0. V_{SET} can be selected as a percentage (75%, 50% or 25%) of the original 2.5 V typ, non-attenuated V_{SET} value, effectively scaling down the charge current.

The ISET1 resistor always sets the maximum charge current if the AC input is selected. When the USB input is selected, the maximum charge current is defined by the USB input current limit and the programmed charge current. If the USB input current limit is lower than the $I_{O(OUT)}$ value, the battery switch is set in the dropout region and the charge current is defined by the input current limit value and system load, as shown in the following curves:

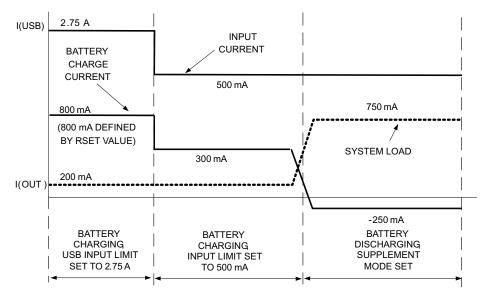


Figure 36. Input Current Limit Impact on Effective Charge Current

CHARGE TERMINATION AND RECHARGE

The TPS65810 monitors the charging current during the voltage regulation phase. Charge is terminated when the charge current is lower than an internal threshold, set to 10% (typ) of the fast charge current rate. The termination point applies to both AC and USB charging, and it can be calculated as follows:

$$I_{\text{TERM}} = \frac{V_{\text{TERM}} \times K_{\text{SET}}}{R_{\text{SET}}}$$
(4)

where

 V_{TERM} is the termination detection voltage reference.

The voltage at ISET1 pin is monitored to detect termination, and termination is detected when V(SET1) < V_{TERM} (0.25 V typ). The voltage reference V_{TERM} is internally set to 10% of the V_{SET} reference voltage, and it is modified if the reference voltage V_{SET} is scaled via I²C register CHG_CONFIG bits ISET1_1 and ISET1_0. V_{TERM} is reduced by the same percentage used to scale down V_{SET} .

The table below shows charge current and termination thresholds for a 1-A charge current set $(1-k\Omega)$ resistor connected to ISET1 pin), with the selected input current limit set to a value higher than the programmed charge current. The termination current is scaled for all charge current modes (AC or USB), as it is always set by the ISET1 pin external resistor value.

Table 7. Charge Current and Termination	Threshold Selection Example
---	-----------------------------

Charge Contr	ol Register Bits	Charge Current, (% of typical value	Vset	Vterm	Charge	Termination	
ISET1_1	ISET1_0	programmed by ISET1 resistor)	(V)	(mV)	Current (A)	Current (mA)	
0	0	25%	0.6	60	0.24	20	
0	1	50%	1.25	115	0.5	40	
1	0	75%	1.9	160	0.78	60	
1	1	100%	2.5	250	1	100	



(5)

Once termination is detected, a new charge cycle starts if the voltage on the BAT pin falls below the $V_{(RCH)}$ threshold. A new charge start is also triggered if the charger is enabled/disabled/enabled via I²C (CHG_CONFIG register bits CE or CHGON), or if both AC and USB input power are removed and then at least one of them is re-inserted.

The termination is disabled when the thermal loop OR DPPM loop are active, and during supplement mode.

BATTERY VOLTAGE REGULATION, CHARGE VOLTAGE

The voltage regulation feedback is Implemented by sensing the BAT pin voltage, which is connected to the positive side of the battery pack. The TPS65810 monitors the battery-pack voltage between the BAT and AGND1 pins, when the battery voltage rises to the $V_{O(REG)}$ threshold the voltage regulation phase begins and the charging current tapers down.

The charging voltage can be selected as 4.2 V or 4.365 V (typ). The default power-up voltage is 4.2 V. As a safety measure the 4.365 V charge voltage is programmed only if two distinct bits are set via I^2C : VCHG=HI in the CHG_CONFIG, and CHG_VLTG=LO in the GPIO3 register.

TEMPERATURE QUALIFICATION

The TPS65810 charger section does not monitor the battery temperature. This function may be implemented by an external host, which can measure the pack temperature by monitoring the ADC channel connected to the TS pin. An external pullup resistor should be connected to the TS pin in order to bias the pack thermistor, as the TPS65810 has no internal current source connected to the TS pin.

DYNAMIC POWER PATH MANAGEMENT

Under normal operating conditions, the OUT pin voltage is regulated when the AC or USB pin is powering the OUT pin and the battery pack is being charged. If the total (system + charge current) exceeds the available input current, the system voltage drops below the regulation value.

The dynamic power path management function monitors the system output voltage. A condition where the external input supply rating has been exceeded or the input current limit has been reached is detected when the OUT pin voltage drops below an user-defined threshold, V_{DPPM}:

$$V_{DPPM} = R_{DPPM} \times K_{DPPM} \times I_{DPPM}$$

where:

 R_{DPPM} = external resistor connected to DPPM pin

 $K_{\text{DPPM}} = \text{DPPM}$ scaling factor

I_{DPPM} = DPPM pin internal current source

To correct this situation the DPPM loop reduces the charge current, regulating the OUT pin voltage to the user-defined V_{DPPM} threshold. The DPPM loop effectively identifies the maximum current that can be delivered by the selected input and dynamically adjusts the charge current to guarantee that the end equipment is always powered. In order to minimize OUT voltage ripple during DPPM operation the V_{DPPM} threshold should be set just below the system regulation voltage.

If the charge current is reduced to zero by the DPPM and the input current is still lower than the OUT pin load, the output voltage falls below the DPPM threshold, decreasing until the battery supplement mode is set [V(OUT) = $V(BAT) - V_{SUP(DT)}$].

CHARGER OFF MODE

The TPS65810 charger circuitry enters the low-power OFF mode if both AC and USB power are not detected. This feature prevents draining the battery during the absence of input supply.

PRE-CHARGE SAFETY TIMER

The TPS65810 activates an internal safety timer during the battery pre-conditioning phase. The pre-charge safety timer time-out value is set by the external resistor connected to TMR pin, RTMR, and the timeout constants K_{PRE} and K_{TMR} :

 $T_{PRECHG} = K_{PRE} \times R_{TMR} \times K_{TMR}$

The K_{PRF} constant typical value is 0.1, setting the pre-charge timer value to 10% of the charge safety timer value.

When the charger is in suspend mode, set via I^2C register CHG_CONFIG bit CHGON or set by a pack temperature fault, the pre-charge safety timer is put on hold (i.e., charge safety timer is not reset). Normal operation resumes when the charger exits the suspend mode. If V(BAT) does not reach the internal voltage threshold V_{PRECHG} within the pre-charge timer period a fault condition is detected and the charger is turned off.

If the TMR pin is left floating, an internal resistor of 50 K Ω (typ) is used to generate the time base used to set the pre-charge timeout value. The typical pre-charge timeout value can be then calculated as:

 $T_{PRECHG} = K_{PRE} \times 50K \times K_{TMR}$

CHARGE SAFETY TIMER

As a safety mechanism the TPS65810 has a user-programmable timer that measures the total fast charge time. This timer (charge safety timer) is started at the end of the pre-conditioning period. The safety charge timeout value is set by the value of an external resistor connected to the TMR pin R_{TMR}). The charge safety timer time-out value is calculated as follows:

 $T_{CHG} = K_{TMR} \times R_{TMR}$

When the charger is in suspend mode, set via I²C register CHG_CONFIG bit CHGON or set by a pack temperature fault, the charge safety timer is put on hold (i.e., charge safety timer is not reset). Normal operation resumes when the charger exits the suspend mode. If charge termination is not reached within the timer period a fault condition is detected, and the charger is turned off.

The charge safety timer is held in reset if the TMR pin is left floating. Under this mode of operation an internal resistor, $50K\Omega$ typical, sets the internal charger and power path deglitch and delay times, as well as the pre-charge safety timer timeout value.

TIMER FAULT RECOVERY

The TPS65810 provides a recovery method to deal with timer fault conditions. The following summarizes this method:

• Condition 1: Charge voltage above recharge threshold, V_{RCH}, and timeout fault occurs.

Recovery method: The IC waits for the battery voltage to fall below the recharge threshold. This could happen as a result of a load on the battery, self-discharge or battery removal. Once the battery falls below the recharge threshold, the IC clears the fault and starts a new charge cycle.

• Condition 2: Charge voltage below recharge threshold, V_(RCH), and timeout fault occurs.

Recovery method: Under this scenario, the IC connects an internal pullup resistor from OUT pin to BAT pin. This pullup resistor is used to detect a battery removal condition and remains on as long as the battery voltage stays below the recharge threshold. If the battery voltage goes above the recharge threshold, the IC disables the pullup resistor connection and executes the recovery method described for condition 1.

All timers are reset and all timer fault conditions are cleared when a new charge cycle is started either via I²C (toggling CHG_CONFIG bits CE, CHGON) or by cycling the input power. All timers are reset and all timer fault conditions are cleared when the TPS65810 enters the UVLO mode.

DYNAMIC TIMER FUNCTION

The charge and pre-charge safety timers are programmed by the user to detect a fault condition if the charge cycle duration exceeds the total time expected under normal conditions. The expected total charge time is usually calculated based on the fast charge current rate.

When the thermal loop or the DPPM loops are activated the charge current is reduced, and a false safety timer fault can be observed if this mode of operation is active for a long periods. To avoid this undesirable fault condition the TPS65810 activates the dynamic timer function when the DPPM and thermal loops are active. The dynamic timer function slows down the safety timers clock, effectively adding an extra time to the programmed timeout value as follows:

- 1. If the battery voltage is below the battery depleted threshold: the pre-charge timer value is modified while the thermal loop or the DPPM loop are active
- 2. If the battery voltage is above the pre-charge threshold: the safety timer value is modified if the DPPM or the

thermal loop are active AND the battery voltage is below the recharge threshold.

The TPS65810 dynamic timer function circuit monitors the voltage at pin ISET1 during pre-charge and fast charge. When the charger is regulating the charge current, the voltage at pin ISET1 is regulated by the control loops to either V_{SET} or V_{PRECHG} . If the thermal loop or DPPM loops are active, the voltage at pin ISET1 is lower than V_{SET} or V_{PRECHG} , and the dynamic timer control circuit changes the safety timers clock period based on the $V_{SET}/V(ISET1)$ ratio (fast charge) or $V_{PRECHG}/V(ISET1)$ ratio (pre-charge).

The maximum *clock period* is internally limited to twice the value of the programmed clock period, which is defined by the resistor connected to TMR pin, as shown in the following figure:

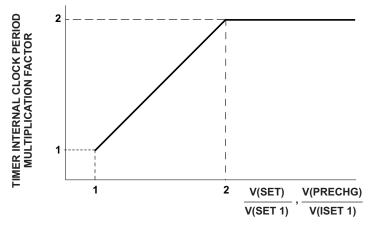


Figure 37. Safety Timer Internal Clock Slowdown

The effective charge safety timer value can then be expressed as follows:

Effective pre-charge timeout = $t_{(PRECHG)} + t_{(PCHGADD)}$

Effective charge safety timeout = $t_{(CHG)} + t_{(CHGADD)}$

where the *added* timeout values, $t_{(PCHGADD)}$, $t_{(CHGADD)}$, are equal to the sum of all time periods when either the thermal loop or DPPM loops were active. The *maximum added* timeout value is internally limited to $2 \times t_{(CHG)}$ or $2 \times t_{(PRECHG)}$

CHARGE AND SYSTEM POWER MANAGEMENT — I²C REGISTERS

The I²C registers that control charger and power path related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values. Note that the CHG_STAT register contents are valid only when either AC or USB power are applied to the TPS65810. The output of linear regulator LDO_PM can be used as an indicator of external input power detection; if LDO_PM is in regulation the CHG_STAT register contents are valid.



CHG_CONF	IG, ADDRESS=9,	ALL BITS R/W						
	B7	B6	B5	B4	B3	B2	B1	В0
Bit name	VCHG	CHGON	NOT USED	ISET1_1	ISET1_0	ISET2	PSEL	CE ⁽¹⁾
Function	CHARGE VOLTAGE SELECTION	SUSPEND CHARGE	NOT USED		RENT SCALING TOR	USB CURRENT LIMIT	SELECTED INPUT CURRENT LIMIT	SYSTEM POWER SELECTION
When 0	4.36 V	CHARGE SUSPENDED	NOT USED	00= 0.25 10=0.75 01= 0.5 11= 1 Note: Relative to ch	arge current	100 mA	USE USB CURRENT LIMIT	BATTERY TO SYSTEM
When 1	4.20 V	CHARGE ON	NOT USED	programmed by externed by exte	ernal ISET pin	500 mA	INPUT CURRENT LIMIT SET TO MAXIMUM	INPUT POWER TO SYSTEM ⁽¹⁾

(1) The CE bit state is latched inside the charger control logic (CE latch) during an OUT pin UVLO event, prior to resetting the charge control register bit CE to its power up default value. The charger CE latch controls the charger and power path state as long as the TPS65810 is in UVLO mode and an external supply is connected to the charger block. The CE latch is reset to its power-up value (CE=HI) only when the input power is removed from the charger block. The CE latch is disabled and the CE charge control register bit sets the charger and power path MOSFETs state when the TPS65810 exits the UVLO mode. This feature avoids a host software *loop* when the host algorithm requires a depleted (or absent) battery to be connected to the system bus while input power is present.

	B7	B6	B5	B4	B3	B2	B1	B0
Bit name	GPIO3i/O	GPIO3_LEVEL	LDO0_ENABLE	CHARGE _VLTG	NOT USED	GPIO2_INTSRC	GPIO1_INTSRC	GPIO2 _SM2
Function	SEE Table 15	SEE Table 15	SEE Table 15	CHARGE VOLTAGE SELECTION SAFETY BIT	NOT USED	SEE Table 15	Table 15	SEE Table 15
When 0				4.2 V				
When 1	-			4.36 V				

	B7	B6	B5	B4	B3	B2	B1	B0
Bit name	BAT_STAT ^{(1) (2)}	INPUT _PWR	THDPPM_ON	ACPG ⁽³⁾	USBPG ⁽³⁾	STAT1	STAT2	INP_OV
Function	BATTERY SUPPLEMENT MODE STATUS	SELECTED INPUT POWER STATUS	THERMAL LOOP AND DPPM STATUS	AC INPUT POWER STATUS	USB INPUT POWER STATUS	CHARGE STATUS		AC OR USB INPUT OVP DETECTION
When 0	SUPPLEMENT MODE OFF	AC INPUT SELECTED	BOTH OFF	AC NOT DETECTED	USB NOT DETECTED	00 = FAULT/SUSPEND/OFF 01 = CHARGE DONE 10 = FAST CHARGE ON 11 = PRECHARGE		NO OVP
When 1	SUPPLEMENT MODE ON	USB INPUT SELECTED	DPPM ON OR THERMAL ON	AC DETECTED	USB DETECTED			OVP DETECTED

(1) The battery supplement is entered when V_(BAT) - V_(OUT) > 60 mV (typ), and it ends when V_(BAT) - V_(OUT) < 20 mV. When the system power bus current exceeds the input current limit or the external supply current capability, the supplement mode is set. An oscillatory behavior for BAT_STAT bit can happen if the battery switch dropout voltage is less than 20 mV (typ) when in supplement mode.</p>

(2) The BAT_STAT is always masked internally, and does not generate interrupts.

(3) The ACPG and USBPG bits have valid data only when $V_{(LDO_{PM})} > 2 V$.



FUNCTIONALITY GUIDE — LINEAR REGULATORS

SELECTA	BLE OUTPUT VO	LTAGE LDO						
Supply	ON/OFF	Output Discharge	OUTPUT \	/OLTAGE (V), set	via l ² C	IO Max	Acc %	
	Control	Switch	# of Steps	Available V	alues (V)	(mA)		Default
LDO1	Yes, set via I ² C	Yes, enabled via I ² C	8	1.25/1.5/1.8/2.5/2.85/3/3.2/3.3		150	3	OFF, 1.25 V
LDO2	Yes, set via I ² C	Yes, enabled via I ² C	8	1.25/1.5/1.8/2.5/	/2.85/3/3.2/3.3	150	3	OFF, 3.3 V
SIM	Yes, set via I ² C	no	2	1.8 /	8	2	ON, 2.5 V	
PROGRAM	MABLE OUTPU	T VOLTAGE LDO						
Supply	ON/OFF	Output Discharge	OUTPUT \	IO Max	Acc %			
	Control	Switch	Range	# of Steps	Min Step	(mA)		Default
LDO3	yes, set via l ² C	Yes, enabled via I ² C	1.224-4.46	128	25 mV	100	3	OFF, 1.505
LDO4	yes, set via I ² C	Yes, enabled via I ² C	1.224-4.46	128	25 mV	100	3	OFF, 1.811
LDO5	yes, set via I ² C	Yes, enabled via I ² C	1.224-4.46	128	25 mV	100	3	ON, 3.111 \
FIXED OU	TPUT VOLTAGE	LDO'S			1		4	
Supply	ON/OFF Control		OUTPUT VOLTAGE (V)	IO Max (mA)	Acc %	Power Up Default		Default
RTC_OUT	Yes, via I ² C		1.5, fixed	8	5	ON		
LDC0			3.3, fixed	150	3	OFF		
LDO_PM	NO, ena	bled internally	3.3, fixed	20	5	ON if AC or USB power dete		

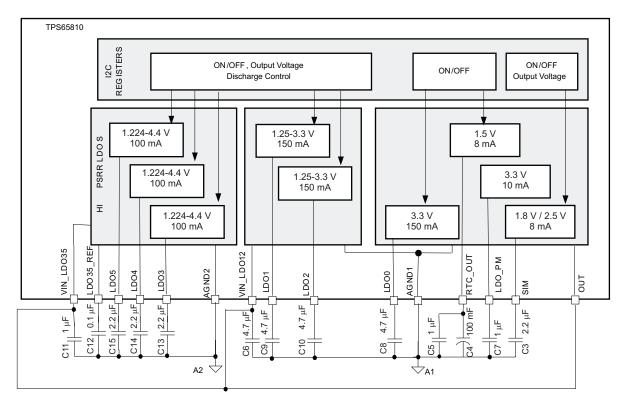


Figure 38. Required External Components, Recommended Values, External Connections



LINEAR REGULATORS — FUNCTIONAL DESCRIPTION

The TPS65810 offers nine integrated linear regulators, designed to be stable over the operating load range with use of external ceramic capacitors, as long as the recommended filter capacitor values (see application diagram and pinout description) are used. The output voltage can be programmed via I²C (LDO0-2, LDO3-5) or have a fixed output voltage.

Simplified Block Diagram

A simplified block diagram for the LDOs is shown in Figure 39.

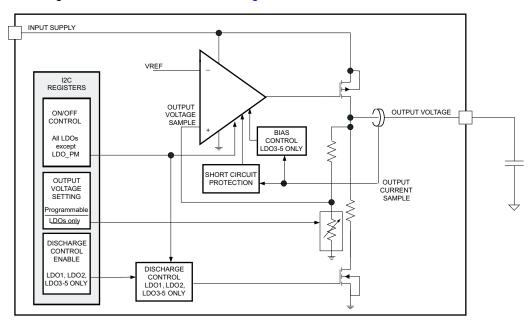


Figure 39. Simplified Block Diagram

Connecting the LDO Input Supply

Both LDO1-2 and LDO3-5 have uncommitted input power supply pins (VIN_LDO12, VIN_LDO35), which should be externally connected to the OUT pin. Optionally the LDO0-2 and LDO3-5 input supplies can be connected to the output of the available buck converters SM1 or SM2, as long as the resulting overall power-up sequence meets the system requirements.

The RTC_OUT, SIM, LDO0 and LDO_PM linear regulators are internally connected to the OUT pin.

ON/OFF Control

All the LDO's, with exception of LDO_PM LDO, have a ON/OFF control which can be set via I²C commands, facilitating host management of the distinct system power rails. The LDO_PM LDO On/OFF control is internally hard-wired, and it is set to ON when either the AC or USB input power is detected.

Output Discharge Switch

LDO1, LDO2 AND LDO3-5 have integrated switches that discharge each output to ground when the LDO is set to OFF by an I²C command. The output discharge switch function can be disabled by using I²C register control bits. The discharge switches are enabled after the initial power-up

Special Functions

The RTC_OUT, SIM (Subscriber line interface module) and LDO_PM linear regulators are designed to support lower load currents. The SIM and RTC_LDO have low leakage in OFF mode, with the input pin voltage above or below the output pin voltage. The LDO_PM can be used for USB enumeration, or a status indication of input power connection.

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Output Voltage Monitoring

Internal power good comparators monitor the LDO outputs and detect when the output voltage is below 90% of the programmed value. This information is used by the TPS65810 to generate interrupts or to trigger distinct operating modes, depending on specific I²C register settings. See interrupt and sequencing controller section for additional details.

LINEAR REGULATORS — I²C REGISTERS

The I²C registers that control LDO-related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values.

	B7	B6	B5	B4	B3	B2	B1	В0				
EN_LDO: ADD	RESS = B, ALL BI	TS R/W			1		1	L				
Bit name	LDO1_EN	LDO2_EN	LDO3_EN	LDO4_EN	LDO5_EN	SIM_SET	SIM EN1	RTC_EN				
Function		LDO1	5 ON/OFF CONT	ROL		SIM LDO output voltage	SIM/RTC ON/O	FF CONTROL				
When 0	OFF	OFF	OFF	OFF	OFF	2.5 V, ON	OFF	OFF				
When 1	ON	ON	ON	ON	ON	1.8 V	ON	ON				
LDO12: ADDR	ESS = C, ALL BIT	S R/W		•								
Bit name	LDO1_DISCH	LDO1_2 SET	LDO1_1 SET	LDO1_0 SET	LDO2_DISCH	LDO2_2 SET	LDO2_1 SET	LDO2_0 SET				
Function	LDO1 output discharge switch enable	LDO1 OU	LDO1 OUTPUT VOLTAGE SETTING LDO2 output LDO2 OUTPUT VOLTAGE SETTIN discharge switch enable									
When 0	OFF	000 = 1.25 V	001 = 1.5 V	Default =	OFF	000 = 1.25 V	001 = 1.5 V	Default = 3.3 V				
When 1	ON	010 = 1.8 V 100 = 2.85 V 110 = 3.2 V	011 = 2.5 V 110 = 3 V 111 = 3.3 V	1.25 V	ON	010 = 1.8 V 100 = 2.85 V 110 = 3.2 V	011 = 2.5 V 110 = 3 V 111 = 3.3 V					
LDO3, ADDRE	SS = D, ALL BITS	R/W										
Bit name	LDO3_DISCH	LDO3_6 SET	LDO3_5 SET	LDO3_4 SET	LDO3_3 SET	LDO3_2 SET	LDO3_1 SET	LDO3_0 SET				
Function	LDO3 output discharge switch enable		LDO3 OUTPUT VOLTAGE SETTING									
When 0	OFF		SeeTable 8 f	for LDO3-5 output	voltage setting,	Power-up def	ault = 1.505 V					
When 1	ON											
LDO4, ADDRE	SS = E, ALL BITS	R/W										
Bit name	LDO4_DISCH	LDO4_6 SET	LDO4_5 SET	LDO4_4 SET	LDO4_3 SET	LDO4_2 SET	LDO4_1 SET	LDO4_0 SET				
Function	LDO4 output discharge switch enable			LDO4 O	UTPUT VOLTAG	SE SETTING						
When 0	OFF		See Table 8	for LDO3-5 output	t voltage setting,	Power-up det	fault = 1.811 V					
When 1	ON											
LDO5, ADDRE	SS = F, ALL BITS	R/W										
Bit name	LDO5_DISCH	LDO5_6 SET	LDO5_5 SET	LDO5_4 SET	LDO5_3 SET	LDO5_2 SET	LDO5_1 SET	LDO5_0 SET				
Function	LDO5 output discharge switch enable			LDO5 O	UTPUT VOLTAG	SE SETTING						
When 0	OFF		See Table 8	for LDO3-5 output	t voltage setting,	Power-up det	fault = 3.111 V					
When 1	ON											
GPIO3, ADDR	ESS = 1C, ALL BIT	S R/W. NOTE: O	NLY BIT B5 CON	TROLS LDO-REL	ATED FUNCTION	ONALITY						
Bit name	GPIO3i/O	GPIO3 LEVEL	LDO0 ENABLE	CHARGE _VLTG	NOT USED	GPIO2_INTSRC	GPIO1_INTSRC	GPIO2 _SM2				
Function	SEE Table 15	SEE Table 15	LDO0 ON/OFF CONTROL	SEE Table 15	NOT USED	SEE Table 15	SEE Table 15	SEE Table 15				
When 0			LDO0 OFF									
When 1			LDO0 ON									



TPS65810



Step	B6–B0	Vset	Step	B6-B0	Vset	Step	B6B0	Vset	Step	B6-B0	Vset	
0	000 0000	1.224	32	010 0000	2.040	64	100 0000	2.015	96	110 0000	2.856	
1	000 0001	1.250	33	010 0001	2.066	65	100 0001	2.040	97	110 0001	2.882	
2	000 0010	1.275	34	010 0010	2.091	66	100 0010	2.907	98	110 0010	3.723	
3	000 0011	1.301	35	010 0011	2.117	67	100 0011	2.933	99	110 0011	3.749	
4	000 0100	1.326	36	010 0100	2.142	68	100 0100	2.958	100	110 0100	3.774	
5	000 0101	1.352	37	010 0101	2.168	69	100 0101	2.984	101	110 0101	3.800	
6	000 0110	1.377	38	010 0110	2.193	70	100 0110	3.009	102	110 0110	3.825	
7	000 0111	1.403	39	010 0111	2.219	71	100 0111	3.035	103	110 0111	3.851	
8	000 1000	1.428	40	010 1000	2.244	72	100 1000	3.060	104	110 1000	3.876	
9	000 1001	1.454	41	010 1001	2.270	73	100 1001	3.086	105	110 1001	3.902	
10	000 1010	1.479	42	010 1010	2.295	74	100 1010	3.111	106	110 1010	3.927	
11	000 1011	1.505	43	010 1011	2.321	75	100 1011	3.137	107	110 1011	3.953	
12	000 1100	1.530	44	010 1100	2.346	76	100 1100	3.162	108	110 1100	3.978	
13	000 1101	1.556	45	010 1101	2.372	77	100 1101	3.188	109	110 1101	4.004	
14	000 1110	1.581	46	010 1110	2.397	78	100 1110	3.213	110	110 1110	4.029	
15	000 1111	1.607	47	010 1111	2.423	79	100 1111	3.239	111	110 1111	4.055	
16	001 0000	1.632	48	011 0000	2.448	80	101 0000	3.264	112	111 0000	4.080	
17	001 0001	1.658	49	011 0001	2.474	81	101 0001	3.290	113	111 0001	4.106	
18	001 0010	1.683	50	011 0010	2.499	82	101 0010	3.315	114	111 0010	4.131	
19	001 0011	1.709	51	011 0011	2.525	83	101 0011	3.341	115	111 0011	4.157	
20	001 0100	1.734	52	011 0100	2.550	84	101 0100	3.366	116	111 0100	4.182	
21	001 0101	1.760	53	011 0101	2.576	85	101 0101	3.392	117	111 0101	4.208	
22	001 0110	1.785	54	011 0110	2.601	86	101 0110	3.417	118	111 0110	4.233	
23	001 0111	1.811	55	011 0111	2.627	87	101 0111	3.443	119	111 0111	4.259	
24	001 1000	1.836	56	011 1000	2.652	88	101 1000	3.468	120	111 1000	4.284	
25	001 1001	1.862	57	011 1001	2.678	89	101 1001	3.494	121	111 1001	4.310	
26	001 1010	1.887	58	011 1010	2.703	90	101 1010	3.519	122	111 1010	4.335	
27	001 1011	1.913	59	011 1011	2.729	91	101 1011	3.545	123	111 1011	4.361	
28	001 1100	1.938	60	011 1100	2.754	92	101 1100	3.570	124	111 1100	4.386	
29	001 1101	1.964	61	011 1101	2.780	93	101 1101	3.596	125	111 1101	4.412	
30	001 1110	1.989	62	011 1110	2.805	94	101 1110	3.621	126	111 1110	4.437	
31	001 1111	2.015	63	011 1111	2.831	95	101 1111	3.647	127	111 1111	4.463	



FUNCTIONALITY GUIDE — SWITCHED MODE STEP-DOWN CONVERTERS

Supply	PFM Mode	M Mode Standby Mode	OUTPUT VOLTAGE (V), Set via I ² C, Separate Settings for Normal or Standby Mode			IO Max (mA)	PWM Freq and Phase	SLEW R	ATE, mV/ via l ² C	μ S, Set	Power Up Default	
		-	Range	# of Steps	Min Step	Acc (%)			Range	# of Steps	Min Step	
SM1	PFM/PWM with automatic mode selection or PWM only.	Standby mode with distinct voltage available	0.6-1.8	32	40 mV	3	600	1.5MHz, 0°	0, 0.24 to 15.36	8	0.24	OFF, skip mode off, PWM only, 1.24 V(on/sby), 15.36mV/μS
SM2	Mode of operation set via I ² C	Standby mode set via I ² C or with GPIO pin	1.0-3.4	32	80mV	3	600	1.5MHz, 0/90/180 270°, with respect to SM1, set via I ² C	0, 0.48- 30.72	8	0.48	OFF, skip mode on, PWM/PFM, 3.32V (on/sby), 180°, 30.72mV/μS

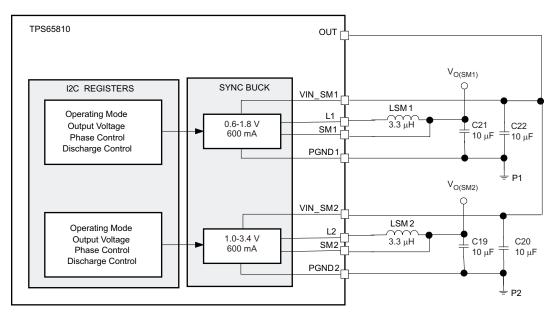


Figure 40. Required External Components, Recommended Values, External Connections

STEP-DOWN SWITCHED MODE CONVERTERS: SM1 and SM2

The TPS65810 has two highly efficient step down synchronous converters. The integration of the power stage switching MOSFETs reduces the external component count, and only the external output inductor and filter capacitor are required. The integrated power stage supports 100% duty cycle operation. Multiple operation modes are available, enabling optimization of the overall system performance under distinct load conditions.

The converters have two modes of operation: a 1.5 MHz fixed frequency pulse width modulation (PWM) mode at moderate to heavy loads, and a pulse frequency modulation (PFM) mode at light loads. The converter output voltage is programmable via I²C registers SM1_SET1 and SM2_SET1.

When the SM1/SM2 converters are disabled an integrated switch automatically discharges the converter output capacitor. The discharge switch function can be disabled by setting the control bits DISCHSM1 and DISCHSM2 to LO, in I²C registers SM1_SET2 and SM2_SET2.

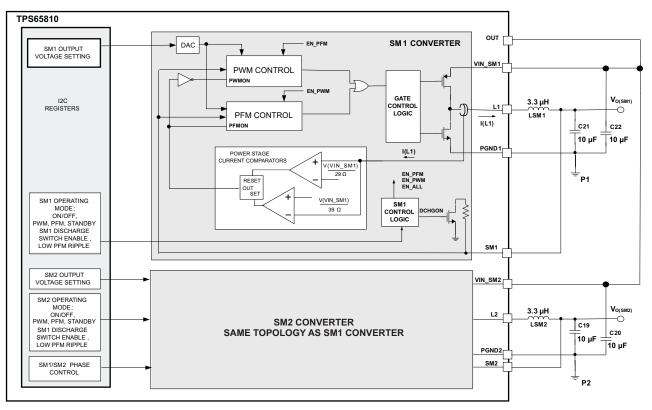


Figure 41. SM1/SM2 Converter

The TPS65810 SM1 and SM2 buck converters can be set to operate only in PWM mode or to switch automatically between PFM and PWM modes. The average load current is monitored, and the PFM mode is set if the average load current is below the threshold IPFM(ENTER). When in PFM mode the load current is also monitored, and the PWM mode is set when the load current exceeds the threshold I_{PFM(LEAVE)}. The thresholds for automatic PFM/PWM switching are calculated as shown in Equation 6 for the SM1 converter, the same thresholds apply to the SM2 converter by replacing VIN_SM1 by VIN_SM2:

$$I_{\text{PFM}(\text{LEAVE})} = \frac{V(\text{VIN}_{\text{SM3}})}{29 \ \Omega} , \qquad I_{\text{PFM}(\text{ENTER})} = \frac{V(\text{VIN}_{\text{SM3}})}{39 \ \Omega}$$
(6)

The automatic switching mode is enabled via the control bits PFM_SM1 and PFM_SM2 on I²C registers SM1_SET1 and SM2_SET1.

Output Voltage Slew Rate

 l^2 C registers enable setting the output voltage slew rate, when transitioning from one programmed voltage to a new programmed voltage value. These events can be triggered by a new output voltage selection or by switching from a low power mode (standby) to a normal operating mode. During a transition, the output voltage is stepped from the currently programmed voltage to the new target voltage. The slew rate from the initial voltage to the final voltage can be selected using l^2 C registers, SM1_SET2 and SM2_SET2, ranging from 0.24 mv/µs to 15.36 mV/µs for the SM1 converter and 0.48 to 30.72 mV/µS for the SM2 converter. If the slew rate is set to OFF the output voltage goes from the current value to the programmed value in a single step.

During the transition to standby mode the Power Good comparators are disabled.



Soft Start

SM1 and SM2 have an internal soft start circuit that limits the inrush current during start-up. An initial delay (170 μ sec typ) from the converter enabled command to the converter effectively being operational is required, to assure that the internal circuits of the converter are properly biased. At the end of that initial delay the soft start is initiated, and the internal compensation capacitor is charged with a low value current source. The soft start time is typically 750 μ s, with the output voltage ramping from 5% to 95% of the final target value.

Dropout Operation at 100% Duty Cycle

The TPS65810 buck converters offer a low input to output voltage difference while still maintaining operation when the duty cycle is set to 100%. In this mode of operation the P-channel switch is constantly turned on, enabling operation with a low input voltage. The dropout operation starts if:

$$V(VIN_SM1) \le V(SM1) + I(L1)(R_{DSON(PSM1)} + R_L)$$

(7)

Where:

I(L1) = Output current plus inductor ripple current.

 $R_L = DC$ resistance of the inductor

Equation 7 can be also used for the SM2 converter, replacing SM1 by SM2 and L1 by L2.

Output Voltage Monitoring

The output voltage of converters SM1 and SM2 is monitored by internal comparators, and an output low voltage condition is detected when the output voltage is below 90% of the programmed value. The power good status for SM1 and SM2 is accessible via I^2C , see interrupt controller section for more details.

The power good comparators for SM1 and SM2 are disabled during the transition to standby mode operation. They are enabled when the transition to standby mode is complete.

Standby Mode

Using the I²C SM1 and SM2 can be set in stand-by mode. In STANDBY mode the PFM operation mode is set and the output voltage is defined by I²C registers SM1_STANDBY and SM2_STANDBY, and it can be set to a value different than the normal mode output regulation voltage. The standby mode can also be set by the GPIO pins, if those are configured as control pins that define the SM1/SM2 operating mode.

PWM Operation

During PWM operation the converters use a fast response voltage mode controller scheme with input voltage feed-forward, enabling the use of small ceramic input and output capacitors. At the beginning of each clock cycle the P-channel MOSFET switch is turned on, and the oscillator starts the voltage ramp. The inductor current ramps up until the ramp voltage reaches the error amplifier output voltage, when the comparator trips and the p-channel MOSFET switch is turned off. Internal adaptative break-before-make circuits turn on the integrated n-channel MOSFET switch after an internal, fixed dead-time delay, and the inductor current ramps down, until the next cycle is started. When the next cycle starts the ramp voltage is reset to its low value and the p-channel MOSFET switch is turned on again.

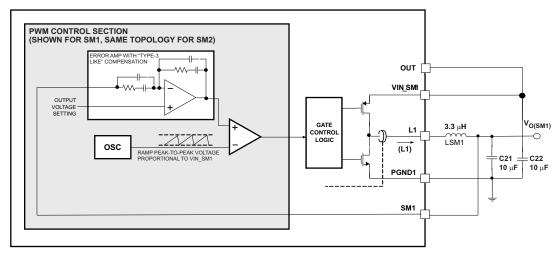


Figure 42. PWM Operation

The integrated power MOSFETs current is monitored at all times and the power MOSFET is turned off if its internal short circuit current limit is reached.

Phase Control in PWM Mode

The SM1 and SM2 converters operate synchronized to each other when both are in PWM mode, with converter SM1 as the master. I²C control register bits S1S2PHASE in register SM1_SET2 enables delaying the SM2 PWM clock with respect to SM1 PWM clock, selecting a phase shift from 0 to 270 degrees. The out-of-phase operation reduces the average current at the input node, enabling use of smaller input filter capacitors when both converters are connected to the same input supply.

PFM Mode Operation

Using the I²C interface the SM1 and SM2 converters can have the automatic power saving PFM mode enabled. When the PFM mode is set the switching frequency is reduced and the internal bias currents are decreased, optimizing the converter efficiency under light load conditions.

In PFM mode, the output voltage is monitored by a voltage comparator, which regulates the output voltage to the programmed value, $V_{O(SM1)}$. If the output voltage is below $V_{O(SM1)}$, the PFM control circuit turns on the power stage, applying a burst of pulses to increase the output voltage. When the output voltage exceeds the target regulation voltage, $V_{O(SM1)}$, the power stage is disabled, and the output voltage drops until it is below the regulation voltage target, when the power stage is enabled again.



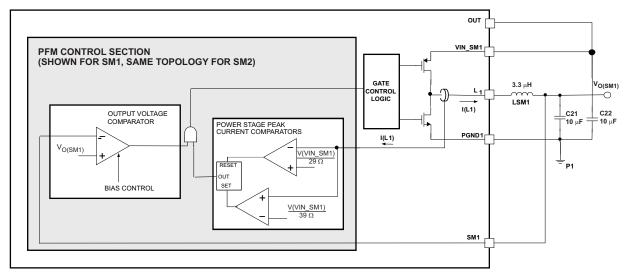


Figure 43. PFM Mode Operation

During burst operation two current comparators control the power stage integrated MOSFETs. These comparators monitor the instantaneous inductor current and compare it to the internal thresholds $I_{PFM(ENTER)}$ and $I_{PFM(LEAVE)}$, turning the p-channel switch on if the inductor current is less than $I_{PFM(LEAVE)}$ and turning it off if the inductor current exceeds $I_{PFM(ENTER)}$. The n-channel switch is turned on when the p-channel MOSFET is off.

The PFM output voltage comparator quiescent current may be reduced using the I^2C register bits PFM_RPL1 and PFM_RPL2 in registers SM1_SET and SM2_SET. The voltage comparator quiescent current is reduced if PFM_RPL1 and PFM_RPL2 bits are set to LO, and the comparator response time (t_{COMP} , see Figure 44) increases. A reduction in quiescent current increases the converter efficiency at light loads, at the expense of a larger output voltage ripple when in PFM mode.

The ripple is minimized if PFM_RPL1 and PFM_RPL2 bits are set to HI, at the expense of reduced efficiency under light loads. The operation under low and high ripple settings is described in Figure 44.

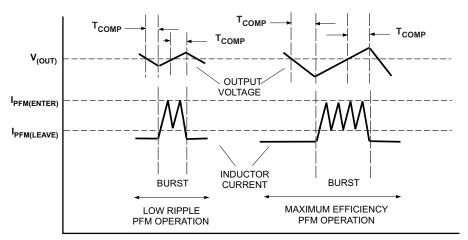


Figure 44. PFM mode operation waveforms

When a burst of pulses is generated, the PFM current comparators control the power-stage MOSFETs to limit the inductor current to a value between the thresholds $I_{PFM(LEAVE)}$ and $I_{PFM(ENTER)}$. The number of pulses in a burst cycle is proportional to the load current, and the average current is always below $I_{PFM(LEAVE)}$ once PFM operation is set. The typical burst operation in PFM mode is shown in Figure 45.



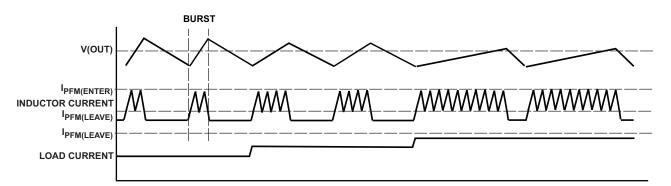


Figure 45. Typical Burst Operation in PFM Mode

The PFM operation is disabled and PWM operation set if one of the following events happen during PFM operation:

- 1. The total burst operation time exceeds 10 $\mu s,$ typ.
- 2. The output voltage falls below 2% of the target regulation voltage.

The PFM mode can be disabled through the serial interface to force the individual converters to stay in fixed frequency PWM mode.



SWITCHED-MODE STEP-DOWN CONVERTERS — I²C REGISTERS

The I²C registers that control buck converter-related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values.

	B7	B6	B5	B4	B3	B2	B1	B0		
SM1_SET1, A	DDRESS=10, ALL	BITS R/W								
Bit name	SM1 EN	PFM_RPL1	PFM_SM1	SetV4_SM1	SetV3_SM1	SetV2_SM1	SetV1_SM1	SetV0_SM1		
Function	SM1 ON/OFF CONTROL	SM1 PFM FUNCTION OPERATION	SM1 PFM MODE ON/OFF CTRL	SM1 OUTPU	JT VOLTAGE RE	GULATION VALU	E, STANDBY MOI	DE NOT SET		
When 0	OFF	MAXIMIZE EFFICIENCY	PWM/PFM	See Tab	le 9 for SM1, SM2	2 voltage setting,	Power up defau	lt=1.24 V		
When 1	ON	MINIMIZE OUTPUT RIPPLE	Only PWM							
SM1_SET2, A	DDRESS=11, ALL I	BITS R/W								
Bit name	NOT USED	STANDBY_SM 1	DISCHSM1	S1S2PHASE_1	S1S2PHASE_0	SLEWSM1_2	SLEWSM1_1	SLEWSM1_0		
Function	NOT USED	SM1 STANDBY MODE ON	SM1 output discharge switch enable	WITH RESPEC	LOCK DELAY, T TO SM1 PWM DCK	SM1 OUT	PUT SLEW RATE	SETTING		
When 0	NOT USED	OFF	OFF	00 = 0°	10 = 180°		0 = 0.96 $100 = 5$			
When 1	NOT USED	ON	ON	01 = 90°	11 = 270° Default = 180°	IMMEDIATE	011 = 1.92 101 = 7 Default= 15.36	7.68 111 =		
SM1_STANDE	BY, ADDRESS=12,	B4-B0 R/W, B7-B	5 READ ONLY	L	1	1				
Bit name	GPIO3LVL	GPIO2LVL	GPIO1LVL	SetV4_SM1SL	SetV3_SM1SL	SetV2_SM1SL	SetV1_SM1SL	SetV0_SM1SL		
Function	GPIO3 pin logic level	GPIO2 pin logic level	GPIO1 pin logic level	SM1 OUT	PUT VOLTAGE P	REGULATION VA	LUE, STANDBY M	IODE SET		
When 0	LO	LO	LO	See Tab	ole 9 for SM1, SM	2 voltage setting, I	Power-up default	= 1.24 V		
When 1	Н	н	н							
SM2_SET1, A	DDRESS=13, ALL	REGISTER BITS F	R/W							
Bit name	SM2 EN	PFM_RPL2	PFM_SM2	SetV4_SM2	SetV3_SM2	SetV2_SM2	SetV1_SM2	SetV0_SM2		
Function	SM2 ON/OFF CONTROL	SM2 PFM FUNCTION OPERATION	SM2 PFM MODE ON/OFF CTRL	SM2 OUTPU	JT VOLTAGE RE	GULATION VALU	E, STANDBY MOI	DE NOT SET		
When 0	OFF	MAXIMIZE EFFICIENCY	PWM/PFM	See Tat	ble 9 for SM1, SM	2 voltage setting, I	Power-up default	= 3.32 V		
When 1	ON	MINIMIZE OUTPUT RIPPLE	ONLY PWM	-						
SM2_SET2, A	DDRESS=14, ALL I	REGISTER BITS F	R/W							
Bit name	NOT USED	STANDBY_SM 2	DISCHSM2	NOT USED	NOT USED	SLEWSM2_2	SLEWSM2_1	SLEWSM2_0		
Function	NOT USED	SM2 STANDBY MODE ON	SM2 output discharge switch enable	NOT USED	NOT USED	SM2 OUT	PUT SLEW RATE	SETTING		
When 0	NOT USED	OFF	OFF	NOT USED	NOT USED		0 = 1.92 100 = 7			
When 1	NOT USED	ON	ON	NOT USED	NOT USED	110 = 30.72 001 = 0.096 011 = 3.84 101 = 15.36 111 = IMMEDIATE Unit: mV/µs Default = 30.72				
SM2_STANDE	BY, ADDRESS=15,	ALL REGISTER B	ITS R/W							
Bit name	NOT USED	NOT USED	NOT USED	SetV4_SM2SL	SetV3_SM2SL	SetV2_SM2SL	SetV1_SM2SL	SetV0_SM2SL		
Function	NOT USED	NOT USED	NOT USED	SED SM1 OUTPUT VOLTAGE REGULATION VALUE, STANDBY MODE SET						
When 0	NOT USED	NOT USED	NOT USED	SED See Table 9 for SM1, SM2 voltage setting, Power up default=3.32 V						
When 1	NOT USED	NOT USED	NOT USED							



Table 9. Programmable Settings for SM1 and SM2 (Including STANDBY)

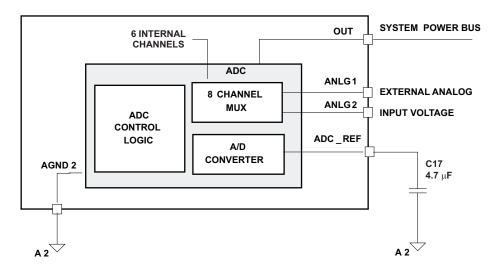
SetV4_ SM	SetV3_ SM	SetV2_ SM	SetV1_ SM	SetV0_ SM	Vset SM1	Vset SM2	SetV4_ SM	SetV3_ SM	SetV2_ SM	SetV1_ SM	SetV0_ SM	Vset SM1	Vset SM2
0	0	0	0	0	0.6	1	1	0	0	0	0	1.24	2.28
0	0	0	0	1	0.64	1.08	1	0	0	0	1	1.28	2.36
0	0	0	1	0	0.68	1.16	1	0	0	1	0	1.32	2.44
0	0	0	1	1	0.72	1.24	1	0	0	1	1	1.36	2.52
0	0	1	0	0	0.76	1.32	1	0	1	0	0	1.4	2.6
0	0	1	0	1	0.8	1.4	1	0	1	0	1	1.44	2.68
0	0	1	1	0	0.84	1.48	1	0	1	1	0	1.48	2.76
0	0	1	1	1	0.88	1.56	1	0	1	1	1	1.52	2.84
0	1	0	0	0	0.92	1.64	1	1	0	0	0	1.56	2.92
0	1	0	0	1	0.96	1.72	1	1	0	0	1	1.6	3
0	1	0	1	0	1	1.8	1	1	0	1	0	1.64	3.08
0	1	0	1	1	1.04	1.88	1	1	0	1	1	1.68	3.16
0	1	1	0	0	1.08	1.96	1	1	1	0	0	1.72	3.24
0	1	1	0	1	1.12	2.04	1	1	1	0	1	1.76	3.32
0	1	1	1	0	1.16	2.12	1	1	1	1	0	1.8	3.4
0	1	1	1	1	1.2	2.2	1	1	1	1	1	0.6	1

	SM1, SM2 PHASE		SMX_SLEW RATE, SMX = SM1 OR SM2								
S1S2_PHASE1	S1S2_PHASE0	PHASE	SLEWX_2	SLEWX_1	SLEWX_0	SM1 mV/μs	SM2 mV/μs				
0	0	0°	0	0	0	0.24	0.48				
0	1	90°	0	0	1	0.48	0.96				
1	0	180°	0	1	0	0.96	1.92				
1	1	270°	0	1	1	1.92	3.84				
			1	0	0	3.84	7.68				
			1	0	1	7.68	15.36				
			1	1	0	15.36	30.72				
			1	1	1	Imme	ediate				



FUNCTIONALITY GUIDE – ANALOG TO DIGITAL CONVERTER

ADC Input	t Channels	Trigger Mode	Conversion	Converter Mode	Trigge	r Delay	Wait Time, Multiple	Power Up Default
Internal	External		Count		Range	Min Step	Conversions	
Charge Current, Thermistor temperature, IC junction temperature, RTC_OUT voltage, OUT voltage, Battery voltage	ANLG1 and ANLG2 voltages	GPIB, I ² C driven, Repeat	1, 4, 8, 16, 32, 64, 128, 256	Single, Average, Find max value, Find min value	0-750 μs, 16 steps	50 μs	μs: 20, 40, 60, 80, 160, 240, 320, 640 ms: 1.28, 1.92, 2.56, 5.12, 10.24, 15.36, 20.48	ADC off
Fixed internally	Selectable via I ² C	Selectable via I ² C	Selectable via I ² C	Selectable via I ² C	Selectable via I ² C	Selectable via I ² C	Selectable via I ² C	





ANALOG-TO-DIGITAL CONVERTER

Overview

The TPS65810 has a 10 bit integrated successive approximation A/D, capable of running A/D conversions on eight distinct channels in a variety of modes. Two of the eight channels are connected to uncommitted pins ANLG1 and ANLG2, and can be used to convert external voltages. The other six channels monitor system parameters which are critical to the overall system monitoring. The channel selection is set via I²C.

A dedicated set of I²C registers enables configuration of the ADC to perform a conversion cycle with either a single conversion or a multiple conversions. The ALU generates a data set containing maximum value detection, minimum value detection and average value calculation for each conversion cycle. Each cycle can be performed a single time or multiple times.

Input Channels

The following channels are available for selection via the I²C register ADC_SET bits CHSEL_SET bits:



Channel	Connection	Parameter Sampled	Voltage Range Under Normal Operating Conditions	Special Features	Full Scale Reading (Internal reference selected)	LSB value
CH1	ANLG1 pin	User defined	User defined	Internal pullup current source programmable via I ² C: 0/ 10/50/60 μA	2.535 V	Full scale reading ÷ 1023
CH2	ANLG2 pin				2.535 V	
CH3	ISET1 pin	Voltage proportional to charge current	0 V (charger off) to 2.525 V (fast charge)	—	2.535 V	
CH4	TS pin	Voltage proportional to pack temperature	0 V (short) to 4.7V (no thermistor)	No internal pullup current, use external pullup resistor to bias pack thermistor	2.535 V	
CH5	Internal junction temperature	Voltage proportional to IC junction temperature	1.85 V at T _J = 25°C, –6.5 mV/°C slope typ	-	2.535 V	
CH6	RTC_OUT pin	Internal LDO output voltage	0 V to 3.3 V	—	4.7 V	
CH7	OUT pin	System Power bus voltage	0 V to 4.4 V	—	4.7 V	
CH8	BAT pin	Battery pack positive terminal voltage	0 V to 4.4 V	_	4.7 V	

Table 10. ADC input channel overview

FUNCTIONAL OVERVIEW

The TPS65810 ADC can be subdivided in four sections:

 Input selection: The input selection section has two major blocks, the input bias control and an 8 channel MUX. The input bias control provides the bias currents that are applied to pins ANLG1 and ANLG2. The bias currents for pins ANLG1 and ANLG2 are set on I²C register ADC_WAIT.

The ANLG1 pin current source is automatically enabled when the input power is detected, providing the required setup to measure a battery ID resistor (ANLG1 pin). ANLG1 and ANLG2 can be used to measure external resistive loads or analog voltages. The bias current sources are always connected to the OUT pin internally.

The internal MUX connects one of the monitored analog inputs to the ADC engine, following the selection defined on register ADC_SET.

2. ADC engine: The ADC engine uses an internal or external voltage reference, as defined by the ADC_REF bit on the ADC_SET control register. If the internal reference is selected ADC_REF is connected to an internal LDO that regulates the ADC_REF pin voltage to generate the ADC supply and internal voltage reference. The internal LDO maximum output current is 6 mA typical, and a conversion should be started only after the external capacitor is fully charged.

If an external reference is used it should be connected to the ADC_REF pin. When an external reference is selected the internal LDO connected to ADC_REF is disabled. Care must be taken when selecting an external reference as the ADC reference voltage, as it affects the ADC LSB absolute value.

3. Trigger control and synchronization: The ADC engine starts a conversion of the selected input when the trigger control circuit sends a start command. The trigger control circuit starts the ADC conversion and transfers the ADC output data to the arithmetic logic unit (ALU) at the end of the conversion. It also synchronizes the data transfer from the ALU to the I²C ADC_READING register at the end of a conversion cycle, and generates the ADC status information sent to the ADC registers.

An ADC engine conversion is triggered by the TPS65810 trigger control circuit using either an internal trigger or an external trigger. The internal trigger is automatically generated by the TPS65810 at the end of each ADC engine conversion, following the timing parameters set on I²C registers ADC_SET, ADC_DELAY and ADC_WAIT.

The GPIO3 pin can be used as an external trigger if the bit ADC_TRG_GPIO3 is set HI, in the I²C register ADC_DELAY. In the external trigger mode a new conversion is started after the GPIO3 pin has an edge transition, following the timing parameters set on I²C registers ADC_SET, ADC_DELAY and ADC_WAIT.

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- 4. Arithmetic Logic Unit (ALU): The ALU performs mathematical operations on the ADC output data as defined by the I²C ADC_READING registers. It executes average calculations or minimum /maximum detection. The result of the calculations is stored in a 11 bit accumulator register (1 bit allocated for carry-over). The accumulator value is transferred to the I²C data register at the end of a conversion cycle.
- A simplified block diagram for the ADC is shown in Figure 47.

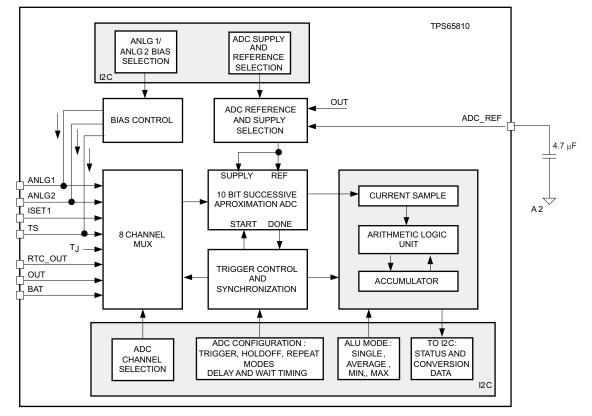


Figure 47. ADC Simplified Block Diagram

ADC Conversion Cycle

A conversion cycle includes all the steps required to successfully sample the selected input signal and transfer the converted data to the l^2C , generating an interrupt request to the host (pin: $HI \rightarrow LO$). The number of individual conversions (samples) in a conversion cycle is defined by the l^2C ADC_SET register bits READ_MODE settings, and can range from a single sample to 256 samples. The conversion cycle settings for the ALU is defined by register ADC_READING and it can be set to average, maximum value detection, minimum value detection or no processing (ADC engine output loaded in the accumulator directly).

The conversion cycle starts with the first sampling and ends when:

- The required ALU operations are performed on the final sample, and
- The ALU accumulator data is transferred to the I²C ADC_READING register, and
- The register bit ADC_STATUS in the ADC_READING register is set to LO.

A conversion cycle is always started by the external host when the ADC_EN bit in the ADC_SET register is toggled from LO to HI by a I²C write operation. Resetting the ADC_EN bit to LO before the current conversion cycle ends (INT: LO \rightarrow HI, ADC_STATUS bit set to LO) is not recommended, as the ADC keeps its current configuration until the current conversion cycle ends.

At the end of a conversion cycle the output data is stored at registers in the ALU block. The ADC_STATUS bit is set to LO (DONE) and an interrupt is generated (\overline{INT} pin: HI \rightarrow LO) if the ADC_STATUS bit is unmasked, at the interrupt masking registers INT_MASK. It should be noted that the minimum, maximum and average values are ALWAYS calculated by the ALU for each conversion cycle.

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The value loaded in the I²C registers ADC READING_HI and ADC READING_LO at the end of a conversion cycle is defined by control bits ADC_READ0 and ADC_READ1 in register ADC READING_HI. The average, minimum, maximum, and last-sample values for a conversion cycle can be read if the external host executes an I²C write operation, changing the values of bits ADC_READ0 and ADC_READ1, followed by an I²C read operation on registers ADC READING_HI and ADC READING_LO. The minimum, maximum, average, and last values have the same value if a conversion cycle with only one sample is executed.

The ADC_READ0 and ADC_READ1 bits *can not be modified* during the execution of a conversion cycle. A new conversion cycle should be started *only after* the current conversion cycle is completed, by toggling the ADC_EN bit from HI to LO and HI again.

External Trigger Operation

The trigger control circuit can be programmed to use an external signal to start a conversion. The TPS65810 GPIO3 input is configurable as an ADC trigger, with ADC conversion starting on either a rising edge or falling edge. When using an external trigger the trigger delay, trigger wait time delay and trigger hold-off mode can be programmed using I²C registers.

The procedure to start an externally-triggered conversion cycle has the following steps:

- 1. Verify that the current conversion cycle has ended (ADC_STATUS=LO, I²C register ADC_READING_HI)
- 2. Set ADC_EN=LO
- 3. Configure ADC sampling mode, ALU mode, trigger parameters, etc.
- 4. Set ADC_EN=HI

After step 4 the ADC is armed, waiting for an external trigger detection to start a conversion cycle. Similarly to the non-triggered mode, the ADC configuration *should not be modified until the current conversion cycle ends*. Note that in the external trigger mode the current cycle does not end if the converter is armed and an external trigger is not detected.

Detecting an External Trigger Event

An external trigger event is detected when the GPIO3 input has an edge that matches the edge detection programmed in the EDGE bit, at the I²C register ADC_DELAY. The internal ADC trigger can be delayed with respect to the external trigger signal edge. The delay time value is set by the ADC_DELAY register bits DELAY_n, and can range from 0 μ s (no delay) to 750 μ sec. A conversion is started only if the external trigger remains at its active level when the delay time expires, as shown in Figure 48. In a positive-edge detection the active trigger level is HI; in a negative-edge detection the active trigger level is LO.

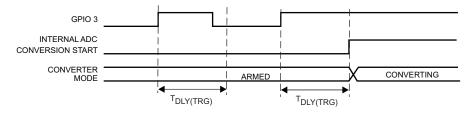


Figure 48. ADC Conversion Triggered by GPIO3 Positive Edge Triggered Active Level Hi

Executing Multiple-Sample Cycles With an External Trigger

When executing conversion cycles that require multiple samples it may be desirable to synchronize the input signal conversion using either an external trigger that has a periodic repetition rate or an external asynchronous trigger that indicates when the external input signal being converted is valid. The TPS65810 has additional operating modes and timing parameters that can be programmed using the I²C to configure multiple sample conversion cycles.

In multiple sample cycles the host can select the wait time between samples using the bits WAITn in the ADC_WAIT register to set the wait time between samples. The wait time is measured between the end of a conversion and the start of a new conversion.

With the default power-up settings (HOLDOFF=LO, ADC_DELAY register), the TPS65810 executes a multiple-sample conversion cycle if the first sample is taken when the trigger is at its active level. Subsequent samples are converted at the end of the wait time, even if the trigger returns to the non-active level. The external trigger level edge is ignored until the current conversion cycle ends.

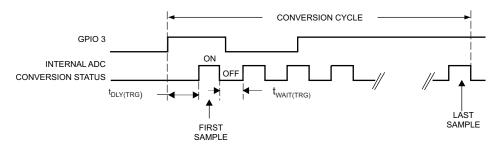


Figure 49. ADC Conversion Triggered by GPIO3 Positive Edge Triggered Active Level Hi, Holdoff = LC

If the sample conversion needs to be synchronized with an external trigger, during multiple sample conversion cycles, the control bit HOLDOFF should be set to HI. When the holdoff mode is active, the internal trigger starts a sample conversion only if the external trigger was detected and is at its active level at the end of the wait time, as shown in Figure 50.

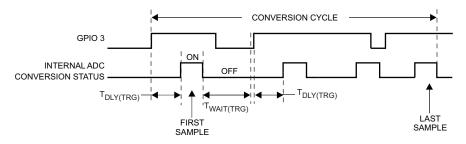


Figure 50. ADC Conversion Triggered by GPIO3 Positive Edge Triggered Active Level HI, Holdoff = HI, Four Sample Cycles

When the multiple sample cycles are executed the host must configure the maximum and minimum limits for the ADC output using registers DLOLIM1, DLOLIM2, DHILIM1 and DHILIM2. A conversion cycle ends if any individual conversion result exceeds the maximum limit value or is below the minimum limit value. When an out of limit conversion is detected an interrupt is sent to the host, and the ADC_STATUS bit on register ADC READING HI is set to DONE.

Continuous Conversion Operation (Repeat Mode)

The TPS65810 ADC can be set to operate in a continuous conversion mode, with back-to-back conversion cycles executed. The REPEAT mode is targeted at applications where an input is continuously monitored for a period of time, and the host must be informed if the monitored input is out of the range set by I²C registers DLOLIM1, DLOLIM2, DHILIM1 and DHILIM2. In REPEAT mode each conversion is started when the ADC trigger (internal or external) is detected, and a new conversion cycle is started when the current conversion cycle ends. All the trigger and sampling modes available for normal conversion cycles are available in repeat mode. Executing I²C read operations to get the ADC readings for average, minimum, maximum and last sample values is possible in REPEAT mode. However, this is not a recommended operation, as the REPEAT mode does not generate a DONE status flag making it difficult to synchronize the ADC data reading to the end of a conversion cycle.

The recommended use of the REPEAT mode is:

- 1. Configure the ADC conversion cycle: trigger mode, sample mode, select input signal, etc.
- 2. Configure the HI and LO limits for the ADC readings
- 3. Set the ADC DELAY register bit REPEAT to HI
- Toggle ADC_DELAY register bit ADC_EN bit from LO to HI



 Monitor the INT pin. An interrupt triggered by ADC_STATUS=LO indicates that the selected input signal is out of range

To exit the continuous mode the host must follow the steps below, if external trigger mode was set:

- 1. Exit external trigger mode
- 2. Set REPEAT bit to LO, effectively terminating the repeat mode. This generates an additional conversion; at the end of this conversion the ADC is ready for a new configuration.
- 3. Set ADC_EN to LO after on-going conversion ends.

To exit the continuous mode the host must follow the steps below, if internal trigger mode was set:

- 1. Set REPEAT bit to LO, effectively terminating the repeat mode.
- 2. Set ADC_EN to LO, after on-going conversion ends

ADC Input Signal Range Setting

The registers DHILIMn and DLOLIMn can be used by the host to set maximum and minimum limits for the DAC engine output. At the end of each conversion the ADC output is checked for the maximum and minimum limits, and a status flag is set if the converted data exceeds the high limit or is under the low limit. In multiple sample operation the converted data range is checked when all programmed samples have been converted.

The host can mask or unmask interrupts caused by the ADC range status bits using the INT_MASKn registers.



ADC State Machine

The ADC state machine with all the trigger and operation modes is shown in Figure 51.

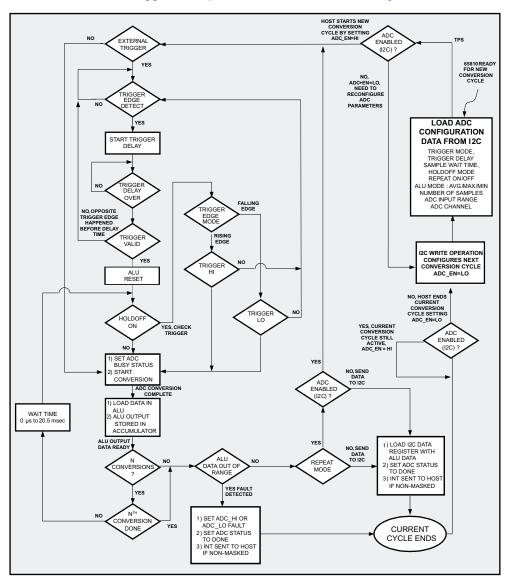


Figure 51. Trigger and Operation Modes for the ADC State Machine

BATTERY DETECTION CIRCUIT

The ANLG1 pin has an internal current source connected between OUT and ANLG1, which is automatically turned on when the OUT pin voltage exceeds the minimum system voltage set by the SYS_IN pin external resistive divider. The current levels for ANLG1 pin can be programmed via I²C register ADC_WAIT, bits BATID_n. An integrated switch discharges the BAT pin to AGND1 when V(ANLG1)> V(OUT) – $V_{(NOBATID)}$, enabling implementation of a battery removal function if an external pack resistor ID is connected between ANLG1 and ground.

The ANLG1 pin may be used to monitor other parameters than a pack ID resistor. When ANLG1 pin is used as a generic ADC analog input V(ANLG1) should never exceed V(OUT) – $V_{(NOBATID)}$, to avoid undesired battery discharge caused by activation of the battery pin discharge circuit.

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ADC – I²C REGISTERS

The I²C registers that control ADC-related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Default, initial power-up values are shown in bold. In the timing equations, replace Bn with 1 for HI state, and 0 for LO state.

			•	•				
	B7	B6	B5	B4	B3	B2	B1	B0
ADC_SET, A	DDRESS=1E, ALL E	ITS R/W						
Bit Name	ADC_ENABLE	ADC_REF_EN	CHSEL2_SET	CHSEL1_SET	CHSEL0_SET	READ_MODE2	READ_MODE1	READ_MODE0
Function	ADC ON/OFF CONTROL	ADC REFERENCE SELECTION	ADC	CHANNEL SELEC	CTION	ADC	SAMPLING SET	TINGS
When 0 When 1	OFF ON	Internal External	000 = ANLG1 001 = ANLG2	011 = V(TS) 100 = Tj	110 = V(OUT) 111 = V(BAT)	000 = 1 001= 4	011 = 16 100 = 32	110 = 128 111 = 256
			010 = V(ISET1)	101 = V(RTC_OUT)	Default = ANLG1	010 = 8	101 = 64	Default = 1
ADC READI	NG_HI, ADDRESS=1	F, BITS B3/B4 R/	W, ALL OTHER E	ITS READ ONLY	,	L		
Bit Name	ADC_STATUS	NOT USED	NOT USED	ADC_READ1	ADC_READ0	D10	D9_MSB	D8
Function	CURRENT CONVERSION STATUS	NOT USED	NOT USED		PUT DATA CTION	ADC AVERAGE CARRYOVER BIT		RSION OUTPUT
When 0	DONE	NOT USED	NOT USED	00=LAST 10 =	= MAXIMUM		VALID ONL	AFTER ADC
When 1	BUSY	NOT USED	NOT USED	01=AVERAGE Default= LAST	11 = MINIMUM			ON ENDS SEE ADING_LO
ADC READI	NG_LO, ADDRESS=	20, READ ONLY						
Bit Name	D7	D6	D5	D4	D3	D2	D1	D0_LSB
Function		ADC CC	NVERSION OUT	PUT BITS, VALID	ONLY AFTER AD	C CONVERSION	ENDS	
Value		0*512 + B9*256 + he LSB bit value						
DHILIM1, AD	DRESS=21, ALL BI	rs R/W						
Bit Name	NOT USED	NOT USED	NOT USED	NOT USED	NOT USED	DHILIM10	DHILIM9	DHILIM8
Function		I	RESERVED		I	ADC MAX IN	PUT LIMIT RANG MSBs)	E SETTING (3
DHILIM2, AD	DRESS=22, ALL BI	rs R/W					/	
Bit Name	DHILIM7	DHILIM6	DHILIM5	DHILIM4	DHILIM3	DHILIM2	DHILIM1	DHILIM0_LSB
Function			ADC MAX	X INPUT LIMIT R	ANGE SETTING (8 LSBs)		
DLOLIM1, A	DDRESS=23, ALL B	TS R/W						
Bit Name	NOT USED	NOT USED	NOT USED	NOT USED	NOT USED	DLOLIM10	DLOLIM9	DLOLIM8
Function		I	RESERVED		I	ADC MIN INPUT	LIMIT RANGE S	ETTING (3 MSBs)
DLOLIM2, A	DDRESS=24, ALL B	TS R/W				L		
Bit Name	DLOLIM7	DLOLIM6	DLOLIM5	DLOLIM4	DLOLIM3	DLOLIM2	DLOLIM1	DLOLIM0_LSB
Function		I	ADC MIN	I INPUT LIMIT RA	ANGE SETTING (8	3 LSBs)	L	
ADC_DELAY	, ADDRESS=25, AL	L BITS R/W						
Bit Name	ADC_TRG_GPIO3	EDGE _GPIO3	HOLDOFF	REPEAT	Delay_3	Delay_2	Delay_1	Delay_0
Function	USE GPIO3 AS ADC TRIGGER	GPIO3 TRIGGER MODE	ADC HOLDOFF ON/OFF CONTROL	REPEAT MODE ON/OFF	ADC	EXTERNAL TRIC	GER DELAY SE	TTING
When 0	OFF	Falling Edge	OFF	OFF	t _{DLY(TRIG)} = B4*40			nits = μs Default =
When 1	ON	Rising Edge	ON	ON		0	μ s	
ADC_WAIT,	ADDRESS=26, ALL	BITS R/W						
Bit Name	ADC_cH2I_D1	ADC_cH2I_D0	BATIDI_D1	BATIDI_D0	WAIT_D3	WAIT_D2	WAIT_D1	WAIT_LSB
Function		ANLG2 PULL-UP CURRENT ANLG1 PULL-UP CURRENT SOURCE VALUE SOURCE VALUE			ADC SAM	PLE WAIT TIME,	MULTIPLE SAMP	LES MODE
When 0 When 1	11:60 μΑ, 10:50 μΑ Defaul t	, 01:10 μA, 00: 0	11:60 μA, 10:50 00: WEAK	0 μΑ, 01:10 μΑ, C PULL UP	0000 = 0 0001 = 0.02 0010 = 0.04	0100 = 0.08 0101 = 0.16 0110 = 0.24	1000 = 0.64 1001 = 1.28 1010 = 1.92	1100 = 5.12 1101 = 10.24 1110 = 15.36
			Default: 00		0010 = 0.04 0011 = 0.06 Units = ms	0110 = 0.24 0111 = 0.32	1010 = 1.92 1011 = 2.56	1110 = 15.36 1111 = 20.48 Default = 0



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FUNCTIONALITY GUIDE - LED AND PERIPHERAL DRIVERS

Driver	PWM		Output	LED Cu	LED Current			
	Duty Cycle Range	# of Steps	Voltage	ю(Тур)	Max	Acc (%)		Default
SM3	Off (0%), 0.4% -99.6% Set via I ² C	256	5 V–25 V	Set by external resistor	25 mA	25	80	Off (0%)

OPEN DRAIN PWM DRIVERS

Driver	PWM Freq (kHz)	PW	M Duty Cycle	lo(max)	Power Up Default	
		Range	# of Steps	Min Step	mA	
PWM	0.5/1/1.5/2/3/ 4.5/7.8/15.6 Set via I ² C	Off (0%), 6.25% to 100 Set via I ² C	8	6.25%	150	Off(0%)
LED_PWM	15.625 or 23.4 , set via I ² C	Off(0%), 0.4% to 99.6% Set via I ² C	256	0.4%	150	Off (0%)

Driver	N DRAIN LED DRIVER Flash Period (same for RGB)			Flash On time (same for RGB)			Brightness (Individual R/G/B Control)			lo mA	Power Up Default
	Range	# of Steps	Min Step	Range	# of Steps	Min Step	Duty (%)	# of Steps	Min Steps		
RED, GREEN, BLUE	No flash, or 1–8 sec Set via I ² C	16	0.5 sec	0.1–0.6 sec Set via I ² C	8	0.1 sec	Off (0%), 3.125 to 96.87 Set via I ² C	32	3.125%	0/4/8/12	Flash Off, 0 mA, 0% brightness duty cycle

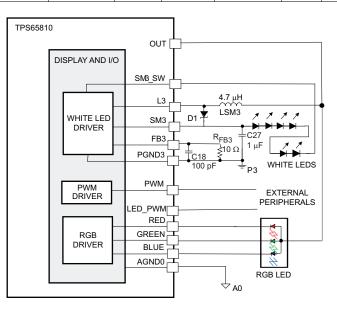


Figure 52. Required External Components, Recommended Values, External Connections



WHITE LED CONSTANT CURRENT DRIVER

The TPS65810 has an integrated boost converter (SM3) that is optimized to drive white LEDs connected in a series configuration. Up to six series white LEDs can be driven, with programmable current and duty cycle adjustable via a dedicated I²C register.

The SM3 boost converter (SM3) has a 30-V, 500-mA, low-side integrated power stage switch that drives the external inductor. Another integrated 30-V, 25-mA switch (LED switch) is used to modulate the brightness of the external white LEDs. A simplified block diagram is shown in Figure 53

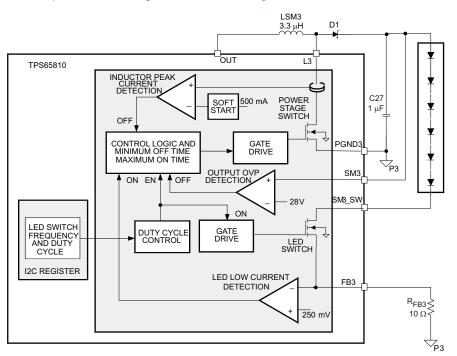


Figure 53. Simplified Block Diagram

The SM3 converter operates like a standard boost converter. The LED current is defined by the value of the external resistor R_{FB3} , connected from pin FB3 to AGND1. The integrated power stage switch control monitors the LED switch current (FB3) and the integrated power stage switch current, implementing a topology that effectively regulates the LED current independently of the input voltage and number of LEDs connected. The high voltage rating of the integrated switches enables driving up to six white LEDs, connected in a series configuration.

The internal LED switch, in series with the external LEDs, disconnects the LEDs from ground during shutdown. In addition, the LED switch is driven by a PWM signal that sets the duty cycle, enabling adjustment to the average LED current by modifying the settings of the I²C register SM3_SET. With this control method, the LED brightness depends on the LED switch duty cycle only, and is independent of the PWM control signal.

The duty cycle control used in the SM3 converter LED switch is implemented by generating a burst of high frequency pulses, with a pattern that is repeated periodically. For a duty cycle of 50%, all of the high frequency pulses have a 50% duty cycle. The duty cycle control sets individual pulses to 100% duty cycle when increasing the LED_PWM output duty cycle; for decreasing LED_PWM output duty cycles, individual pulses are set to 0% duty cycle. An example of distinct duty cycles is shown in Figure 54, the sum of the individual pulses on/off time over the repetition period are equivalent to the duty cycle obtained with traditional single-pulse duty cycle circuits.



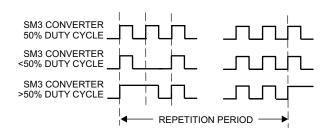


Figure 54. Example of Distinct Duty Cycles

The repetition period can be set using the register SOFT_RESET control bit SM3_LF_OSC to either 183 Hz (HI) or 122 Hz (LO). Each repetition period has a total of 256 pulses, enabling a resolution of 0.4% when programming the duty cycle.

SM3 Control Logic Overview

The SM3 boost converter operates in a pulse frequency modulation (PFM) scheme with constant peak current control. This control scheme maintains high efficiency over the entire load current range and enables the use of small external components, as the switching frequency can reach up to 1 MHz depending on the load conditions. The LED current ripple is defined by the external inductor size.

The converter monitors the sense voltage at pin FB3, and turns on the integrated power stage switch when $V_{(FB3)}$ is below the 250-mV (typ) internal reference voltage and the LED Switch is ON, starting a new cycle. The integrated power switch turns off when the inductor current reaches the internal 500-mA (typ) peak current limit, or if the switch is on for a period longer than the maximum on-time of 6 μ s (typ). The integrated power switch also turns off when the LED switch is set to OFF. As the integrated power switch is turned off, the external Schottky diode is forward biased, delivering the stored inductor energy to the output. The main switch remains off until the FB3 pin voltage is below the internal 250-mV reference voltage and the LED switch is turned ON, when it is turned on again.

This PFM peak current control scheme sets the converter in discontinuous conduction mode (DCM), and the switching frequency depends on the inductor, input/output voltage and LED current. Lower LED currents reduce the switching frequency, with high efficiency over the entire LED current range. This regulation scheme is inherently stable, allowing a wide range for the selection of the inductor and output capacitor.

Peak Current Control (Boost Converter)

The SM3 integrated power stage switch is turned on until the inductor current reaches the dc current limit $I_{MAX(L3)}$ (500 mA, typ). Due to internal delays, typically around 100 ns, the actual current exceeds the DC current limit threshold by a small amount. The typical peak current limit can be calculated as shown in Equation 8

$$I_{P(typ)} = I_{MAX(L3)} + \frac{V(OUT)}{L} \times 100 \text{ ns, or}: I_{P(typ)} = 500 \text{ mA} + \frac{V(OUT)}{L} \times 100 \text{ ns}$$
 (8)

The current overshoot is directly proportional to the input voltage, and inversely proportional to the inductor value.

Soft Start

All inductive step-up converters exhibit high in-rush current during start-up. If no special precautions are taken, voltage drops can be observed at the input supply rail during start-up, with unpredictable results in the overall system operation.

The SM3 boost converter limits the inrush current during start-up by increasing the current limit in three steps:

- 1. 125 mA (typ),
- 2. 250 mA (typ) and
- 3. 500 mA (typ)

The two initial steps (125 mA and 250 mA) are active for 256 power stage switching cycles.



Enabling the SM3 Converter

The SM3_SET I²C register controls the SM3 LED switch duty cycle. If the register is set to all zeros SM3 is set to OFF mode. When the host writes a value other than 00 in SM3_SET the SM3 converter is enabled, entering the soft start phase and then normal operation. The SM3 converter can operate with duty cycles varying from 0.4% to 99.6%, with LED switch frequencies of 122 Hz or 180 Hz. The LED switch operating frequency is set by bit SM3_LF, in the SOFT_RESET register.

Overvoltage Protection

The output voltage of the boost converter is sensed at pin SM3, and the integrated power stage switch is turned OFF when V(SM3) exceeds the internal overvoltage threshold V_{OVP3} . The converter returns to normal operation when V(SM3) < $V_{OVP3} - V_{HYS(OVP3)}$.

Under Voltage Lockout Operation

When the TPS65810 enters the UVLO mode, the SM3 converter is set to OFF mode with the power stage MOSFET switch and the LED switch open (off).

Thermal Shutdown Operation

When the TPS65810 enters the thermal shutdown mode, the SM3 converter is set to OFF mode with the power stage MOSFET switch and the LED switch open (off).

PWM DRIVERS

PWM Pin Driver

The TPS65810 offers one low-frequency, open-drain PWM driver, capable of driving up to 150 mA. The PWM frequency and duty cycle are defined by the PWM I^2C register settings. The PWM parameters are set in I^2C register PWM. Available frequency values range from 500 Hz to 15 kHz, with 8 frequency values and 16 duty cycle options (6.25% each).

LED_PWM Pin Driver

The TPS65810 has another PWM driver output (pin LED_PWM), which is optimized to drive a backlight LED. The LED_PWM driver controls the external LED current intensity using a pulse-width control method, with duty cycle being set by the I²C register LED_PWM.

The pulse width method implemented generates a burst of high frequency pulses, with a pattern that is repeated periodically. For a duty cycle of 50%, all of the high -frequency pulses have a 50% duty cycle. The duty cycle control sets individual pulses to 100% duty cycle when increasing the LED_PWM output duty cycle; for decreasing LED_PWM output duty cycles individual pulses are set to 0% duty cycle. An example of distinct duty cycles is shown in Figure 55; the sum of the individual pulses on/off time over the repetition period is equivalent to the duty cycle obtained with traditional single-pulse duty cycle circuits.

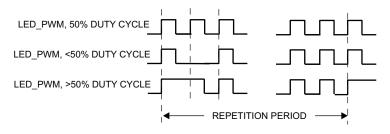


Figure 55. Example of Distinct Duty Cycles

The repetition period can be set using the register SOFT_RESET control bit SM3_LF_OSC to either 180 Hz (HI) or 122 Hz (LO). Each repetition period has a total of 256 pulses, enabling a resolution of 0.4% when programming the duty cycle. The LED_SET register enables control of the duty cycle via I²C, with duty cycle ranging from 0.4% to 99.6%. Setting the LED_SET register to all zeros forces the LED_PWM pin to 0% duty cycle (OFF).

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RGB Driver

The TPS65810 has a dedicated driver for an RGB external LED. Three outputs are available (pins RED, GREEN, BLUE), with common settings for operation mode (flash on/off, flash period, flash on time), LED current and phase delay between outputs. The TPS65810 RGB driver continually flashes the external LEDs connected to the RED, GREEN and BLUE pins using the flash operation parameters defined in register RGB_FLASH.

The currents for the external LEDs can be programmed via I^2C , and external resistors are not required to limit the LED current. However, they can be added to set the LED current if the available I^2C values are not compatible with the current application, as shown in the circuit below:

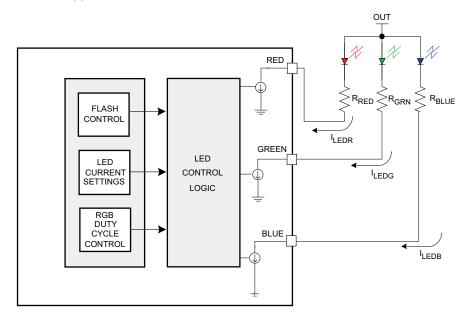


Figure 56. Limiting the External LED Current

The flashing-mode parameters defined in register RGB_FLASH enable setting the flashing period from 1 to 8 seconds in 0.5-sec steps, or to continuous operation. Flashing operation is enabled by setting the FLASH_EN bit in register RGB_FLASH to HI. This bit must be set HI to enable the RGB current-sink channels.

Each driver has an individual duty cycle control. The duty cycle modulation method used is similar to the PWM_LED duty cycle control, with high frequency pulses being generated when the driver (RED, GREEN, or BLUE pins) is ON. The repetition period for the RGB drivers has a total of 32 pulses, enabling a 3.125% resolution when programming the individual RED, GREEN and BLUE drivers duty cycles. The duty cycles for each driver can be set individually using control bits on registers RGB_RED, RGB_GREEN and RGB_BLUE.

The RGB drivers can be programmed to sink 4, 8, or 12 mA, with no external current limiting resistor.

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White LED, PWM Drivers — I²C Registers

The I²C registers that control LED AND PWM driver related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values. In the equations replace Bn with 1 for HI state, and 0 for LO state.

	B7	 B6	B5	B4	В3	B2	B1	B0
		-	БЭ	D4	БЭ	BZ	ы	ВО
	RESS = 16, ALL I	1	0110.15	01 0	0110 10 1	0110.10		0140 10 1
Bit Name	SM3_I7 set	SM3_I6 set	SM3_I5 set	SM3_I4 set	SM3_I3 set	SM3_I2 set	SM3_I1 set	SM3_I0 set
Function					CLE CONTROL			
Value			See Table 1	1 for SM3 duty cy	cle settings, defau	ult = 0 (OFF)		
RGB_FLASH, A	DDRESS = 17, A	LL BITS R/W	1	1	1		1	
Bit Name	FLASH_EN	FLASH_ON2	FLASH_ON1	FLASH_ON0	FLASH_PER3	FLASH_PER2	FLASH_PER1	FLASH_PER0
Function	FLASH MODE ON/OFF CTRL	FL/	ASH MODE ON TI	IME		FLASH MO	DE PERIOD	
When 0	OFF	See Table 12 for	RGB ON TIME s	ettings, default =	See Ta	ble 12 for RGB FL	ASH settings, det	ault = 1
When 1	ON		0.1					
RGB_RED, ADD	RESS = 18, ALL	BITS R/W						
Bit Name	RGB_ISET1	RGB_ISET0	PHASE	PWMR_D4	PWMR_D3	PWMR_D2	PWMR_D1	PWMR_D0
Function	RGB LED CURF	RENT SETTINGS	PHASE CONTROL		REG DRIV	ER DUTY CYCLE	CONTROL	
When 0		10= 8 mA 11=12 mA	GREEN out of Φ with RED & BLUE	S	See Table 12 for R	GB_RED DUTY s	ettings, default =	0
When 1	•		BLUE out of Φ with RED & GREEN	*				
RGB_GREEN, A	DDRESS = 19, A	LL BITS R/W						
Bit Name	NOT USED	NOT USED	NOT USED	PWMG_D4	PWMG_D3	PWMG_D2	PWMG_D1	PWMG_D0
Function	NOT USED	NOT USED	NOT USED		GREEN DRI	VER DUTY CYCL	E CONTROL	1
Value	NOT USED	NOT USED	NOT USED	Se	e Table 12 for RG	B_GREEN DUTY	settings, default	= 0
RGB_BLUE, AD	DRESS = 1A, AL	L BITS R/W	I	I				
Bit Name	NOT USED	NOT USED	NOT USED	PWMB_D4	PWMB_D3	PWMB_D2	PWMB_D1	PWMB_D0
Function	NOT USED	NOT USED	NOT USED		BLUE DRIV	ER DUTY CYCLE	CONTROL	
Value	NOT USED	NOT USED	NOT USED	S	ee Table 12 for R	GB_BLUE DUTY	settings. default =	: 0
PWM. ADDRESS	S = 1D, ALL BITS	R/W				_	0,	
Bit Name	PWM EN	PWM1 F2	PWM F1	PWM F0	PWM D3	PWM D2	PWM D1	PWM D0
Function	PWM ON/OFF CONTROL	_	ER FREQUENCY	SETTINGS	_	M DRIVER DUT	Y CYCLE SETTIN	GS
When 0	Disabled	000 = 15.6 kHz	011 = 3 kHz	110 = 1 kHz	See Table	a 13 for PWM DUT	Y settings. defau	lt = 0.0625
When 1	Enabled	001 = 7.8 kHz 010 = 4.5 kHz	100 = 2 kHz 101 = 1.5 kHz	111 = 500 Hz Default = 15.6 kHz			0,	
LED_PWM, ADD	RESS = 27, ALL	BITS R/W			1			
D'ANI AN		1		1	1	1		T
Bit Name	LPWM_7 set	LPWM_6 set	LPWM_5 set	LPWM_4 set	LPWM_3 set	LPWM_2 set	LPWM_1 set	LPWM_0 set
Bit Name Function	LPWM_7 set	LPWM_6 set	_	LPWM_4 set _PWM DRIVER DI	_	_	LPWM_1 set	LPWM_0 set

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Table 11. SM3 Duty Cycle Settings

								-	_			1		· · · · · · · · · · · · · · · · · · ·
Dec	B7-B0	Dcpu	Dec	B7-B0	Dcpu	Dec	B7-B0	Dcpu	Dec	B7-B0	Dcpu	Dec	B7-B0	Dcpu
0	0000 0000	-	52	0011 0100	0.203	104	0110 1000	0.406	156	1001 1100	0.609	208	1101 0000	0.813
1	0000 0001	0.004	53	0011 0101	0.207	105	0110 1001	0.41	157	1001 1101	0.613	209	1101 0001	0.816
2	0000 0010	0.008	54	0011 0110	0.211	106	0110 1010	0.414	158	1001 1110	0.617	210	1101 0010	0.82
3	0000 0011	0.012	55	0011 0111	0.215	107	0110 1011	0.418	159	1001 1111	0.621	211	1101 0011	0.824
4	0000 0100	0.016	56	0011 1000	0.219	108	0110 1100	0.422	160	1010 0000	0.625	212	1101 0100	0.828
5	0000 0101	0.02	57	0011 1001	0.223	109	0110 1101	0.426	161	1010 0001	0.629	213	1101 0101	0.832
6	0000 0110	0.023	58	0011 1010	0.227	110	0110 1110	0.43	162	1010 0010	0.633	214	1101 0110	0.836
7	0000 0111	0.027	59	0011 1011	0.23	111	0110 1111	0.434	163	1010 0011	0.637	215	1101 0111	0.84
8	0000 1000	0.031	60	0011 1100	0.234	112	0111 0000	0.438	164	1010 0100	0.641	216	1101 1000	0.844
9	0000 1001	0.035	61	0011 1101	0.238	113	0111 0001	0.441	165	1010 0101	0.645	217	1101 1001	0.848
10	0000 1010	0.039	62	0011 1110	0.242	114	0111 0010	0.445	166	1010 0110	0.648	218	1101 1010	0.852
11	0000 1011	0.043	63	0011 1111	0.246	115	0111 0011	0.449	167	1010 0111	0.652	219	1101 1011	0.855
12	0000 1100	0.047	64	0100 0000	0.25	116	0111 0100	0.453	168	1010 1000	0.656	220	1101 1100	0.859
13	0000 1101	0.051	65	0100 0001	0.254	117	0111 0101	0.457	169	1010 1001	0.66	221	1101 1101	0.863
14	0000 1110	0.055	66	0100 0010	0.258	118	0111 0110	0.461	170	1010 1010	0.664	222	1101 1110	0.867
15	0000 1111	0.059	67	0100 0011	0.262	119	0111 0111	0.465	171	1010 1011	0.668	223	1101 1111	0.871
16	0001 0000	0.063	68	0100 0100	0.266	120	0111 1000	0.469	172	1010 1100	0.672	224	1110 0000	0.875
17	0001 0001	0.066	69	0100 0101	0.27	121	0111 1001	0.473	173	1010 1101	0.676	225	1110 0001	0.879
18	0001 0010	0.07	70	0100 0110	0.273	122	0111 1010	0.477	174	1010 1110	0.68	226	1110 0010	0.883
19	0001 0011	0.074	71	0100 0111	0.277	123	0111 1011	0.48	175	1010 1111	0.684	227	1110 0011	0.887
20	0001 0100	0.078	72	0100 1000	0.281	124	0111 1100	0.484	176	1011 0000	0.688	228	1110 0100	0.891
21	0001 0101	0.082	73	0100 1001	0.285	125	0111 1101	0.488	177	1011 0001	0.691	229	1110 0101	0.895
22	0001 0110	0.086	74	0100 1010	0.289	126	0111 1110	0.492	178	1011 0010	0.695	230	1110 0110	0.898
23	0001 0111	0.09	75	0100 1011	0.293	127	0111 1111	0.496	179	1011 0011	0.699	231	1110 0111	0.902
24	0001 1000	0.094	76	0100 1100	0.297	128	1000 0000	0.5	180	1011 0100	0.703	232	1110 1000	0.906
25	0001 1001	0.098	77	0100 1101	0.301	129	1000 0001	0.504	181	1011 0101	0.707	233	1110 1001	0.91
26	0001 1010	0.102	78	0100 1110	0.305	130	1000 0010	0.508	182	1011 0110	0.711	234	1110 1010	0.914
27	0001 1011	0.105	79	0100 1111	0.309	131	1000 0011	0.512	183	1011 0111	0.715	235	1110 1011	0.918
28	0001 1100	0.109	80	0101 0000	0.313	132	1000 0100	0.516	184	1011 1000	0.719	236	1110 1100	0.922
29	0001 1101	0.113	81	0101 0001	0.316	133	1000 0101	0.52	185	1011 1001	0.723	237	1110 1101	0.926
30	0001 1110	0.117	82	0101 0010	0.32	134	1000 0110	0.523	186	1011 1010	0.727	238	1110 1110	0.93
31	0001 1111	0.121	83	0101 0011	0.324	135	1000 0111	0.527	187	1011 1011	0.73	239	1110 1111	0.934
32	0010 0000	0.125	84	0101 0100	0.328	136	1000 1000	0.531	188	1011 1100	0.734	240	1111 0000	0.938
33	0010 0001	0.129	85	0101 0101	0.332	137	1000 1001	0.535	189	1011 1101	0.738	241	1111 0001	0.941
34	0010 0010	0.133	86	0101 0110	0.336	138	1000 1010	0.539	190	1011 1110	0.742	242	1111 0010	0.945
35	0010 0011	0.137	87	0101 0111	0.34	139	1000 1011	0.543	191	1011 1111	0.746	243	1111 0011	0.949
36	0010 0100	0.141	88	0101 1000	0.344	140	1000 1100	0.547	192	1100 0000	0.75	244	1111 0100	0.953
37	0010 0101	0.145	89	0101 1001	0.348	141	1000 1101	0.551	193	1100 0001	0.754	245	1111 0101	0.957
38	0010 0110	0.148	90	0101 1010	0.352	142	1000 1110	0.555	194	1100 0010	0.758	246	1111 0110	0.961
39	0010 0111	0.152	91	0101 1010	0.355	143	1000 1111	0.559	195	1100 0011	0.762	247	1111 0111	0.965
40	0010 1000	0.156	92	0101 1100	0.359	144	1001 0000	0.563	196	1100 0100	0.766	248	1111 1000	0.969
40	0010 1000	0.156	92	0101 1100	0.363	144	1001 0000	0.566	190	1100 0100	0.786	240	1111 1000	0.969
41	0010 1001	0.16	93 94	0101 1101	0.363	145	1001 0001	0.566	197	1100 0101	0.77	249 250	1111 1001	0.973
42	0010 1010	0.164	94 95	0101 1110	0.367	140	1001 0010	0.57	198	1100 0110	0.773	250	1111 1010	0.977
		0.168	95 96		0.371	147		0.574						0.98
44	0010 1100			0110 0000			1001 0100		200	1100 1000	0.781	252	1111 1100 1111 1101	
45	0010 1101	0.176	97	0110 0001	0.379	149		0.582	201	1100 1001	0.785	253		0.988
46	0010 1110	0.18	98	0110 0010	0.383	150	1001 0110	0.586	202	1100 1010	0.789	254	1111 1110	0.992
47	0010 1111	0.184	99	0110 0011	0.387	151	1001 0111	0.59	203	1100 1011	0.793	255	1111 1111	0.996
48	0011 0000	0.188	100	0110 0100	0.391	152	1001 1000	0.594	204	1100 1100	0.797			
49	0011 0001	0.191	101	0110 0101	0.395	153	1001 1001	0.598	205	1100 1101	0.801			
50	0011 0010	0.195	102	0110 0110	0.398	154	1001 1010	0.602	206	1100 1110	0.805			
51	0011 0011	0.199	103	0110 0111	0.402	155	1001 1011	0.605	207	1100 1111	0.809			

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RGB_D4	RGB_D3	RGB_D2	RGB_D1	RGB_D0	DC(%)	FLASH_PER3	FLASH_PER2	FLASH_PER1	FLASH_PER0	P(s)
0	0	0	0	0	0.00	0	0	0	0	1
0	0	0	0	1	3.23	0	0	0	1	1.5
0	0	0	1	0	6.45	0	0	1	0	2
0	0	0	1	1	9.68	0	0	1	1	2.5
0	0	1	0	0	12.90	0	1	0	0	3
0	0	1	0	1	16.13	0	1	0	1	3.5
0	0	1	1	0	19.35	0	1	1	0	4
0	0	1	1	1	22.58	0	1	1	1	4.5
0	1	0	0	0	25.80	1	0	0	0	5
0	1	0	0	1	29.03	1	0	0	1	5.5
0	1	0	1	0	32.25	1	0	1	0	6
0	1	0	1	1	35.48	1	0	1	1	6.5
0	1	1	0	0	38.70	1	1	0	0	7
0	1	1	0	1	41.93	1	1	0	1	7.5
0	1	1	1	0	45.15	1	1	1	0	8
0	1	1	1	1	48.38	1	1	1	1	Continuous
1	0	0	0	0	51.60					
1	0	0	0	1	54.83					
1	0	0	1	0	58.05		FLASH_ON2	FLASH_ON1	FLASH_ON0	ON_TIME (s)
1	0	0	1	1	61.23		0	0	0	0.1
1	0	1	0	0	64.50		0	0	1	0.15
1	0	1	0	1	67.73		0	1	0	0.2
1	0	1	1	0	70.95		0	1	1	0.25
1	0	1	1	1	74.18		1	0	0	0.3
1	1	0	0	0	77.40		1	0	1	0.4
1	1	0	0	1	80.63		1	1	0	0.5
1	1	0	1	0	83.85		1	1	1	0.6
1	1	0	1	1	87.08					
1	1	1	0	0	90.30					
1	1	1	0	1	93.53					
1	1	1	1	0	96.75					
1	1	1	1	1	99.98					

Table 12. RGB Duty Cycle Control Settings

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	PWM FREQU	ENCY TABLE			PW	M_D DUTY CY	CLE	
PWM_F2	PWM_F1	PWM_F0	F (Hz)	PWM2_D3	PWM2_D2	PWM2_D1	PWM2_D0	D_cycle (pu)
0	0	0	15600	0	0	0	0	0.0625
0	0	1	7800	0	0	0	1	0.125
0	1	0	4500	0	0	1	0	0.1875
0	1	1	3000	0	0	1	1	0.25
1	0	0	2000	0	1	0	0	0.3125
1	0	1	1500	0	1	0	1	0.375
1	1	0	1000	0	1	1	0	0.4375
1	1	1	500	0	1	1	1	0.5
				1	0	0	0	0.5625
				1	0	0	1	0.625
				1	0	1	0	0.6875
				1	0	1	1	0.75
				1	1	0	0	0.8125
				1	1	0	1	0.875
				1	1	1	0	0.9375
				1	1	1	1	1

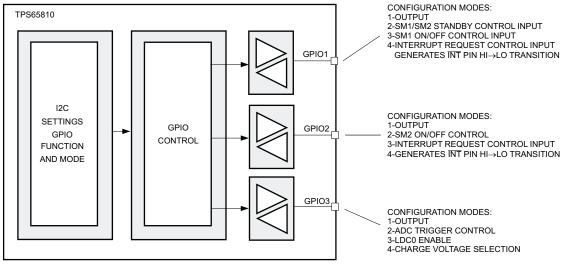
Table 13. PWM Frequency and Duty Cycle Settings

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FUNCTIONALITY GUIDE – GENERAL PURPOSE INPUTS/OUTPUTS

CONFIGURED AS O	UTPUT	С	ONFIGURED AS INPUT		POWER-UP					
OUTPUT LEVEL	lo(max) mA	A/D CO	NVERSION START TRIG	GER	DEFAULT					
HI or LO at output set via I ² C	5	Falling	Falling or rising edge selected via I ² C							
GPIO2 FUNCTIONS										
CONFIGURED AS O	UTPUT	C	ONFIGURED AS INPUT		POWER-UP					
OUTPUT LEVEL	lo(max) mA	HOST INTERRUPT REQUEST	SM2	DEFAULT						
HI or LO at output set via I ² C	5	Set \overline{INT} pin to LO via I ² C when GPIO2 pin edge is detected. Rising or falling edge detection selected via I ² C	GPIO2 level sets SM2 c GPIO2 pin level (HI select	Input, SM2 enable, SM2 ON@ GPIO2=HI						
		The host interrupt request and and they shou								
GPIO1 FUNCTIONS										
CONFIGURED AS O	UTPUT	С	ONFIGURED AS INPUT		POWER-UP					
OUTPUT LEVEL	lo(max) mA	HOST INTERRUPT REQUEST	SM1 ENABLE	SM1 AND SM2 STANDBY CONTROL	DEFAULT					
HI or LO at output set via I ² C	C when GPIO1 pin edge is detected. Rising or falling edge detection set via I ² C converter ON/OFF operation. GPIO2 pin level (HI or LO) for ON SM1 conver mode. GPIO		GPIO1 level sets SM2 and SM1 converters in standby mode. GPIO1 pin level (HI or LO) for standby mode set selected via I ² C	Input, SM1 enable, SM1 ON@ GPIO1=HI						
		The host interrupt request, functions are mutually exclusive	~							







General Purpose I/Os — GPIO 1, 2, 3

The TPS65810 integrates 3 general purpose open drain ports (GPIOs) that can be configured as selectable inputs or outputs. When configured as outputs the output level can be set to LO or HI via I^2C commands. When the GPIOs are configured as inputs the action to be taken when a transition or HI/LO level is detected at the GPIO pin is selectable via I^2C .

When configured as inputs the GPIOs can be set in the following modes:

- 1. Interrupt request: In this mode of operation, a transition at the GPIO pin generates an interrupt request at the interrupt controller. The GPIO interrupt request can be masked at the INT_MASK register. This operation mode is available for GPIO's 1 and 2.
- SM1 and SM2 control: The GPIO's can be used to turn the converters SM1 and SM2 ON/OFF, as well as setting them in standby mode. This control mode is available for GPIO1 (SM1 on/off and SM1/SM2 standby) and GPIO2 (SM2 on/off control).
- 3. ADC trigger: GPIO3 can be configured as an external ADC trigger. The GPIO3 trigger configuration bit is located at the ADC register ADC_DELAY.

GPIOs Input Level Configuration

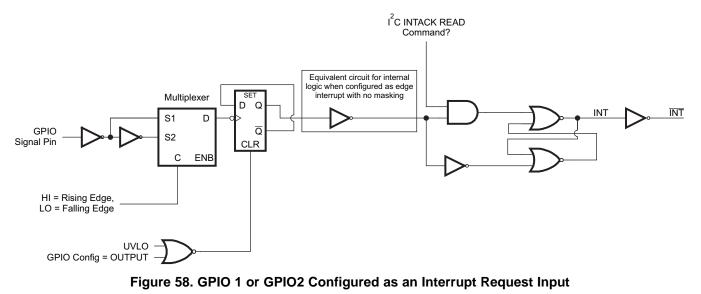
When using I²C commands, the GPIO1 and GPIO2 pins can be configured as logic output signals or as level-controlled inputs which enables (or disables) the switch mode converters SM1 and/or SM2. These pins may also be configured as rising- or falling-edge-triggered inputs to externally control the generation of an interrupt signal (INT), if desired.

The GPIO3 pin may be used as an external trigger source to start an A/D conversion cycle or as a logic output.

See Figure 58 for a description of the logic used for GPIO1 and GPIO2 inputs when configured for edge-triggered interrupt generation. The signal from the GPIO pin input is double-latched before being sent to the interrupt contoller logic. The inversion of the Q output from the first flip-flop must be HI to allow the output latch to be cleared when a READ command occurs. On the initial edge of the GPIO signal, the Q output of the flip-flop is set (HI). The INT line is asserted (LO) after the initial selected edge from the GPIO pin. On the next falling (or rising) edge of the GPIO pin, the interrupt can again be cleared (which allows the INT pin to go back high). The INT signal is cleared (set back HI) after an I²C READ operation is performed.

Thus, two successive edges of the GPIO signal, followed by an I²C READ command, are required to clear the INT pin output. If no I²C READ commands occur, repeatedly applying edges to the GPIO pin does not toggle the state of the INT pin output.

In addition to an I²C READ command after two GPIO edges, a UVLO event or reconfiguration of the GPIO pins as outputs also de-asserts the INT signal.





Function Implementation: I²C Commands Versus GPIO Commands

Some of the GPIO SM1/SM2 control functions overlap I^2C register control functions. Table 14 describes the TPS65810 action when the GPIO's command and I^2C registers commands are not compatible with each other.

Table 14. GPIO Commands and I²C Registers Commands

SM1 AND SM2 ON/OFF I ² C COMMAND	GPIO COMMAND	SM1 OR SM2 MODE SET
CONVERTER DISABLED	CONVERTER DISABLED	DISABLED
CONVERTER ENABLED	DON'T CARE	ENABLED
DON'T CARE	CONVERTER ENABLED	ENABLED
SM1 AND SM2 STANDBY I ² C COMMAND	GPIO COMMAND	SM1 OR SM2 MODE SET
DO NOT SET STANDBY	DON'T CARE	NORMAL
SET STANDBY	SET STANDBY	STANDBY
DON'T CARE	DO NOT SET STANDBY	NORMAL

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GPIO Configuration Table

Table 15 describes the I^2C register settings required to program the available GPIO modes. The GPIO pins logic level is available at register SM1_STANDBY, bits B5, B6 and B7.

GPIO MODE	I ² C REGISTERS	I ² C REGISTER BIT SETTING	ADDITIONAL DETAILS
GPIO3 = OUTPUT	GPIO3	GPIO3I/O=HI AND GPIO3OUT=HI	GPIO3 PIN SET TO HIGH IMPEDANCE MODE
		GPIO3I/O=HI AND GPIO3OUT=LO	V(GPIO3) = V _{OL}
GPIO3 =INPUT ADC CONVERSION	GPIO3 AND ADC_DELAY	GPIO3I/O=LO AND ADC_TRG_GPIO3=HI AND EDGE_GPIO3=HI	GPIO3 pin rising edge triggers ADC conversion
START TRIGGER		GPIO3I/O=LO AND ADC_TRG_GPIO3=HI AND EDGE_GPIO3=LO	GPIO3 pin falling edge triggers ADC conversion
GPIO2 = OUTPUT	GPIO12	GPIO2I/O=HI AND GPIO2OUT=HI	GPIO2 PIN SET TO HIGH IMPEDANCE MODE
		GPIO2I/O=HI AND GPIO2OUT=LO	V(GPIO2) = V _{OL}
GPIO2=INPUT, HOST INTERRUPT	GPIO12 AND GPIO3	GPIO2I/O=LO AND GPIO2INT=HI AND GPIO2LVL=HI AND GPIO2SM2=LO	\overline{INT} pin HI \rightarrow LO \rightarrow HI at V(GPIO2) falling edge
REQUEST		GPIO2I/O=LO AND GPIO2INT=HI AND GPIO2LVL=HI AND GPIO2SM2=LO	$\overline{\text{INT}} \text{ pin HI} \rightarrow \text{LO} \rightarrow \text{HI}$ at V(GPIO2) rising edge
GPIO2=INPUT, SM2 ENABLE	GPIO12 AND GPIO3	GPIO2I/O=LO AND GPIO2INT=LO AND GPIO2LVL=HI AND GPIO2SM2=HI	SM2 converter ON at V(GPIO2)=HI
		GPIO2I/O=LO AND GPIO2INT=LO AND GPIO2LVL=LO AND GPIO2SM2=HI	SM2 converter ON at V(GPIO2)=LO
GPIO1 = OUTPUT	GPIO12	GPIO1I/O=HI AND GPIO1OUT=HI	GPIO1 PIN SET TO HIGH IMPEDANCE MODE
		GPIO1I/O=HI AND GPIO1OUT=LO	V(GPIO1) = V _{OL}
GPIO1=INPUT, HOST INTERRUPT REQUEST	GPIO12 AND GPIO3	GPIO1I/O=LO AND GPIO1INT=HI AND GPIO1LVL=HI AND GPIO1SM1=LO AND GPIO1SMSBY=LO	INT pin HI→LO→HI at V(GPIO1) falling edge
		GPIO1I/O=LO AND GPIO1INT=HI AND GPIO1LVL=LO AND GPIO1SM1=LO AND GPIO1SMSBY=LO	INT pin HI→LO→HI at V(GPIO1) rising edge
GPIO1=INPUT, SM1 ENABLE	GPIO12 AND GPIO3	GPIO1I/O=LO AND GPIO1INT=LO AND GPIO1LVL=HI AND GPIO1SM1=HI AND GPIO1SMSBY=LO	SM1 converter ON at V(GPIO1)=HI
		GPIO1I/O=LO AND GPIO1INT=LO AND GPIO1LVL=LO AND GPIO1SM1=HI AND GPIO1SMSBY=LO	SM1 converter ON at V(GPIO1)=LO
GPIO1=INPUT, SM1/SM2 STANDBY CONTROL	GPIO12 AND GPIO3	GPIO1I/O=LO AND GPIO1INT=LO AND GPIO1LVL=HI AND GPIO1SM1=LO AND GPIO1SMSBY=HI	SM1/SM2 converter standby set at V(GPIO1) = HI
		GPIO1I/O=LO AND GPIO1INT=LO AND GPIO1LVL=LO AND GPIO1SM1=LO AND GPIO1SMSBY=HI	SM1/SM2 converter standby set at V(GPIO1) = LO

Table 15. Recommended GPIO Configuration Procedure



GPIOs — I²C Registers

The I²C registers that control GPIO-related functions are shown below. The HEX address for each register is shown by the register name, together with the R or W functionality for the register bits. Shaded values indicate default initial power-up values.

	B7	B6	B5	B4	B3	B2	B1	B0
GPIO12, ADDR	ESS=1B, ALL BIT	S R/W						
Bit Name	GPIO2I/O	GPIO1I/O	GPIO2OUT	GPIO1OUT	GPIO2LVL	GPIO1LVL	GPIO1SMSBY	GPIO1SM1
Function	GPIO2 MODE	GPIO1 MODE	SET GPIO2 LEVEL (OUTPUT ONLY)	SET GPIO1 LEVEL (OUTPUT ONLY)	GPIO2 EDGE AND LEVEL DETECTION	GPIO1 EDGE AND LEVEL DETECTION	GPIO 1 CONTROLS SM1 AND SM2 STANDBY ON/OFF	GPIO1 CONTROLS SM1 ON/OFF
When 0	INPUT	INPUT	LOW	LOW	RISING EDGE, LO LEVEL	RISING EDGE, LO LEVEL	DISABLED	DISABLED
When 1	OUTPUT	OUTPUT	HIGH	HIGH	FALLING EDGE, HI LEVEL	FALLING EDGE, HI LEVEL	ENABLED	ENABLED
GPIO3, ADDRE	SS=1C, ALL BITS	R/W						
Bit Name	GPIO3I/O	GPIO3OUT	LDO0_EN	CHG_VOLT	NOT USED	GPIO2 INT	GPIO1 INT	GPIO2SM2
Function	GPIO3 MODE	SET GPIO3 LEVEL (OUTPUT ONLY)	LDO0 ON/OFF CONTROL	CHARGE VOLTAGE SAFETY BIT	NOT USED	GPIO2 TRIGGERS INT:HI→LO	GPIO1 TRIGGERS INT:HI→LO	SM2 ON/OFF CONTROL
When 0	INPUT	LOW	OFF	4.20 V	NOT USED	DISABLED	DISABLED	DISABLED
When 1	OUTPUT	HIGH	ON	4.36 V	NOT USED	ENABLED	ENABLED	ENABLED



(9)

APPLICATION INFORMATION

INDUCTOR AND CAPACITOR SELECTION — CONVERTERS SM1 AND SM2

SM1 and SM2 are designed with internal voltage mode compensation and the stabilization is based on choosing an LC filter that has a corner frequency around 27 kHz. It is not recommended to use LC values that would be outside the range of 13 kHz to 40 kHz.

Equation 9 calculates the corner frequency of the output LC filter. The standard recommended LC values are 3.3 μ H and 10 μ F.

$$F = \frac{1}{2\pi\sqrt{LC}} = 27.7 \text{ kHz}$$
 (a) for L = 3.3 μ H and C = 10 μ F

The inductor value, along with the input voltage VIN, output voltage V_{OUT} and switching frequency f define the ripple current. Typically the ripple current target is 30% of the full load current. At light loads it is desirable for ripple current to be less then 150% of the light load current.

The inductor should be chosen with a rating to handle the peak ripple current., if an inductor's current gets higher than its rated saturation level (DCR), the inductance starts to fall off, and the inductor's ripple current increases exponentially. The DCR of the inductor plays an important role in efficiency and size of the inductor. Larger diameter wire has less DCR but may increase the size of the inductor

Equation 10 calculates the target inductor value. If an inductor value has already been chosen, Equation 11, calculates the inductor's ripple current under static operating conditions. The ripple amplitude can be calculated during the on time (positive ramp) or during the off time (negative ramp). It is easiest to calculate the ripple using the off time since the inductor's voltage is the output voltage.

$$I_{\text{target}} = \frac{V_{\text{OUT}}}{0.3 \times I_{\text{OUT}_\text{MAX}}} \frac{\left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}_\text{MAX}}}\right)}{f}$$
(10)
$$\Delta I_{\text{L}} = \frac{V_{\text{L}}}{L} \times \Delta t = \frac{V_{\text{OUT}}}{L} \frac{\left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right)}{f}$$
(11)

Equation 12 calculates the peak current due to the output load and ripple current

$$I_{Lmax} = I_{OUTmax} + \frac{\Delta I_{L}}{2}$$
(12)

For a faster transient response, a lower inductor and higher capacitance allows the output current to ramp faster, while the addition capacitance holds up the output longer (a $2.2 - \mu H$ inductor in combination with a $22 - \mu F$ output capacitor are recommended).

The highest inductor current occurs at the maximum input voltage. The peak inductor current during a transient may be higher than the steady state peak current and should be considered when choosing an inductor. Monitoring the inductor current for non-saturation operation during a transient of $1.2 \times I_loadmax$ at Vin_max ensures adequate saturation margin.

DEVICE	INDUCTOR VALUE	ТҮРЕ	COMPONENT SUPPLIER
DCDC3 converter	3.3 μΗ	CDRH2D14NP-3R3	Sumida
	3.3 μH	PDS3010-332	Coilcraft
	3.3 μH	VLF4012AT-3R3M1R3	TDK
	2.2 μH	VLF4012AT-2R2M1R5	TDK
	2.2 μH	NR3015T2R2	Taoup-Uidem

Table 16. Inductors for Typical Operation Conditions

DEVICE	INDUCTOR VALUE	ТҮРЕ	COMPONENT SUPPLIER
DCDC2 converter	3.3 μΗ	CDRH2D18/HPNP-3R3	Sumida
	3.3 μΗ	VLF4012AT-3R3M1R3	TDK
	2.2 μΗ	VLCF4020-2R2	TDK
DCDC1 converter	3.3 μΗ	CDRH3D14/HPNP-3R2	Sumida
	3.3 μΗ	CDRH4D28C-3R2	Sumida
	3.3 μΗ	MSS5131-332	Coilcraft
	2.2 μH	VLCF4020-2R2	TDK

Table 16. Inductors for Typical Operation Conditions (continued)

OUTPUT CAPACITOR SELECTION, SM1, SM2 CONVERTERS

The advanced Fast Response voltage mode control scheme of the SM1, SM2 converters implemented in the TPS65020 allow the use of small ceramic capacitors with a typical value of 10 μ F for a 3.3- μ H inductor, without having large output voltage under and overshoots during heavy load transients.

Ceramic capacitors having low ESR values have low output voltage ripple, and recommended values and manufacturers are listed in Table 1. Often, due to the low ESR, the ripple current rating of the ceramic capacitor is adequate to meet the inductor's currents requirements.

The RMS ripple current is calculated as:

$$I_{\text{RMSCout}} = \frac{1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}}{2 \times L \times f} \times \frac{1}{\sqrt{3}}$$

\/

(13)

At nominal load current, the inductive converters operate in PWM mode. The overall output voltage ripple is the sum of the voltage spike caused by the output capacitor ESR plus the voltage ripple caused by charging and discharging the output capacitor: The output voltage ripple is maximum at the highest input voltage Vin.

$$V_{\text{RMSCout}} = \frac{1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}}{L \times f} \times \left(\frac{1}{8 \times \text{Cout} \times f} + \text{ESR}\right)$$
(14)

At light load currents, the converters operate in PFM and the output voltage ripple is dependent on the output capacitor value. The output voltage ripple is set by the internal PFM output voltage comparator delay and the external capacitor. The typical output voltage ripple is less than 1% of the nominal output voltage.

CAPACITOR VALUE	CASE SIZE	COMPONENT SUPPLIER	COMMENTS
22 μF	1260	TDK C3216X5R0J226M	Ceramic
22 µF	1260	Taiyo Yuden JMK316BJ226ML	Ceramic
10 µF	0805	Taiyo Yuden JMK212BJ106M	Ceramic
10 μF	0805	TDK C2012X5R0J106M	Ceramic
22 μF	0805	TDK C2012X5R0J226MT	Ceramic
22 µF	0805	Taiyo Yuden JMK212BJ226MG	Ceramic



INPUT CAPACITOR SELECTION, SM1, SM2 CONVERTERS

Buck converters have a pulsating input current that can generate high input voltage spikes at V_{IN}. A low ESR input capacitor is required to filter the input voltage, minimizing the interference with other circuits connected to the same power supply rail. Each dc-dc converter requires a 10-µF ceramic input capacitor on its input pin.

OUTPUT VOLTAGE SELECTION, SM1, SM2 CONVERTERS

Typically the output voltage is programmed by the I²C. An external divider can be added to raise the output voltage, if the available I²C values do not meet the application requirements. Care must be taken with this special option, because this external divider (gain factor) would apply to any selected I²C output voltage value for this converter.

Equation 16 calculates R1, Let R2 = 20 k Ω :

$$R1 = \left\lfloor \frac{V_{SMxOUT}}{V_{FB}} - 1 \right\rfloor R2$$

(16)

(18)

(19)

(20)

where V_{FB} is the I²C selected voltage, is the desired output voltage and R1/R2 is the feedback divider.

DESIGN EXAMPLES

SM1, SM2 CONVERTER DESIGN EXAMPLE

Design Conditions and Parametrs for SM1 or SM2:

Vin_SM1/2: 4.6 V typical (may be less if input source is limited).

Vout SM1/2: 1.24 V lout max: 0.6 A

fsw = 1500 kHz

fc = 25 kHz

$$L_{\text{target}} = \frac{V_{\text{OUT}}}{0.3 \times I_{\text{OUT}_\text{MAX}}} \frac{\left[1 - \frac{V_{\text{OUT}}}{V_{\text{IN}_\text{MAX}}}\right]}{\text{fsw}} = 3.35 \,\mu\text{H}, \, 3.3 \,\mu\text{H} \text{ is a good target.}$$
(17)

 $C = \frac{1}{L[2 \times \pi \times fc]^2} = 10.5 \,\mu\text{F}$ 10 μF is a good target.

CHARGER DESIGN EXAMPLE

Design Conditions and Parameters for Charger:

Vout: 4.6 V; (OUT pin is input to charger)

Fast-charge current, I_{PGM}: 1 A

DPPM-OUT threshold: 4.3 V; (charging current reduces when OUT falls to this level)

Safety timer: 5 h

Battery short-circuit delay, t_{DELAY}: 47 µs; (delays BAT short circuit during hot plug of battery)

TS temperature range: disabled

 $K_{SET} = 400; V_{SET} = 2.5 V; K_{DPPM} = 1.15; I_{DPPM} = 100 \ \mu\text{A}; K_{TMR} = 0.36 \ \text{s}/\Omega$

Program Fast Charge Current Level:

$$R_{ISET} = \frac{K_{SET} \times V_{SET}}{I_{PGM}} = 1 \text{ k}\Omega$$

Program DPPM_OUT Voltage Level (Level at Which Charging Current Reduces)

$$R_{DPPM} = \frac{V_{DPPM}OUT}{K_{DPPM} \times I_{DPPM}} = 3.74 \text{ k}\Omega$$

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Program BAT Short Circuit Delay (Used for inserting battery)

 $C_{DPPM} = t_{DELAY} \times I_{DPPM} = 4.7 \text{ Nf}$

Program 5-Hour Safety Timer

$$R_{TMR} = \frac{t_{SAFETY-HR} \times 3600 \text{ sec/hr}}{K_{TMR}} = 50 \text{ k}\Omega$$

(21)

(22)

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS65810RTQR	ACTIVE	QFN	RTQ	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65810RTQRG4	ACTIVE	QFN	RTQ	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65810RTQT	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65810RTQTG4	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65811RTQR	ACTIVE	QFN	RTQ	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65811RTQRG4	ACTIVE	QFN	RTQ	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65811RTQT	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TPS65811RTQTG4	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal					-							
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS65810RTQR	QFN	RTQ	56	2000	330.0	16.4	8.3	8.3	2.25	12.0	16.0	Q2
TPS65810RTQT	QFN	RTQ	56	250	180.0	16.4	8.3	8.3	2.25	12.0	16.0	Q2
TPS65811RTQR	QFN	RTQ	56	2000	330.0	16.4	8.3	8.3	2.25	12.0	16.0	Q2
TPS65811RTQT	QFN	RTQ	56	250	180.0	16.4	8.3	8.3	2.25	12.0	16.0	Q2



PACKAGE MATERIALS INFORMATION

11-Mar-2008

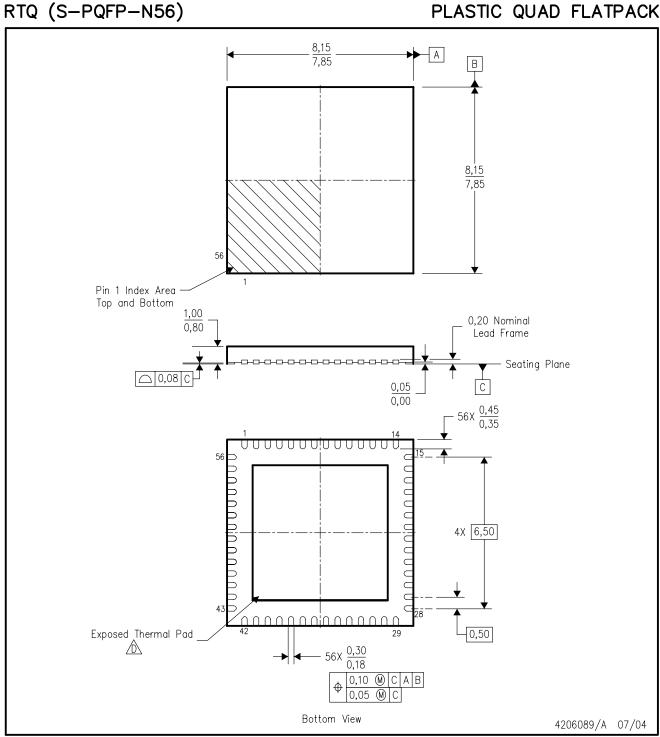


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS65810RTQR	QFN	RTQ	56	2000	346.0	346.0	33.0
TPS65810RTQT	QFN	RTQ	56	250	190.5	212.7	31.8
TPS65811RTQR	QFN	RTQ	56	2000	346.0	346.0	33.0
TPS65811RTQT	QFN	RTQ	56	250	190.5	212.7	31.8

MECHANICAL DATA

PLASTIC QUAD FLATPACK



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.

- B. This drawing is subject to change without notice.
- QFN (Quad Flatpack No-Lead) Package configuration.
- \triangle The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- E. Package complies to JEDEC MO-220.





THERMAL PAD MECHANICAL DATA

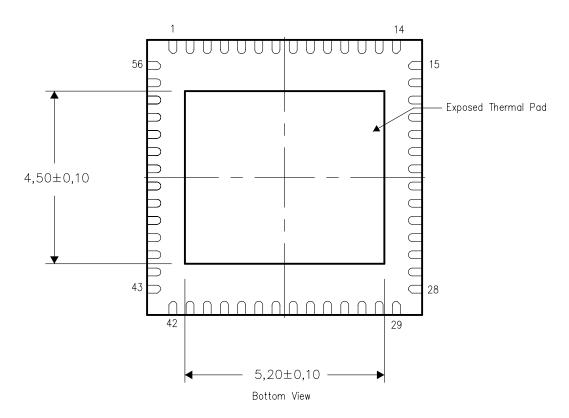
RTQ (S-PQFP-N56)

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

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